

Signetics

Integrated
Fuse
Logic
1981

FOREWORD

Signetics Integrated Fuse Logic elements combine into single-chip dense arrays of gates, buffers, and flip-flops interconnected via fusible Ni-Cr links. IFL, in effect, lifts circuit connections from the printed circuit board and integrates them on chip where they can be selectively blown by the user with standard PROM programming equipment.

The flexible architecture of Signetics IFL elements allows a "firmware" approach to the synthesis of complex logic functions which result in distinct design advantages. Specifically, most random logic designs using discrete TTL elements can be condensed into fewer IC packages, dramatically reducing overall system cost. Also, since IFL devices can be customized or edited in the field without re-tooling, your products can benefit from shorter development cycles, custom design flexibility, and quick recovery from design errors.

With the ability to manipulate a flexible logic system quick to debug and adapt to changes in architecture, you gain a competitive edge, not only by compacting in a system more functions, speed, and cost advantages, but by getting your products to the market ahead of your competitors.

Revised November 1981

Contents

Integrated Fuse Logic Series 28 Data Specifications

82S100/101 – FPLA	3
82S102/103 – FPGA	15
82S104/105 – FPLS	23
82S106/107 – FPRP	45

Integrated Fuse Logic Series 20 Data Specifications

82S150/151 – FPGA	57
82S152/153 – FPLA	63
82S154-159 – FPLS	75

Technical Article

“Field Programmable Arrays: Powerful Alternatives to Random Logic”	89
-----------------------------------------------------------------------------	----

DEFINITION OF TERMS

Data Sheet Identification	Product Status	Definition
Preview	Formative or In Design	This data sheet contains the design specifications for product development. Specifications may change in any manner without notice.
Advance Information	Sampling or Pre-Production	This data sheet contains advance information and specifications are subject to change without notice.
Preliminary	First Production	This data sheet contains preliminary data and supplementary data will be published at a later date. Signetics reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
No Identification Noted	Full Production	This data sheet contains final specifications. Signetics reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

© Copyright 1981 Signetics Corporation

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8) 82S100 (T.S.)/82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

DESCRIPTION

The 82S100 (tri-state outputs) and the 82S101 (open collector outputs) are Bipolar Programmable Logic Arrays, containing 48 product terms (AND terms), and 8 sum terms (OR terms). Each OR term controls an output function which can be programmed either true active-high (Fp), or true active-low (\bar{F}_p). The true state of each output function is activated by any logical combination of 16-input variables, or their complements, up to 48 terms. Both devices are field programmable, which means that custom patterns are immediately available by following the fusing procedure outlined in this data sheet.

The 82S100 and 82S101 are fully TTL compatible, and include chip-enable control for expansion of input variables, and output inhibit. They feature either open collector or tri-state outputs for ease of expansion of product terms and application in bus-organized systems.

Both devices are available in commercial and military temperature ranges. For the commercial temperature range (0°C to +75°C) specify N82S100/101, F or N, and for the military temperature range (-55°C to +125°C) specify S82S100/101, F or G, I, R.

LOGIC FUNCTION

Typical Product Term:
 $P_0 = I_0 \cdot I_1 \cdot \bar{I}_2 \cdot I_5 \cdot \bar{I}_{13}$

Typical Output Functions: @ $\bar{CE} = 0$:
 $F_0 = (P_0 + P_1 + P_2)$ @ L = Closed
 $F_0 = (\bar{P}_0 \cdot \bar{P}_1 \cdot \bar{P}_2)$ @ L = Open

NOTE

For each of the 8 outputs, either the function Fp (active-high) or \bar{F}_p (active low) is available, but not both. The required function polarity is programmed via link (L).

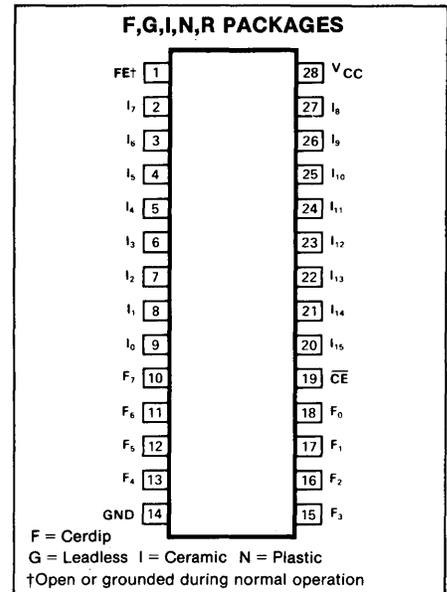
FEATURES

- Field programmable (Ni-Cr link)
- Input variables: 16
- Output functions: 8
- Product terms: 48
- Address access time:
S82S100/101—80ns Max
N82S100/101—50ns Max
- Power dissipation: 600mW typ
- Input loading:
S82S100/101: -150µA Max
N82S100/101: -100µA Max
- Chip enable input
- Output option:
82S100: Tri-state
82S101: Open collector
- Output disable function:
Tri-state—Hi-Z
Open collector—Hi

APPLICATIONS

- CRT display systems
- Random logic
- Code conversion
- Peripheral controllers
- Function generators
- Look-up and decision tables
- Microprogramming
- Address mapping
- Character generators
- Sequential controllers
- Data security encoders
- Fault detectors
- Frequency synthesizers

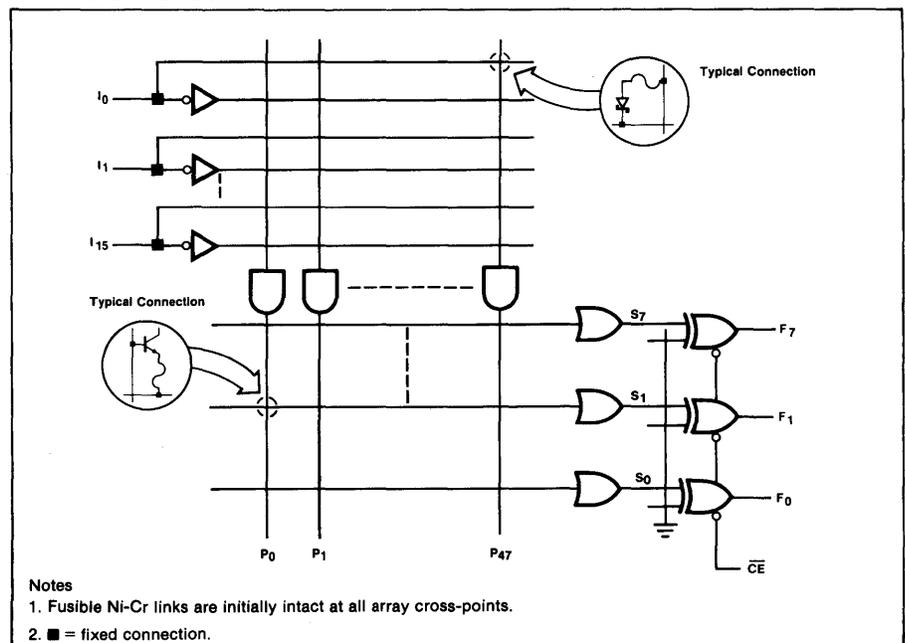
PIN CONFIGURATION



TRUTH TABLE

MODE	Pn	\bar{CE}	Sr ? f(Pn)	Fp	\bar{F}_p
Disabled (82S101)		1		1	1
Disabled (82S100)	X	1	X	Hi-Z	Hi-Z
Read	1	0	Yes	1	0
	0	0	No	0	1
	X	0		0	1

LOGIC DIAGRAM

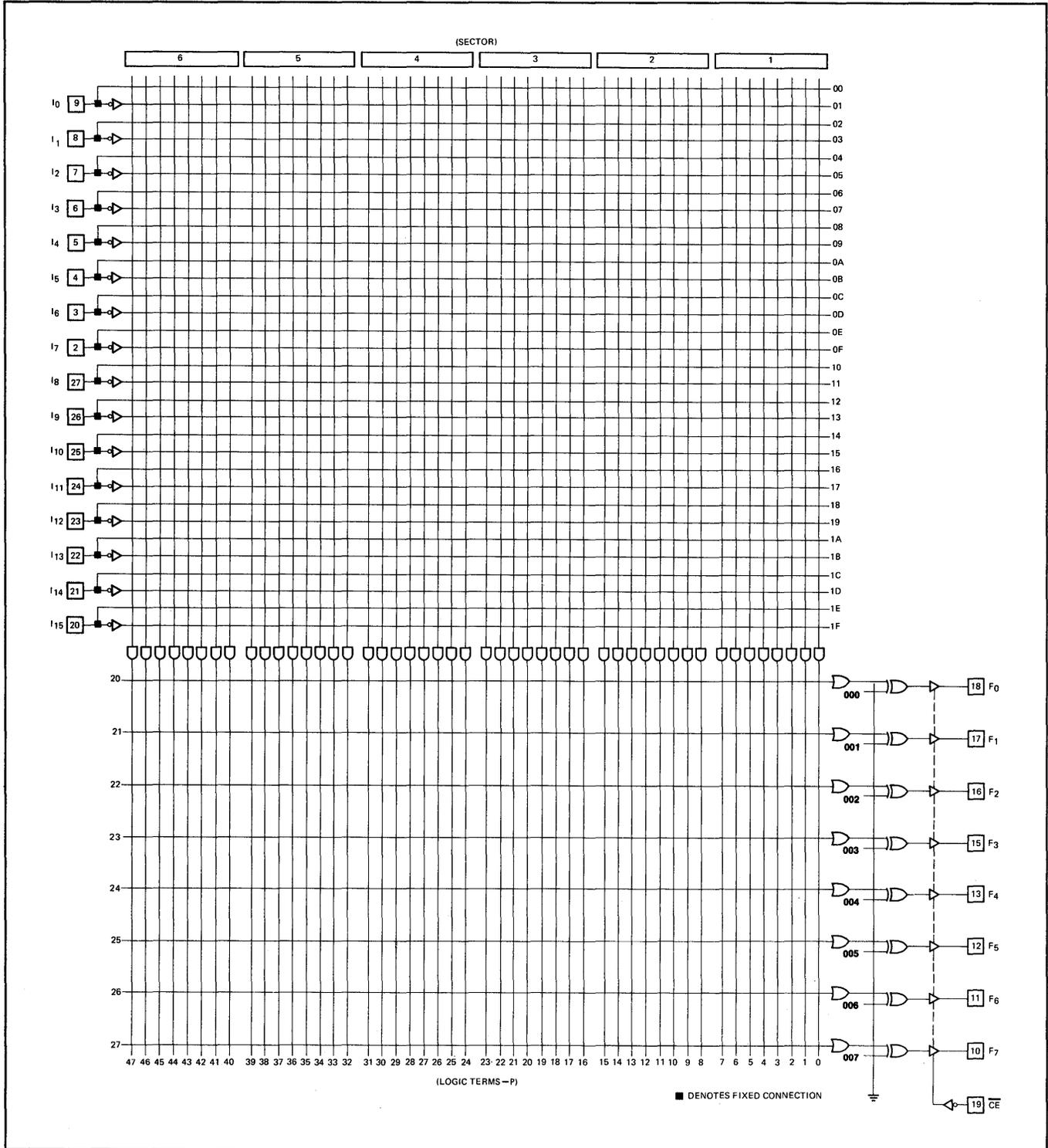


FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

82S100 (T.S.)82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

FPLA LOGIC DIAGRAM



FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8) 82S100 (T.S.)/82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

ABSOLUTE MAXIMUM RATINGS¹

PARAMETER	RATING		UNIT
	Min	Max	
V _{CC} Supply voltage		+7	Vdc
V _{IN} Input voltage		+5.5	Vdc
V _{OUT} Output voltage		+5.5	Vdc
I _{IN} Input currents	-30	+30	mA
I _{OUT} Output currents		+100	mA
T _A Temperature range			°C
Operating	0	+75	
	-55	+125	
T _{STG} Storage	-65	+150	

THERMAL RATINGS

TEMPERATURE	MILI-TARY	COM-MER-CIAL
Maximum junction	175°C	150°C
Maximum ambient	125°C	75°C
Allowable thermal rise ambient to junction	50°C	75°C

DC ELECTRICAL CHARACTERISTICS N82S100/101: 0° ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S100/101: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TEST CONDITIONS	N82S100/101			S82S100/101			UNIT
		Min	Typ ²	Max	Min	Typ ²	Max	
V _{IH} Input voltage ³ High	V _{CC} = Max	2			2			V
V _{IL} Low	V _{CC} = Min			0.85			0.8	
V _{IC} Clamp ^{3,4}	V _{CC} = Min, I _{IN} = -18mA		-0.8	-1.2		-0.8	-1.2	
V _{OH} Output voltage High (82S100) ^{3,5}	V _{CC} = Min I _{OH} = -2mA	2.4			2.4			V
V _{OL} Low ^{3,6}	I _{OL} = 9.6mA		0.35	0.45		0.35	0.50	
I _{IH} Input current High	V _{IN} = 5.5V		<1	25		<1	50	μA
I _{IL} Low	V _{IN} = 0.45V		-10	-100		-10	-150	
I _{OLK} Output current Leakage ⁷	\overline{CE} = High, V _{CC} = Max V _{OUT} = 5.5V		1	40		1	60	μA
I _{O(OFF)} Hi-Z state (82S100) ⁷	V _{OUT} = 5.5V		1	40		1	60	μA
I _{OS} Short circuit (82S100) ^{4,8}	V _{OUT} = 0.45V \overline{CE} = Low, V _{OUT} = 0V	-20	-1	-40	-15	-1	-60	mA
I _{CC} V _{CC} supply current ⁹	V _{CC} = Max		120	170		120	180	mA
C _{IN} Capacitance ⁷ Input	\overline{CE} = High, V _{CC} = 5.0V V _{IN} = 2.0V		8			8		pF
C _{OUT} Output	V _{OUT} = 2.0V		17			17		

AC ELECTRICAL CHARACTERISTICS R₁ = 470Ω, R₂ = 1kΩ, C_L = 30pF
N82S100/101: 0°C ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S100/101: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TO	FROM	N82S100/101			S82S100/101			UNIT
			Min	Typ ²	Max	Min	Typ ²	Max	
T _{IA} Propagation delay Input	Output	Input		35	50		35	80	ns
T _{CE} Chip enable	Output	Chip enable		15	30		15	50	
T _{CD} Disable time Chip disable	Output	Chip enable		15	30		15	50	ns

NOTES on following page.

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

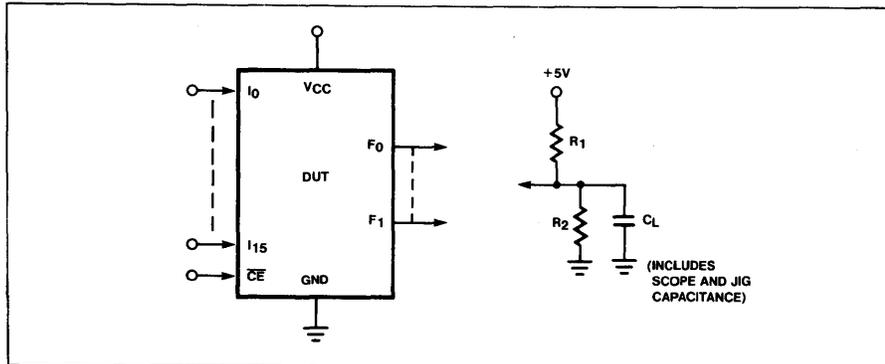
82S100 (T.S.) 82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

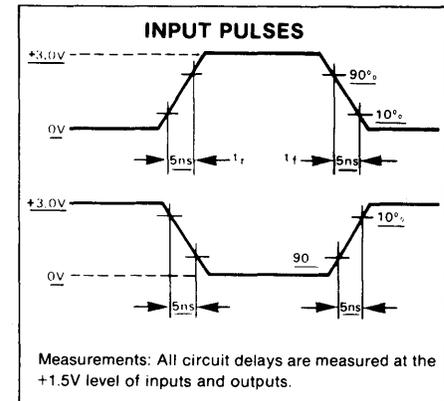
NOTES

1. Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions above those indicated in the operation of the device specifications is not implied.
2. All voltage values are at $V_{CC} = 5V$, $T_A = 25^\circ C$.
3. All voltage values are with respect to network ground terminal.
4. Test one at a time.
5. Measured with V_{IL} applied to \overline{CE} and a logic high stored.
6. Measured with a programmed logic condition for which the output test is at a low logic level. Output sink current is applied thru a resistor to V_{CC} .
7. Measured with V_{IH} applied to \overline{CE} .
8. Duration of short circuit should not exceed 1 second.
9. I_{CC} is measured with the chip enable input grounded, all other inputs at 4.5V and the outputs open.

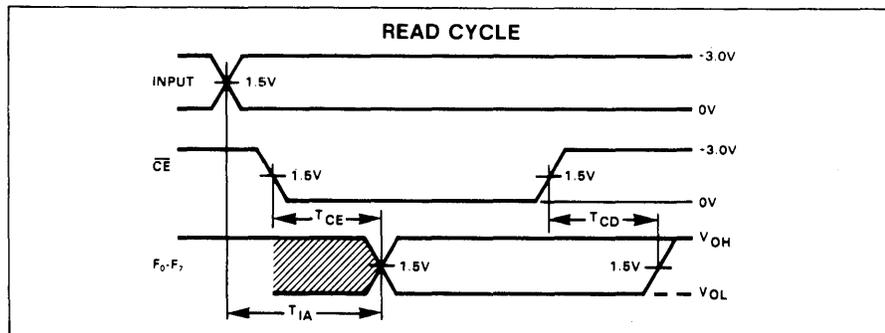
TEST LOAD CIRCUIT



VOLTAGE WAVEFORM



TIMING DIAGRAM



TIMING DEFINITIONS

- T_{CE} Delay between beginning of Chip Enable low (with Input valid) and when Data Output becomes valid.
- T_{CD} Delay between when Chip Enable becomes high and Data Output is in off state (Hi-Z or high).
- T_{IA} Delay between beginning of valid Input (with Chip Enable low) and when Data Output becomes valid.

VIRGIN DEVICE

The 82S100/101 are shipped in an unprogrammed state, characterized by:

1. All internal Ni-Cr links are intact.
2. Each product term (P-term) contains both true and complement values of every input variable I_m (P-terms always logically "false").

3. The "OR" Matrix contains all 48-P-terms.
4. The polarity of each output is set to active high (F_p function).
5. All outputs are at a low logic level.

RECOMMENDED PROGRAMMING PROCEDURE

To program each of 8 Boolean logic functions of 16 true or complement variables, including up to 48 P-terms, follow the Program/Verify procedures for the "AND" matrix, "OR" matrix, and output polarity outlined below. To maximize recovery from programming errors, leave all links in unused device areas intact.

SET-UP

Terminate all device outputs with a 10K resistor to +5V. Set GND (pin 14) to 0V.

Output Polarity

PROGRAM ACTIVE LOW ($\overline{F_p}$ FUNCTION)

Program output polarity before programming "AND" matrix and "OR" matrix. Program 1 output at the time. (L) links of unused outputs are not required to be fused.

1. Set FE (pin 1) to V_{FEL} .
2. Set V_{CC} (pin 28) to V_{CCL} .
3. Set \overline{CE} (pin 19), and I_0 through I_{15} to V_{IH} .
4. Apply V_{OPH} to the appropriate output, and remove after a period t_p .
5. Repeat step 4 to program other outputs.

VERIFY OUTPUT POLARITY

1. Set FE (pin 1) to V_{FEL} ; set V_{CC} (pin 28) to V_{CCS} .
2. Enable the chip by setting \overline{CE} (pin 19) to V_{IL} .
3. Address a non-existent P-term by applying V_{IH} to all inputs I_0 through I_{15} .
4. Verify output polarity by sensing the logic state of outputs F_0 through F_7 . All outputs at a high logic level are programmed active low ($\overline{F_p}$ function), while all outputs at a low logic level are programmed active high ($\overline{F_p}$ function).
5. Return V_{CC} to V_{CCP} or V_{CCL} .

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

82S100 (T.S.)82S101 (O.C.)

INTEGRATED FUSE LOGIC SERIES 28

“AND” Matrix

PROGRAM INPUT VARIABLE

Program one input at the time and one P-term at the time. All input variable links of unused P-terms are not required to be fused. However, unused input variables must be programmed as Don't Care for all programmed P-terms.

1. Set FE (pin 1) to V_{FEL} , and V_{CC} (pin 28) to V_{CCP} .
2. Disable all device outputs by setting \overline{CE} (pin 19) to V_{IH} .
3. Disable all input variables by applying V_{IX} to inputs I_0 through I_{15} .
4. Address the P-term to be programmed (No. 0 through 47) by forcing the corresponding binary code on outputs F_0 through F_5 with F_0 as LSB. Use standard TTL logic levels V_{OHF} and V_{OLF} .
- 5a. If the P-term contains neither I_0 nor $\overline{I_0}$ (input is a Don't Care), fuse both I_0 and $\overline{I_0}$ links by executing both steps 5b and 5c, before continuing with step 7.
- 5b. If the P-term contains I_0 , set to fuse the $\overline{I_0}$ link by lowering the input voltage at I_0 from V_{IX} to V_{IL} . Execute step 6.
- 5c. If the P-term contains $\overline{I_0}$, set to fuse the I_0 link by lowering the input voltage at I_0 from V_{IX} to V_{IL} . Execute step 6.
- 6a. After t_D delay, raise FE (pin 1) from V_{FEL} to V_{FEH} .
- 6b. After t_D delay, pulse the \overline{CE} input from V_{IH} to V_{IX} for a period t_p .
- 6c. After t_D delay, return FE input to V_{FEL} .
7. Disable programmed input by returning I_0 to V_{IX} .
8. Repeat steps 5 through 7 for all other input variables.
9. Repeat steps 4 through 8 for all other P-terms.
10. Remove V_{IX} from all input variables.

VERIFY INPUT VARIABLE

1. Set FE (pin 1) to V_{FEL} ; set V_{CC} (pin 28) to V_{CCP} .
2. Enable F_7 output by setting \overline{CE} to V_{IX} .
3. Disable all input variables by applying V_{IX} to inputs I_0 through I_{15} .
4. Address the P-term to be verified (No. 0 through 47) by forcing the corresponding binary code on outputs F_0 through F_5 .

5. Interrogate input variable I_0 as follows:
 - A. Lower the input voltage at I_0 from V_{IX} to V_{IH} , and sense the logic state of output F_7 .
 - B. Lower the input voltage at I_0 from V_{IH} to V_{IL} , and sense the logic state output F_7 .

The state of I_0 contained in the P-term is determined in accordance with the following truth table:

I_0	F_7	INPUT VARIABLE STATE CONTAINED IN P-TERM
0	1	$\overline{I_0}$
1	0	I_0
0	0	Don't Care
1	1	Don't Care
0	1	(I_0), ($\overline{I_0}$)
1	0	(I_0), ($\overline{I_0}$)

Note that 2 tests are required to uniquely determine the state of the input variable contained in the P-term.

6. Disable verified input by returning I_0 to V_{IX} .
7. Repeat steps 5 and 6 for all other input variables.
8. Repeat steps 4 through 7 for all other P-terms.
9. Remove V_{IX} from all input variables.

“OR” MATRIX

PROGRAM PRODUCT TERM

Program one output at the time for one P-term at the time. All P_n links in the “OR” matrix corresponding to unused outputs and unused P-terms are not required to be fused.

1. Set FE (pin 1) to V_{FEL} .
2. Disable the chip by setting \overline{CE} (pin 19) to V_{IH} .
3. After t_D delay, set V_{CC} (pin 28) to V_{CCS} , and inputs I_6 through I_{15} to V_{IH} , V_{IL} , or V_{IX} .
4. Address the P-term to be programmed (No. 0 through 47) by applying the corresponding binary code to input

- variables I_0 through I_5 , with I_0 as LSB.
- 5a. If the P-term is contained in output function F_0 ($F_0 = 1$ or $\overline{F_0} = 0$), go to step 6, (fusing cycle not required).
- 5b. If the P-term is **not** contained in output function F_0 ($F_0 = 0$ or $\overline{F_0} = 1$), set to fuse the P_n link by forcing output F_0 to V_{OPF} .
- 6a. After t_D delay, raise FE (pin 1) from V_{FEL} to V_{FEH} .
- 6b. After t_D delay, pulse the \overline{CE} input from V_{IH} to V_{IX} for a period t_p .
- 6c. After t_D delay, return FE input to V_{FEL} .
- 6d. After t_D delay, remove V_{OPF} from output F_0 .
7. Repeat steps 5 and 6 for all other output functions.
8. Repeat steps 4 through 7 for all other P-terms.
9. Remove V_{CCS} from V_{CC} .

VERIFY PRODUCT TERM

1. Set FE (pin 1) to V_{FEL} .
2. Disable the chip by setting \overline{CE} (pin 19) to V_{IH} .
3. After t_D delay, set V_{CC} (pin 28) to V_{CCS} , and inputs I_0 through I_{15} to V_{IH} , V_{IL} , or V_{IX} .
4. Address the P-term to be verified (No. 0 through 47) by applying the corresponding binary code to input variables I_0 through I_5 .
5. After t_D delay, enable the chip by setting \overline{CE} (pin 19) to V_{IL} .
6. To determine the status of the P_n link in the “OR” matrix for each output function F_p or $\overline{F_p}$, sense the state of outputs F_0 through F_7 . The status of the link is given by the following truth table:

OUTPUT		P-TERM LINK
Active High (F_p)	Active Low ($\overline{F_p}$)	
0	1	Fused Present
1	0	

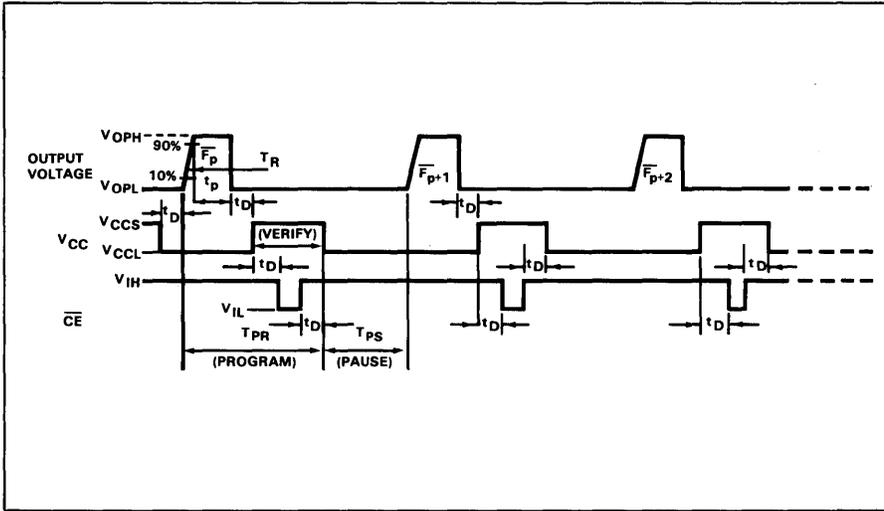
7. Repeat steps 4 through 6 for all other P-terms.
8. Remove V_{CCS} from V_{CC} .

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

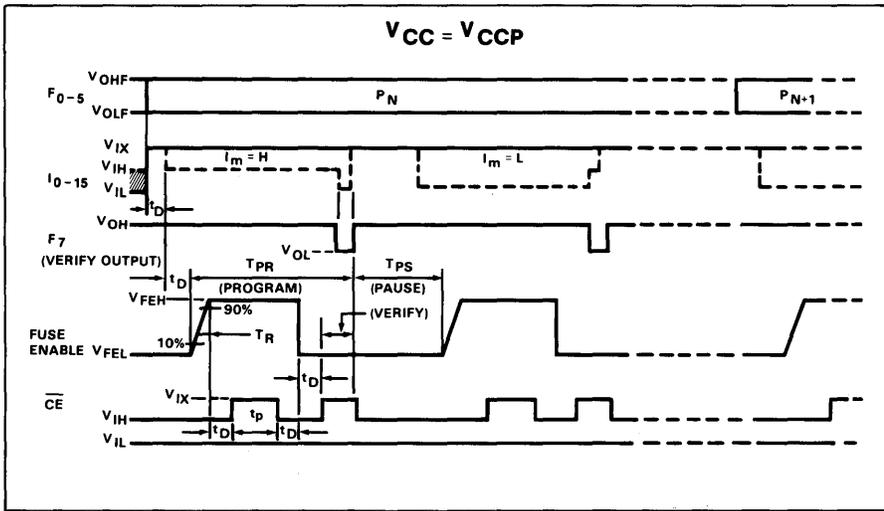
82S100 (T.S.) 82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

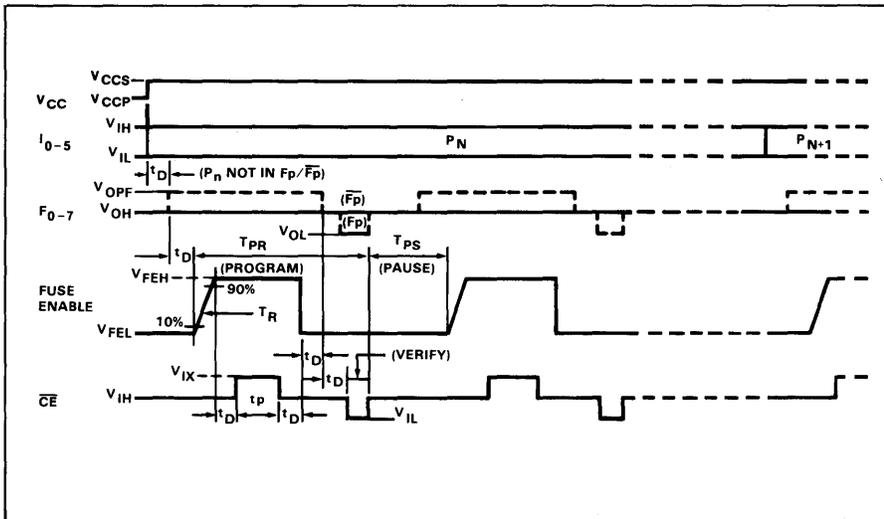
OUTPUT POLARITY PROGRAM-VERIFY SEQUENCE (TYPICAL)



"AND" MATRIX PROGRAM-VERIFY SEQUENCE (TYPICAL)



"OR" MATRIX PROGRAM-VERIFY SEQUENCE (TYPICAL)



FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

82S100 (T.S.)82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28PROGRAMMING SYSTEM SPECIFICATIONS¹ (T_A = +25°C)

PARAMETER		TEST CONDITIONS	LIMITS			UNIT
			Min	Typ	Max	
V _{CCS}	V _{CC} supply (program/verify "OR", verify output polarity) ²	I _{CCS} = 550mA, min, Transient or steady state	8.25	8.5	8.75	V
V _{CCL}	V _{CC} supply (program output polarity)		0	0.4	0.8	V
I _{CCS}	I _{CC} limit (program "OR")	V _{CCS} = +8.5 ± .25V	550		1,000	mA
V _{OPH}	Output voltage Program output polarity ³	I _{OPH} = 300 ± 25mA	16.0	17.0	18.0	V
V _{OPL}	Idle		0	0.4	0.8	
I _{OPH}	Output current limit (Program output polarity)	V _{OPH} = +17 ± 1V	275	300	325	mA
V _{IH}	Input voltage High		2.4		5.5	V
V _{IL}	Low		0	0.4	0.8	
I _{IH}	Input current High	V _{IH} = +5.5V			50	μA
I _{IL}	Low	V _{IL} = 0V			-500	
V _{OHF}	Forced output voltage High		2.4		5.5	V
V _{OLF}	Low		0	0.4	0.8	
I _{OHF}	Output current High	V _{OHF} = +5.5V			100	μA
I _{OLF}	Low	V _{OLF} = 0V			-1	mA
V _{IX}	\overline{CE} program enable level		9.5	10	10.5	V
I _{IX1}	Input variables current	V _{IX} = +10V			10	mA
I _{IX2}	\overline{CE} input current	V _{IX} = +10V			10	mA
V _{FEH}	FE supply (program) ³	I _{FEH} = 300 ± 25mA, Transient or steady state	16.0	17.0	18.0	V
V _{FEL}	FE supply (idle)	I _{FEL} = -1mA, max	1.25	1.5	1.75	V
I _{FEH}	FE supply current limit	V _{FEH} = +17 ± 1V	275	300	325	mA
V _{CCP}	V _{CC} supply (program/verify "AND")	I _{CCP} = 550mA, min, Transient or steady state	4.75	5.0	5.25	V
I _{CCP}	I _{CC} limit (program "AND")	V _{CCP} = +5.0 ± .25V	550		1,000	mA
V _{OPF}	Forced output (program)		9.5	10	10.5	V
I _{OPF}	Output current (program)				10	mA
T _R	Output pulse rise time	10% to 90%	10		50	μs
t _P	\overline{CE} programming pulse width		0.3	0.4	0.5	ms ⁵
t _D	Pulse sequence delay		10			μs
T _{PR}	Programming time			0.6		ms
$\frac{T_{PR}}{T_{PR} + T_{PS}}$	Programming duty cycle				50	%
F _L	Fusing attempts per link				2	cycle
V _S	Verify threshold ⁴		1.4	1.5	1.6	V

NOTES

- These are specifications which a Programming System must satisfy in order to be qualified by Signetics.
- Bypass V_{CC} to GND with a 0.01μf capacitor to reduce voltage spikes.
- Care should be taken to ensure that the voltage is maintained during the entire fusing cycle. The recommended supply is a constant current source clamped at the specified voltage limit.
- V_S is the sensing threshold of the FPLA output voltage for a programmed link. It normally constitutes the reference voltage applied to a comparator circuit to verify a successful fusing attempt.
- These are new limits resulting from device improvements, and which supersede, but do not obsolete the performance requirements of previously manufactured programming equipment.

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

82S100 (T.S.)82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

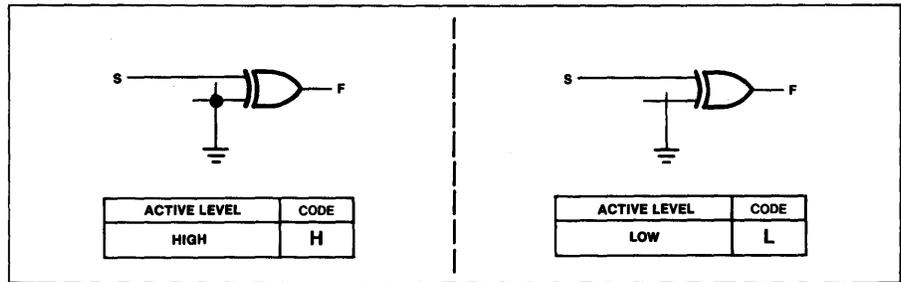
LOGIC PROGRAMMING

The FPLA can be programmed by means of Logic programming equipment.

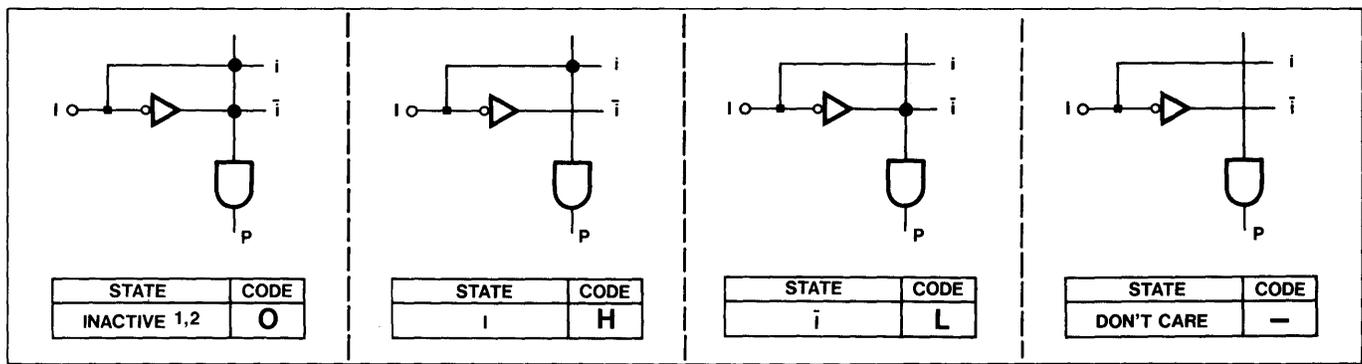
With Logic programming, the AND/OR/EX-OR gate input connections necessary to implement the desired logic function are coded directly from logic equations using the Program Table on the following page.

In this Table the logic state or action of variables I, P, and F, associated with each Sum Term S_r , is assigned a symbol which results in the proper fusing pattern of corresponding link pairs, defined as follows:

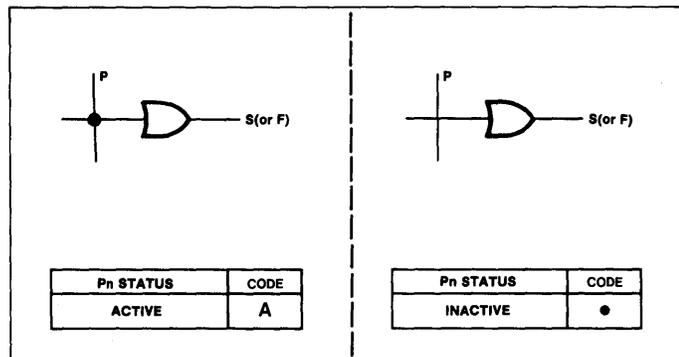
EX-OR ARRAY-(F)



“AND” ARRAY - (I)



“OR” ARRAY - (F)



NOTES

1. This is the initial unprogrammed state of all link pairs. It is normally associated with all unused (inactive) AND gates P_n .
2. Any gate P_n will be unconditionally inhibited if any one of its (I) link pairs is left intact.

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

82S100 (T.S.)82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

FPLA PROGRAM TABLE (Logic)

PROGRAM TABLE ENTRIES				PRODUCT TERM ¹																ACTIVE LEVEL ¹															
				INPUT VARIABLE		OUTPUT FUNCTION		OUTPUT ACTIVE LEVEL		INPUT VARIABLE ¹																OUTPUT FUNCTION ¹									
CUSTOMER NAME		PURCHASE ORDER #		Prod. Term Present in Fp		Prod. Term Not Present in Fp		Active High		Active Low		NO																ACTIVE LEVEL ¹							
SIGNETICS DEVICE #		CF (XXXX)		Don't Care		• (period)		H		L		5 4 3 2 1 0 9 8 7 6 5 4 3 2 1 0																7 6 5 4 3 2 1 0							
CUSTOMER SYMBOLIZED PART #		TOTAL NUMBER OF PARTS		NOTE		NOTE ²		NOTE		NOTE		0																0							
PROGRAM TABLE #		REV		DATE		NOTE		NOTE		NOTE		1																1							
VARIABLE NAME		PIN NO.		NOTE		NOTE		NOTE		NOTE		2																2							
		0		NOTE		NOTE		NOTE		NOTE		3																3							
		1		NOTE		NOTE		NOTE		NOTE		4																4							
		2		NOTE		NOTE		NOTE		NOTE		5																5							
		3		NOTE		NOTE		NOTE		NOTE		6																6							
		4		NOTE		NOTE		NOTE		NOTE		7																7							
		5		NOTE		NOTE		NOTE		NOTE		8																8							
		6		NOTE		NOTE		NOTE		NOTE		9																9							
		7		NOTE		NOTE		NOTE		NOTE		0																0							
		8		NOTE		NOTE		NOTE		NOTE		1																1							
		9		NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7							
				NOTE		NOTE		NOTE		NOTE		8																8							
				NOTE		NOTE		NOTE		NOTE		9																9							
				NOTE		NOTE		NOTE		NOTE		0																0							
				NOTE		NOTE		NOTE		NOTE		1																1							
				NOTE		NOTE		NOTE		NOTE		2																2							
				NOTE		NOTE		NOTE		NOTE		3																3							
				NOTE		NOTE		NOTE		NOTE		4																4							
				NOTE		NOTE		NOTE		NOTE		5																5							
				NOTE		NOTE		NOTE		NOTE		6																6							
				NOTE		NOTE		NOTE		NOTE		7																7</							

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

82S100 (I.S.)82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

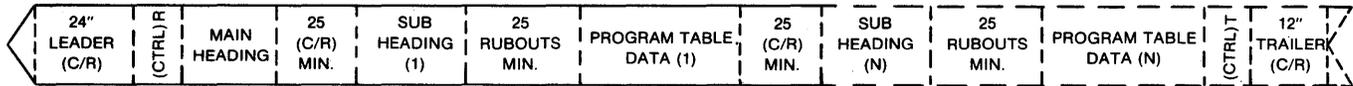
TWX TAPE CODING

The FPLA Program Table can be sent to Signetics in ASCII code format via airmail using any type of 8-level tape (paper, mylar, fanfold, etc.), or via TWX: just dial (910) 339-

9283, tell the operator to turn the paper puncher on, and acknowledge. At the end of transmission instruct the operator to send tape to Signetics Order Entry.

quentially assembled on a continuous tape as follows, however limit tape length to a roll of 1.75 inch inside diameter, and 4.25 inch outside diameter:

A number of Program Tables can be se-



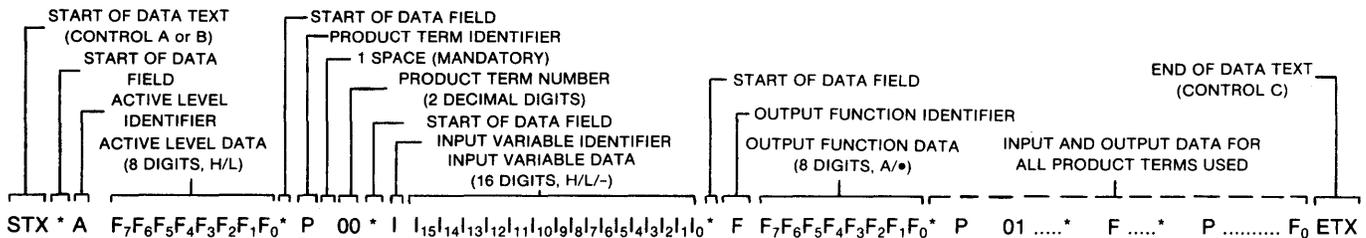
A. The MAIN HEADING at the beginning of tape includes the following information, with each entry preceded by a (\$) character, whether used or not:

- 1. Customer Name _____
- 2. Customer TWX No. _____
- 3. Date _____
- 4. Purchase Order No. _____
- 5. Number of Program Tables _____
- 6. Total Number of Parts _____

B. Each SUB HEADING should contain specific information pertinent to each Program Table as follows, with each entry preceded by a (\$) character, whether used or not:

- 1. Signetics Device No. _____
- 2. Program Table No. _____
- 3. Revision _____
- 4. Date _____
- 5. Customer Symbolized Part No. _____
- 6. Number of Parts _____

C. Program Table data blocks in Logic format are initiated with an STX character, and terminated with an ETX character. The body of the data consists of Output Active Level, Product Term, and Output Function information separated by appropriate identifiers in accordance with the following sequence:



Entries for the 3 Data Fields are determined in accordance with the following Table:

INPUT VARIABLE		
I_m	\bar{I}_m	Don't Care
H	L	— (dash)

NOTE
Enter (—) for unused inputs of used P-terms.

OUTPUT FUNCTION	
Product term present in Fp	Product term not present in Fp
A	• (period)

NOTES
1. Entries independent of output polarity.
2. Enter (A) for unused outputs of used P-terms.

OUTPUT ACTIVE LEVEL	
Active high	Active low
H	L

NOTES
1. Polarity programmed once only.
2. Enter (H) for all unused outputs.

Although the Product Term data are shown entered in sequence, this is not necessary. It is possible to input only one Product Term, if desired. Unused Product Terms require no entry. ETX signalling end of Program Table may occur with less than the maximum number of Product Terms entered.

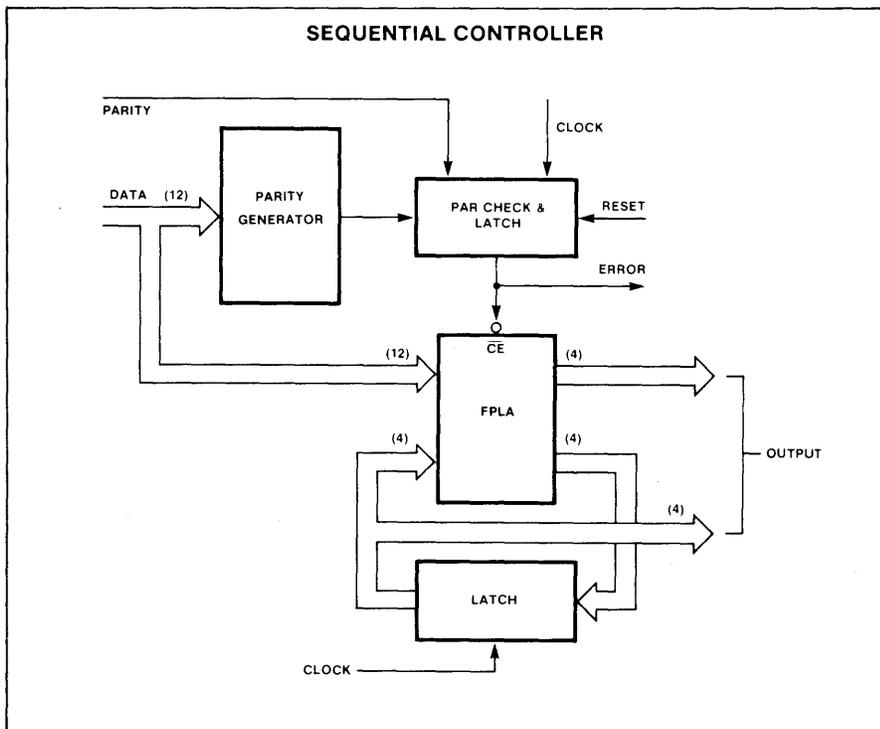
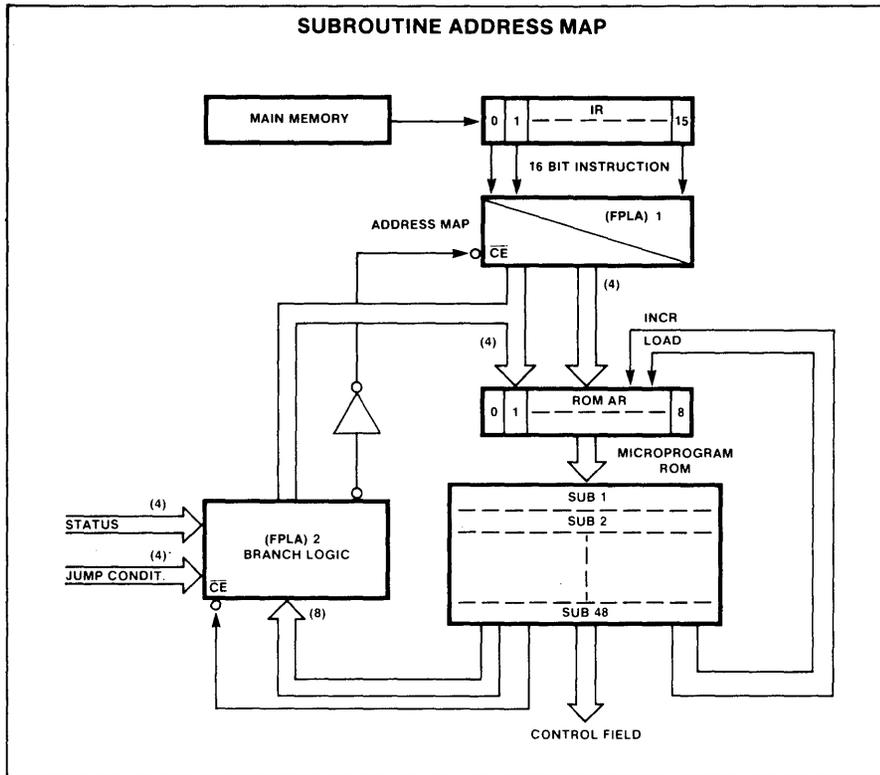
- NOTES
- 1. Corrections to any entry can be made by backspace and rubout. However, limit consecutive rubouts to less than 25.
 - 2. Terms can be re-entered any number of times. The last entry for a particular P-Term will be interpreted as valid data.
 - 3. To facilitate an orderly Teletype print out, carriage returns, line feeds, spaces, rubouts etc. may be interspersed between data groups.
 - 4. Comments are allowed between data fields, provided that an asterisk (*) is not used in any Heading or Comment entry.

FIELD PROGRAMMABLE LOGIC ARRAY (16X48X8)

82S100 (T.S.)82S101 (O.C.)

INTEGRATED FUSE LOGIC
SERIES 28

TYPICAL APPLICATIONS



FIELD PROGRAMMABLE GATE ARRAY (16X9)

82S102 (O.C.)/82S103 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

DESCRIPTION

The 82S102 and 82S103 are Bipolar programmable AND/NAND gate array, containing 9 gates sharing 16 common inputs. On-chip input buffers enable the user to individually program for each gate either the True (I_m), Complement ($\overline{I_m}$), or Don't Care (X) logic state of each input. In addition, the polarity of each gate output is individually programmable to implement either AND or NAND logic functions.

Alternately, if desired, OR/NOR logic functions can also be realized by programming for each gate the complement of its input variables, and output (DeMorgan theorem).

Both devices are field-programmable, which means that custom patterns are immediately available by following the fusing procedure outlined in this data sheet.

The 82S102 and 82S103 include chip-enable control for output strobing and inhibit. They feature either open collector or tri-state outputs for ease of expansion of input variables and application in bus-organized systems.

Both devices are available in the commercial and military temperature ranges. For the commercial range (0°C to +75°C) specify N82S102/103, F or N, and for the military range (-55°C to +125°C) specify S82S102/103, F, G, I, and R.

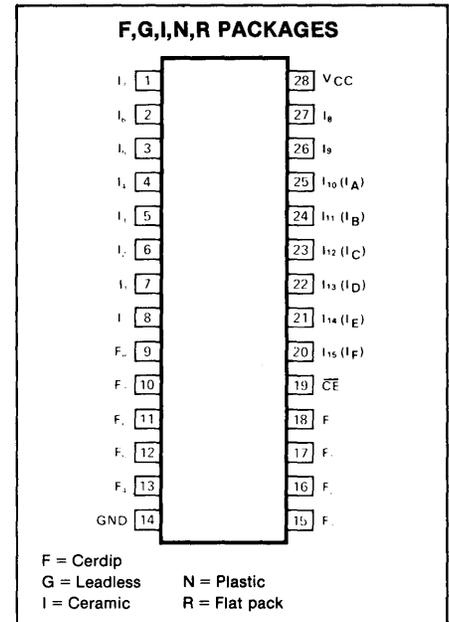
FEATURES

- Field programmable (Ni-Cr link)
- 16 input variables
- 9 output functions
- Chip enable input
- I/O propagation delay:
N82S102/103: 35ns max
S82S102/103: 50ns max
- Power dissipation: 600mW typ
- Input loading:
N82S102/103: -100µA max
S82S102/103: -150µA max
- Output options:
82S102: Open collector
82S103: Tri-state
- Output disable function:
82S102: Hi
82S103: Hi-Z
- Fully TTL compatible

APPLICATIONS

- Random logic
- Address decoders
- Code detectors
- Peripheral selectors
- Fault monitors
- Machine state decoders

PIN CONFIGURATION



LOGIC FUNCTION

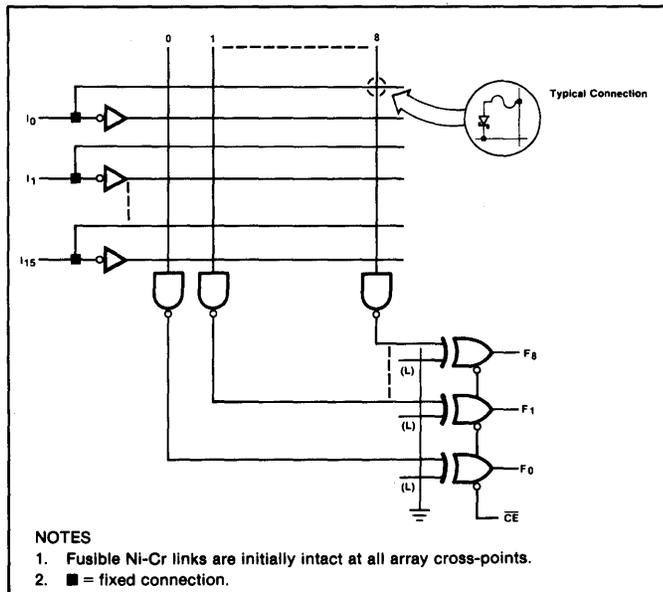
Typical Output Functions @ $\overline{CE} = 0$:

At L = Open:
 $F_0 = (I_0 \cdot I_1 \cdot I_2 \cdot \dots \cdot \overline{I_m})$
 At L = Closed:
 $F_0 = (\overline{I_0} + \overline{I_1} + \overline{I_2} + \dots + I_m)$
 $m = 0, 1, 2, \dots, 15$

NOTES

For each of the 9 outputs, either the function F_p (active high) or $\overline{F_p}$ (active low) is available but not both. The required function polarity is programmed via link (L).

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

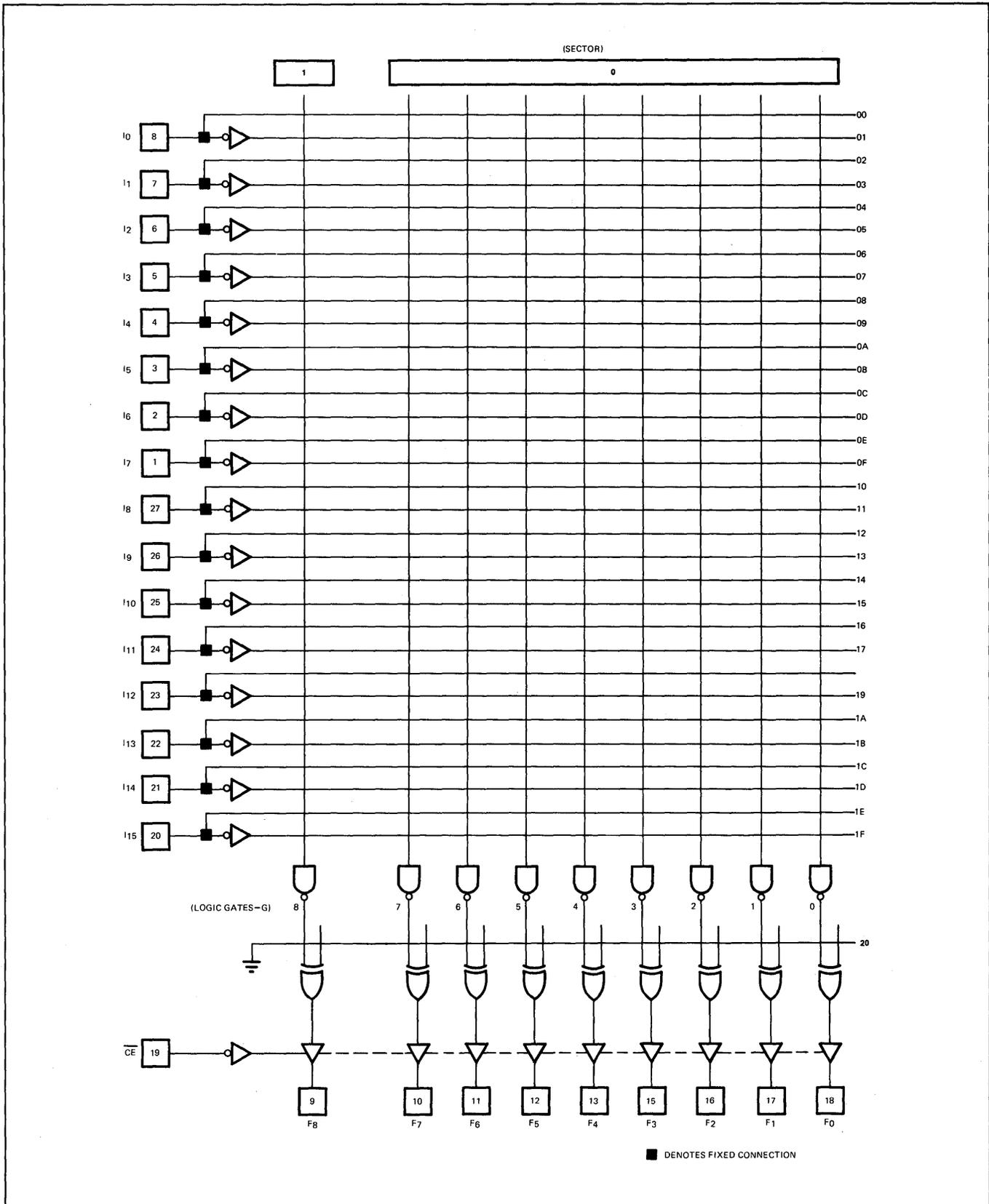
PARAMETER	RATING	UNIT	
VCC	Supply voltage	+7	Vdc
VIN	Input voltage	+5.5	Vdc
VOH	Output voltage		Vdc
VOH	High (82S102)	+5.5	
VO	Off-state (82S103)	+5.5	
IIN	Input current	±30	mA
IOUT	Output current	+100	mA
TA	Temperature range		°C
TA	Operating		
	N82S102/103	0 to +75	
	S82S102/103	-55 to +125	
TSTG	Storage	-65 to +150	

FIELD PROGRAMMABLE GATE ARRAY (16X9)

82S102 (O.C.)/82S103 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

FPGA LOGIC DIAGRAM



FIELD PROGRAMMABLE GATE ARRAY (16X9)

82S102 (O.C.)/82S103 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

DC ELECTRICAL CHARACTERISTICS N82S102/103: 0°C ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S102/103: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER ¹	TEST CONDITIONS	N82S102/103			S82S102/103			UNIT			
		Min	Typ ²	Max	Min	Typ ²	Max				
V _{IL} V _{IH} V _{IC}	Input voltage Low ¹ High ¹ Clamp ^{1,3}	V _{CC} = Min V _{CC} = Max V _{CC} = Min, I _{IN} = -18mA			2.0	-0.8	-1.2	2.0	-0.8	-1.2	V
V _{OL} V _{OH}	Output voltage Low ^{1,4} High (82S103) ^{1,5}	V _{CC} = Min I _{OL} = 9.6mA I _{OH} = -2mA			2.4	0.35	0.45	2.4	0.35	0.50	V
I _{IL} I _{IH}	Input current Low High	V _{IN} = 0.45V V _{IN} = 5.5V				-10 <1	-100 25		-10 <1	-150 50	μA
I _{OLK} I _{O(OFF)}	Output current Leakage (82S102) ⁶ Hi-Z state (82S103) ⁶	V _{CC} = Max V _{OUT} = 5.5V V _{OUT} = 5.5V V _{OUT} = 0.45V				1 1 -1	40 40 -40		1 1 -1	60 60 -60	μA
I _{OS}	Short circuit (82S103) ^{3,7}	V _{OUT} = 0V			-20		-70	-15		-85	mA
I _{CC}	V _{CC} supply current ⁸	V _{CC} = Max				120	170		120	180	mA
C _{IN} C _{OUT}	Capacitance Input Output ⁶	V _{CC} = 5.0V V _{IN} = 2.0V V _{OUT} = 2.0V				8 15			8 15		pF

AC ELECTRICAL CHARACTERISTICS R₁ = 470Ω, R₂ = 1kΩ, C_L = 30pF

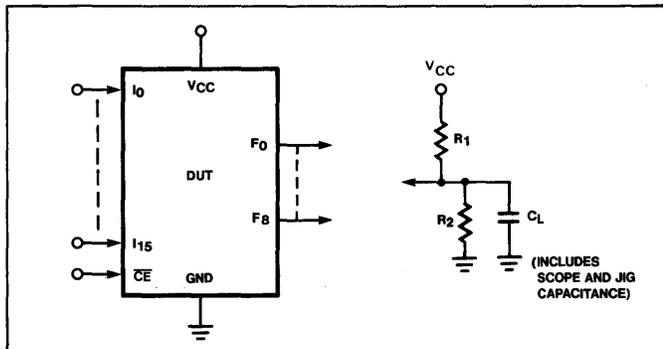
N82S102/103: 0°C ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S102/103: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TO	FROM	N82S102/103			S82S103/103			UNIT
			Min	Typ ²	Max	Min	Typ ²	Max	
T _{IA} T _{CE}	Propagation delay Input Chip enable	Output Output		20 15	35 30		20 15	55 45	ns
T _{CD}	Disable time Chip disable	Output		15	30		15	45	ns

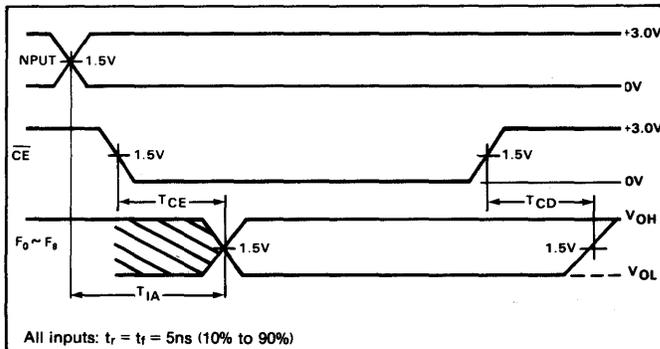
NOTES

- All voltage values are with respect to network ground terminal.
- All typical values are at V_{CC} = 5V, T_A = 25°C.
- Test each output one at a time.
- Measured with a programmed logic condition for which the output under test is at a low logic level.
Output sink current is supplied through a resistor to V_{CC}.
- Measured with V_{IL} applied to \overline{CE} and a logic high at the output.
- Measured with V_{IH} applied to \overline{CE} .
- Duration of short circuit should not exceed 1 second.
- I_{CC} is measured with the chip enable input grounded, all other inputs at 4.5V and the outputs open.

TEST LOAD CIRCUIT



VOLTAGE WAVEFORM



FIELD PROGRAMMABLE GATE ARRAY (16X9)

82S102 (O.C.)/82S103 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

The state of I_0 contained in each gate is determined in accordance with the given truth table. Note that 2 tests are required to uniquely determine the state of the input variable contained in each gate.

- B. Disable verified input by returning I_0 to V_{IX} .
- C. Repeat steps A and B for all other input variables.
- D. Remove V_{IX} from all input variables.

TRUTH TABLE FOR INPUT VERIFICATION

I_0	F_p	$\overline{F_p}$	INPUT VARIABLE STATE
0	1	0	$\overline{I_0}$
1	0	1	I_0
0	0	1	I_0
1	1	0	
0	1	0	Don't care
1	1	0	
0	0	1	$(I_0), (\overline{I_0})$
1	0	1	

PROGRAMMING SYSTEMS SPECIFICATIONS¹ $T_A = 25^\circ C$

PARAMETER	TEST CONDITIONS	LIMITS			UNIT	
		Min	Typ	Max		
V_{CCP} V_{CCV}	V_{CC} supply Program ² Verify	$I_{CCP} = 550mA$, min Transient or steady state	8.25 4.75	8.5 5.0	8.75 5.25	V
I_{CCP}	I_{CC} limit (program)	$V_{CCP} = +8.5 \pm .25V$, Transient or steady state $I_{OP} = 300 \pm 25mA$, Transient or steady state $V_{OP} = +17 \pm 1V$, Transient or steady state	550		1,000	mA
V_{OPF}	Forced output voltage ³ (program)		16.0	17.0	18.0	V
I_{OPF}	Output current (program)		275	300	325	mA
V_{IH} V_{IL}	Input voltage High Low		2.4 0	0.4	5.5 0.8	V
I_{IH} I_{IL}	Input current High Low	$V_{IH} = +5.5V$ $V_{IL} = 0V$			50 -500	μA
V_{IX} I_{IX1} I_{IX2}	\overline{CE} program enable level Input variables current \overline{CE} input current	$V_{IX} = +10V$ $V_{IX} = +10V$	9.5	10	10.5 10.0 10.0	V mA mA
T_R t_P t_D T_{PR} $\frac{T_{PR}}{T_{PR}+T_{PS}}$	Output pulse rise time \overline{CE} programming pulse width Pulse sequence delay Programming time Programming duty cycle	10% to 90%	10 0.3 10	0.4 0.6	50 0.5	μs ms μs ms
F_L V_S	Fusing attempts per link Verify threshold ⁴		1.4	1.5	100 2 1.6	% cycle V

NOTES

1. These are specifications which a Programming System must satisfy in order to be qualified by Signetics.
2. Bypass V_{CC} to GND with a 0.01 μF capacitor to reduce voltage spikes.
3. Care should be taken to ensure that the voltage is maintained during the entire fusing cycle. The recommended supply is a constant current source clamped at the specified voltage limit.
4. V_S is the sensing threshold of a gate output voltage for a programmed link. It normally constitutes the reference voltage applied to a comparator circuit to verify a successful fusing attempt.

FIELD PROGRAMMABLE GATE ARRAY (16X9)

82S102 (O.C.)/82S103 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

LOGIC PROGRAMMING

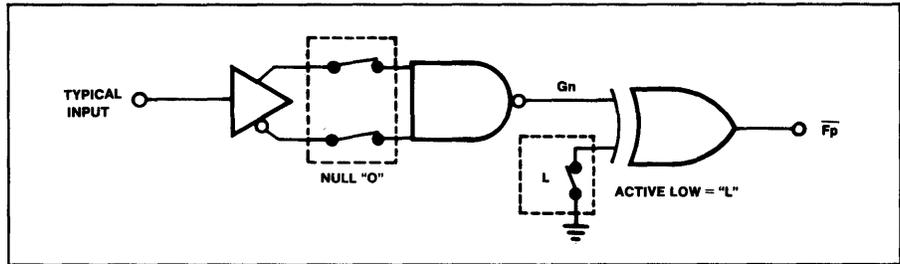
In a virgin device all Ni-Cr links are intact. The initial programmed state of each gate is shown in the Typical Gate illustration.

The FPGA can be programmed by means of Logic programming equipment.

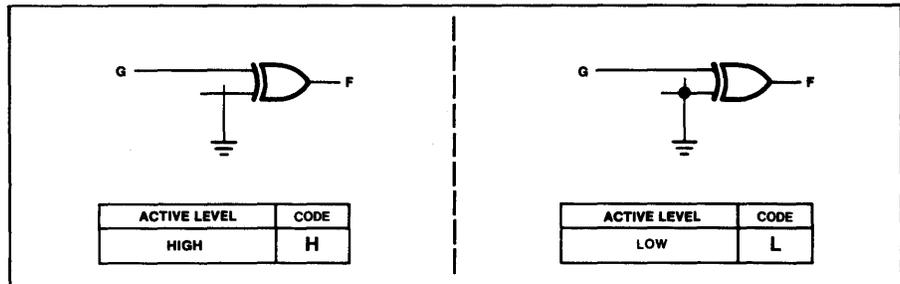
With Logic programming, the AND/EX-OR gate input connections necessary to implement the desired logic function are coded directly from logic equations using the Program Table on the following page.

In this table, the logic state or action of variables I and F associated with each gate G_n is assigned a symbol which results in the proper fusing pattern of corresponding link pairs, defined as follows:

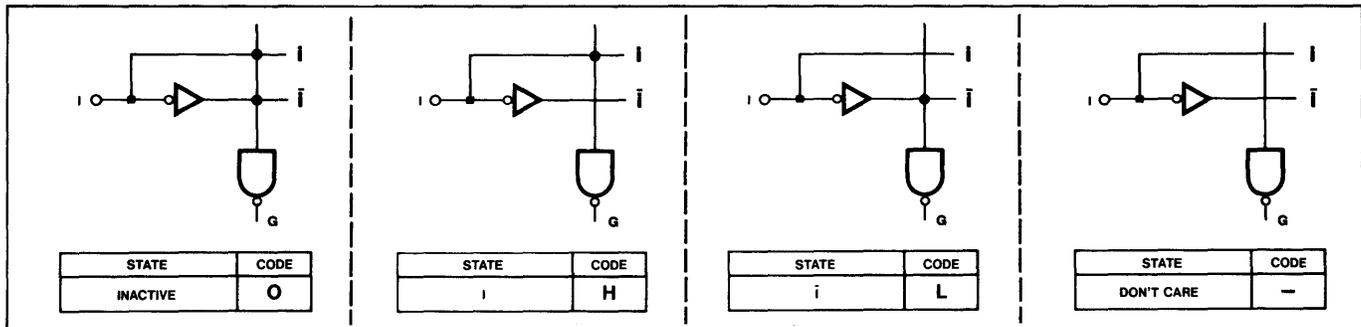
TYPICAL GATE



EX-OR ARRAY - (F)



"AND" ARRAY - (I)



NOTES

1. This is the initial unprogrammed state of all link pairs. It is normally associated with all unused (inactive) AND gates G_n .
2. Any gate G_n will be unconditionally inhibited if any one of its (I) link pairs is left intact.

FIELD PROGRAMMABLE GATE ARRAY (16X9)

82S102 (O.C.)/82S103 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

FPGA PROGRAM TABLE (Logic)

CUSTOMER NAME _____ PURCHASE ORDER # _____ SIGNETICS DEVICE # _____ TOTAL NUMBER OF PARTS _____ PROGRAM TABLE # _____	THIS PORTION TO BE COMPLETED BY SIGNETICS CF (XXXX) _____ CUSTOMER SYMBOLIZED PART # _____ DATE RECEIVED _____ COMMENTS _____
-----------------------------------------------------------------------------------------------------------------------------------	-------------------------------------------------------------------------------------------------------------------------------------------

- F₀ (18) _____ = _____
- F₁ (17) _____ = _____
- F₂ (16) _____ = _____
- F₃ (15) _____ = _____
- F₄ (13) _____ = _____
- F₅ (12) _____ = _____
- F₆ (11) _____ = _____
- F₇ (10) _____ = _____
- F₈ (9) _____ = _____

GATE ACTIVE LEVEL	INPUT VARIABLE																
	I ₁₅	I ₁₄	I ₁₃	I ₁₂	I ₁₁	I ₁₀	I ₉	I ₈	I ₇	I ₆	I ₅	I ₄	I ₃	I ₂	I ₁	I ₀	
F ₀	0	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
F ₁	16	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
F ₂	32	47	46	45	44	43	42	41	40	39	38	37	36	35	34	33	32
F ₃	48	63	62	61	60	59	58	57	56	55	54	53	52	51	50	49	48
F ₄	64	79	78	77	76	75	74	73	72	71	70	69	68	67	66	65	64
F ₅	80	95	94	93	92	91	90	89	88	87	86	85	84	83	82	81	80
F ₆	96	111	110	109	108	107	106	105	104	103	102	101	100	99	98	97	96
F ₇	112	127	126	125	124	123	122	121	120	119	118	117	116	115	114	113	112
F ₈	128	143	142	141	140	139	138	137	136	135	134	133	132	131	130	129	128
PIN NO.	20	21	22	23	24	25	26	27	28	1	2	3	4	5	6	7	8
VARIABLE NAME																	

Active—High = H
 Action—Low = L I_m = H I_m = L Don't Care = -

NOTES

1. The number in each cell in the table denotes its address for programmers with a decimal address display.

FIELD PROGRAMMABLE GATE ARRAY (16X9)

82S102 (O.C.)/82S103 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

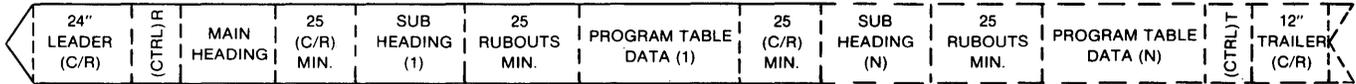
TWX TAPE CODING

The FPGA Program Table can be sent to Signetics in ASCII code format via airmail using any type of 8-level tape (paper, mylar, fanfold, etc.), or via TWX: just dial (910) 339-

9283, tell the operator to turn the paper puncher on, and acknowledge. At the end of transmission instruct the operator to send tape to Signetics Order Entry.

quentially assembled on a continuous tape as follows, however limit tape length to a roll of 1.75 inch inside diameter, and 4.25 inch outside diameter:

A number of Program Tables can be se-



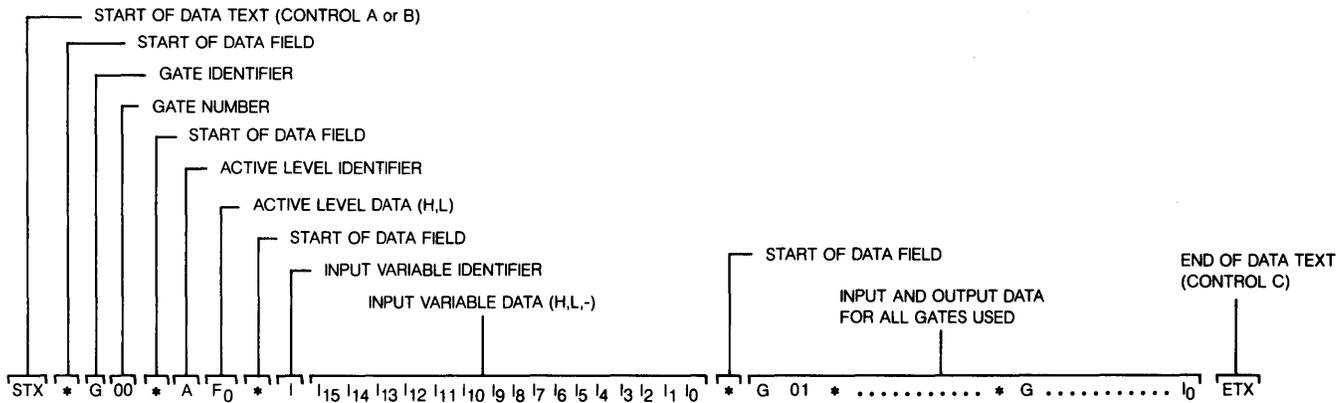
A. The MAIN HEADING at the beginning of tape includes the following information, with each entry preceded by a (\$) character, whether used or not:

- 1. Customer Name _____
- 2. Customer TWX No. _____
- 3. Date _____
- 4. Purchase Order No. _____
- 5. Number of Program Tables _____
- 6. Total Number of Parts _____

B. Each SUB HEADING should contain specific information pertinent to each Program Table as follows, with each entry preceded by a (\$) character, whether used or not:

- 1. Signetics Device No. _____
- 2. Program Table No. _____
- 3. Revision _____
- 4. Date _____
- 5. Customer Symbolized Part No. _____
- 6. Number of Parts _____

C. Program Table data blocks in Logic format are initiated with an STX character, and terminated with an ETX character. The body of the data consists of Output Active Level and AND gates information separated by appropriate identifiers in accordance with the following sequence:



Entries for the 2 Data Fields are determined in accordance with the following Table:

INPUT VARIABLE		
I_M	\bar{I}_M	Don't care
H	L	— (dash)

OUTPUT ACTIVE LEVEL	
Active high	Active low
H	L

NOTE
Enter (—) for unused inputs of used gates.

NOTES
1. Polarity programmed once only.
2. Enter (L) for all unused outputs.

Although AND Gate data are shown entered in sequence, this is not necessary. It is possible to input only one Gate if desired. Unused Gates require no entry. ETX signalling end of Program Table may occur with less than the maximum number of AND Gates entered.

- NOTES
- 1. Corrections to any entry can be made by backspace and rubout. However, limit consecutive rubouts to less than 25.
 - 2. Terms can be re-entered any number of times. The last entry for a particular P-Term will be interpreted as valid data.
 - 3. To facilitate an orderly Teletype print out, carriage returns, line feeds, spaces, rubouts etc. may be interspersed between data groups.
 - 4. Comments are allowed between data fields, provided that an asterisk (*) is not used in any Heading or Comment entry.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

DESCRIPTION

The 82S104 (open collector outputs) and the 82S105 (tri-state outputs) are bipolar, programmable state machines of the Mealy type. They contain logic AND-OR gate arrays with user programmable connections which control the inputs of on-chip State and Output registers. These consist respectively of 6 Q_p, and 8 Q_f edge triggered, clocked S/R flip-flops, with an asynchronous Preset option. All flip-flops are unconditionally preset to "1" during power turn on.

The AND array combines 16 external inputs I₀₋₁₅ with 6 internal inputs P₀₋₅ fed back from the State register to form up to 48 Transition terms (AND terms). All Transition terms can include True, False, or Don't Care states of the controlling variables, and are merged in the OR array to issue next-state and next-output commands to their respective registers on the Low to High transition of the Clock pulse. Both True and Complement Transition terms can be generated by optional use of the internal input variable (C) from the Complement array. Also, if desired, the Preset input can be converted to Output-Enable function, as an additional user programmable option.

Both devices are available in commercial and military temperature ranges. For the commercial temperature range (0°C to +75°C) specify N82S104/105, F or N, and for the military temperature range (-55°C to +125°C) specify S82S104/105, F, I, G or R.

TRUTH TABLE (Output Control)

I ₀	INPUT OPTION		F _N
	PR	O.E.	
*	H		H
+10V	L		Q _p
X	L		Q _f
*		H	H/Hi-Z
+10V		L	Q _p
X		L	Q _f

NOTES

- Positive Logic:
S/R = T₀ + T₁ + T₂ + ... + T₄₇
T_n = C (I₀ I₁ I₂ ...) (P₀ P₁ ... P₅)
- Either Preset (active-High) or Output Enable (active-Low) are available, but not both. The desired function is a user programmable option.
- ↑ denotes transition from Low to High level.
- R = S = High is an illegal input condition.
- * = H/L/+10V
- X = Don't Care (≤5.5V)

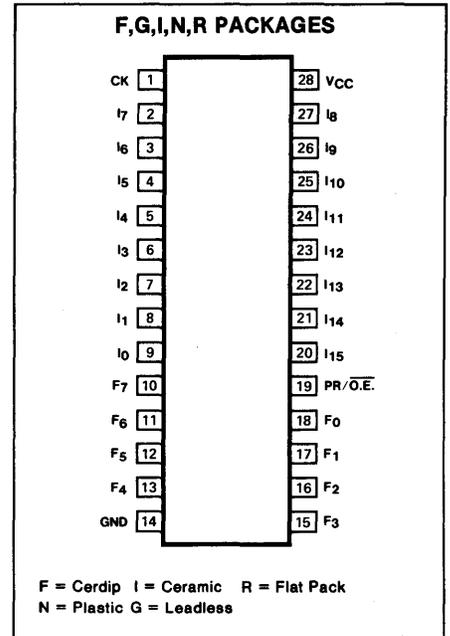
FEATURES

- Field programmable (Ni-Cr link)
- 16 input variables
- 8 output functions
- 48 transition terms
- 6-BIT state register
- 8-BIT output register
- Transition complement array
- Positive edge trigger clock
- Programmable asynchronous preset or output enable
- Power-on preset to all "1" of internal registers
- 90ns maximum I/O delay
- 650mW power dissipation (typical)
- TTL compatible
- Single +5V supply

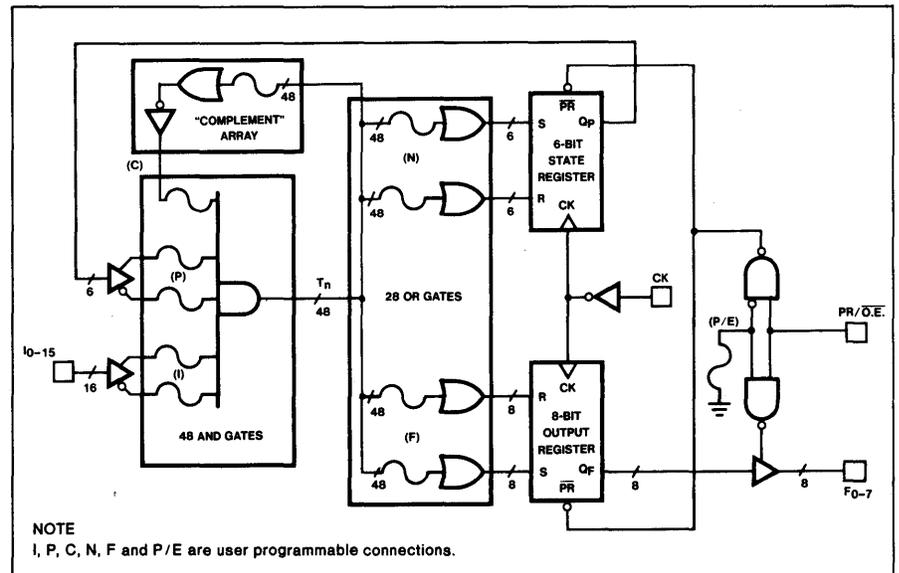
APPLICATIONS

- Interface protocols
- Sequence detectors
- Peripheral controllers
- Timing generators
- Sequential circuits
- Elevator controllers
- Security locking systems

PIN CONFIGURATION



BLOCK DIAGRAM



TRUTH TABLE (All flip-flops)

VCC	INPUT OPTION		CK	S	R	STATE REGISTER	OUTPUT REGISTER
	PR	O.E.				Q _p	Q _f
+5V	H		X	X	X	H	H
	L	X	↑	L	L	Q _p	Q _f
	L	X	↑	L	H	L	L
	L	X	↑	H	L	H	H
	L	X	↑	H	H	INDET.	INDET.
↑	X	X	X	X	X	H	H

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

PIN DESIGNATION

PIN NO.	SYMBOL	NAME AND FUNCTION	POLARITY
1	CK	CLOCK The clock input to the State and Output Registers. A Low-to-High transition on this line is necessary to update the contents of both registers.	Active-High
[2-8] [20-27]	I ₁₋₁₅	LOGIC INPUTS The 15 external inputs to the AND array used to program jump conditions between machine states, as determined by a given logic sequence.	Active-High
9	I ₀	LOGIC/DIAGNOSTIC INPUT A 16th external logic input to the AND array, as above, when exercised with standard TTL levels. When I ₀ is held at +10V, device outputs F ₀₋₅ reflect the contents of State Register bits P ₀₋₅ . The contents of the Output Register remain unaltered.	Active-High
[10-13] [15-18]	F ₀₋₇	LOGIC/DIAGNOSTIC OUTPUTS Eight device outputs which normally reflect the contents of Output Register bits Q ₀₋₅ , when enabled. When I ₀ is held at +10V, F ₀₋₅ = (P ₀₋₅), and F _{6, 7} = Logic "1".	Active-High
19	PR/ $\overline{O.E.}$	PRESET OR OUTPUT ENABLE INPUT A user programmable function: <ul style="list-style-type: none"> • PRESET Provides an asynchronous preset to logic "1" of all State and Output Register bits. Preset overrides Clock, and when held High, clocking is inhibited and F₀₋₇ are High. Normal clocking resumes with the first full clock pulse following a High-to-Low clock transition, after Preset goes Low. • OUTPUT ENABLE Provides an output enable function to buffers F₀₋₇ from the Output Register. 	Active-High Active-Low

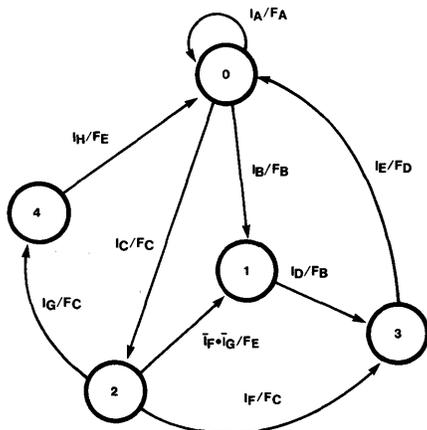
PROGRAMMABLE VARIABLES

The FPLS can be programmed with any clocked sequence expressed in terms of "control" variables, which are coupled to on-chip gates and flip-flops by means of programmable connections through Ni-Cr fusible links:

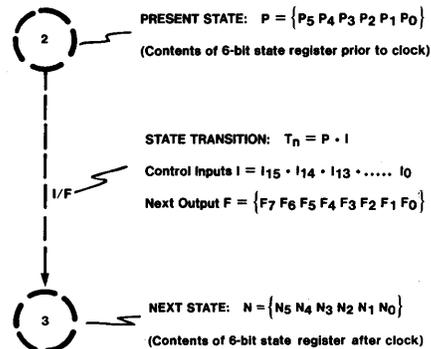
- (I) - External control inputs for state jump conditions.
- (P) - Present state, prior to clock.
- (C) - Complement variable for activating and generating the complement of programmed jump conditions.

- (T_n) - Transition "AND" terms including I, P.
- (N) - Next state, following clock.
- (F) - Next logic output, following clock.
- (P/E) - Asynchronous preset, or output enable function.

TYPICAL STATE DIAGRAM



TYPICAL STATE TRANSITION

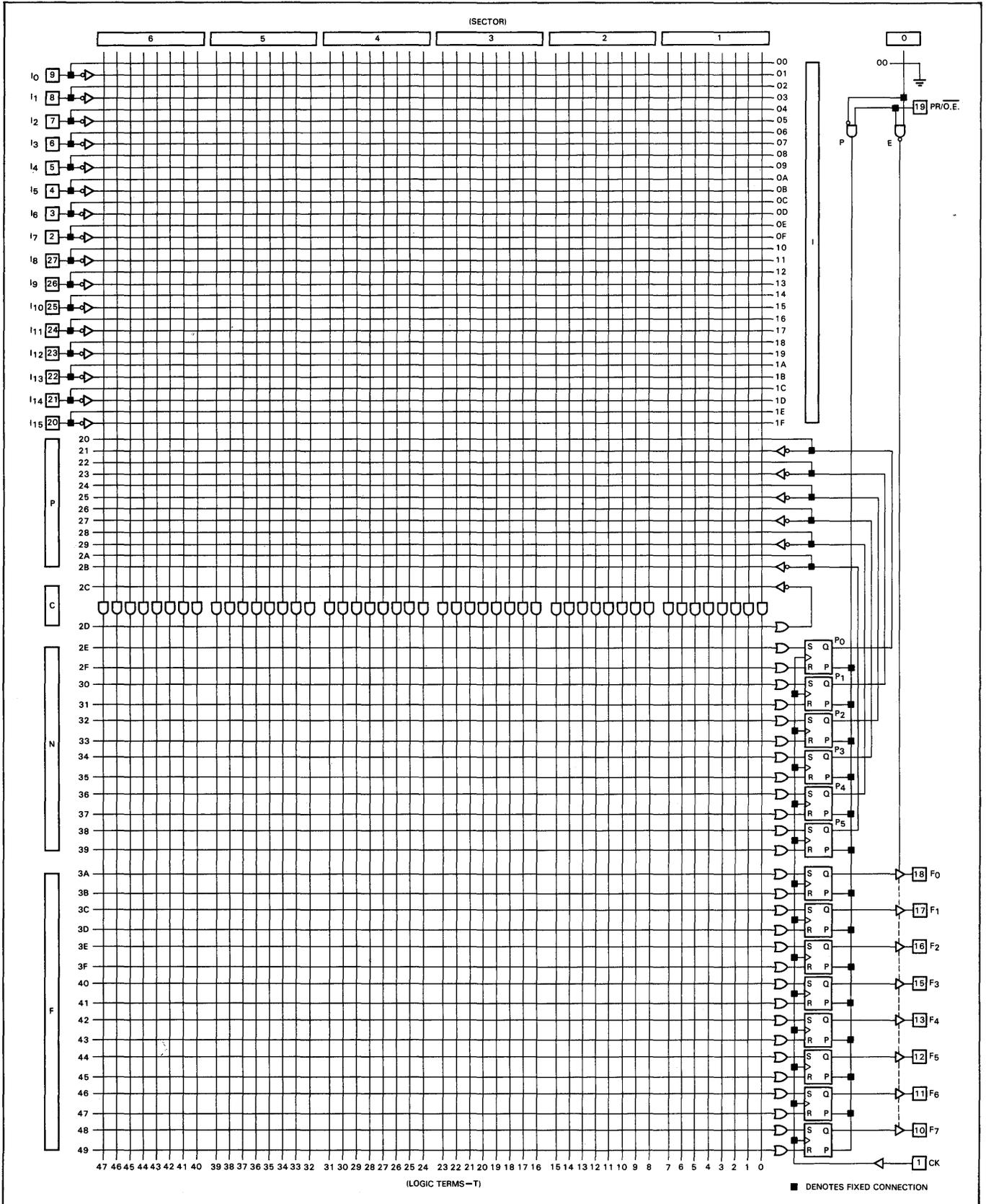


FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

FPLS LOGIC DIAGRAM

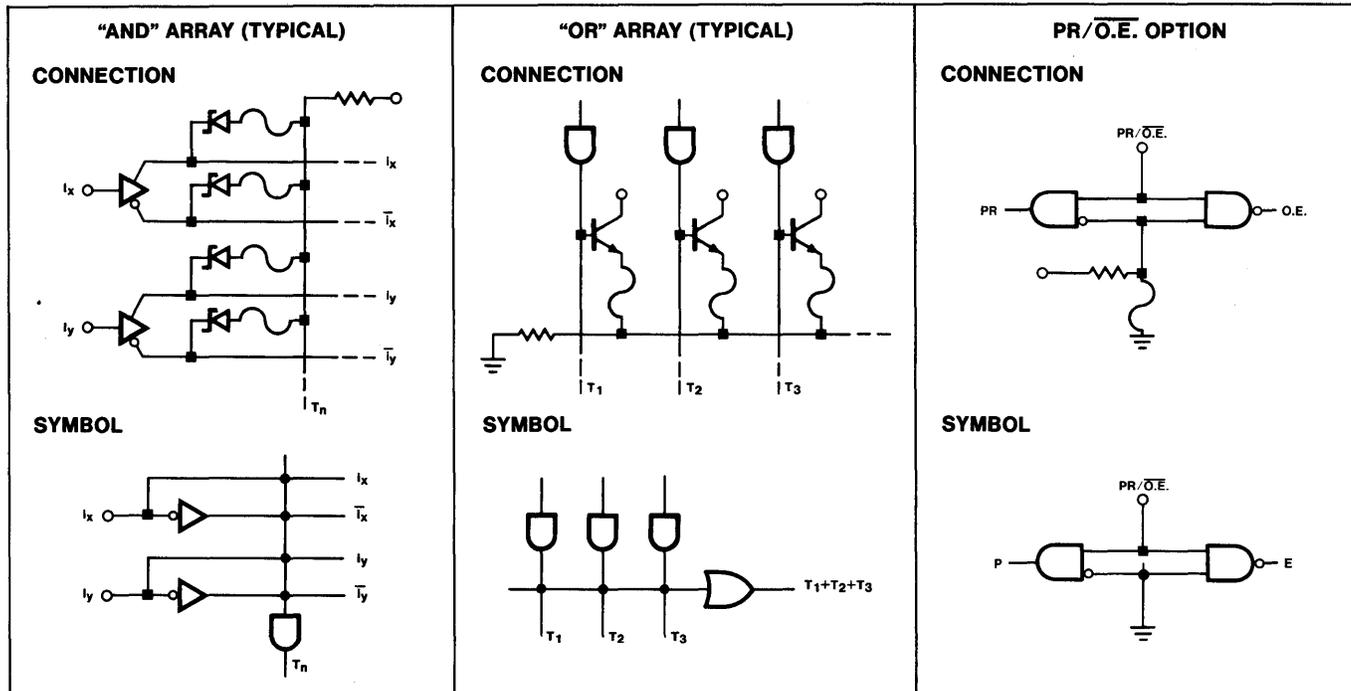


FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

PROGRAMMABLE CONNECTIONS (■ Denotes fixed connection)

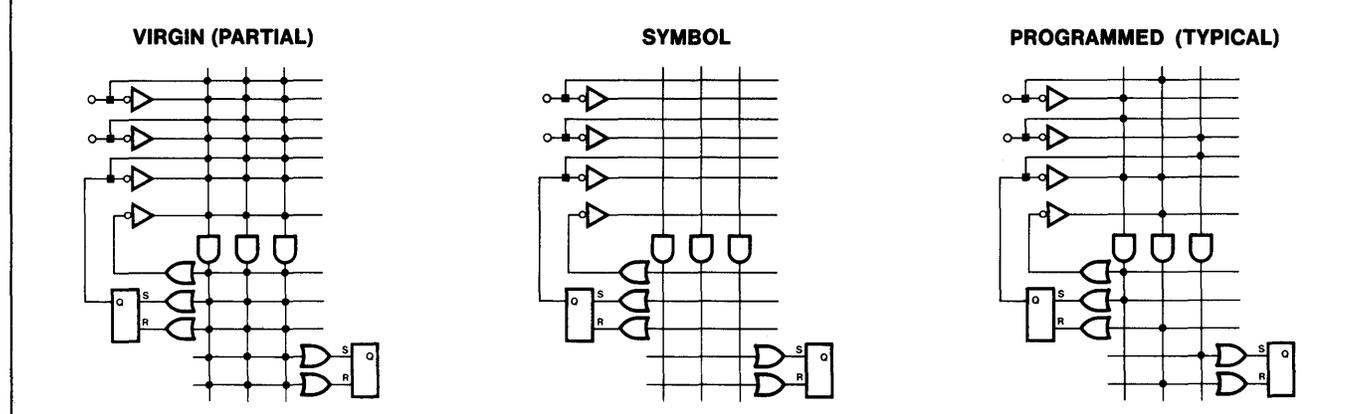


PROGRAMMING LEGEND

AND	OR	PR/O.E.	LINK	SYMBOL
			<p>CLOSED</p>	<p>OR</p>
			<p>OPEN</p>	

VIRGIN DEVICE

The FPLS is shipped with all internal links intact, so that a "dot" connection exists at all cross points in all arrays. For clarity, unprogrammed arrays are initially shown blank. The desired functional logic diagram is obtained by placing "dot" connections in used device areas where links remain intact. (Since both True and Complement input links of all AND gates are initially closed, all gates are disabled, preventing clocking. For testing purposes, clocking can occur via a factory programmed Test Array.



FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

FPLS ARCHITECTURE

The 82S104/105 Logic Sequencer is a programmable state machine of the Mealy type, in which the output is a function of the present state and the present input.

With the FPLS a user can program any logic sequence expressed as a series of jumps between stable states, triggered by a valid input condition (I) at clock time (t). All stable states are arbitrarily assigned and stored in the State Register. The logic output of the machine is also programmable, and is stored in the Output Register.

CLOCKED SEQUENCE

A synchronous logic sequence can be represented as a group of circles interconnected with arrows. The circles represent stable states, labeled with an arbitrary numerical code (binary, hex, etc.) corresponding to discrete states of a suitable register. The arrows represent state transitions, labeled with symbols denoting the jump condition and the required change in output. The number of states in the sequence depends on the length and complexity of the desired algorithm.

STATE JUMPS

The state from which a jump originates is referred as the present state (P), and the state to which a jump terminates is defined as the next state (N). A state jump always causes a change in state, but may or may not cause a change in machine output (F).

State jumps can occur only via "transition terms" T_n . These are logical AND functions of the clock (t), the present state (P), and a valid input (I). Since the clock is actually applied to the State Register, $T_n = t \cdot I \cdot P$. When T_n is "true", a control signal is generated and used at clock time (t) to force the contents of the State Register from (P) to (N), and to change the contents of the Output Register (if necessary). The simple state jump below, involving 2 inputs, 1 state bit, and 1 output bit, illustrates the equivalence of discrete and programmable logic implementations.

FPLS LOGIC STRUCTURE

The FPLS consists of programmable AND and OR gate arrays which control the Set and Reset inputs of a State Register, as well as monitor its output via an internal feedback path. The arrays also control an independent Output Register, added to store output commands generated during state transitions, and to hold the output constant during state sequences involving no output changes. If desired, any number of bits of the Output Register can be used to extend the width of the State Register, via external feedback.

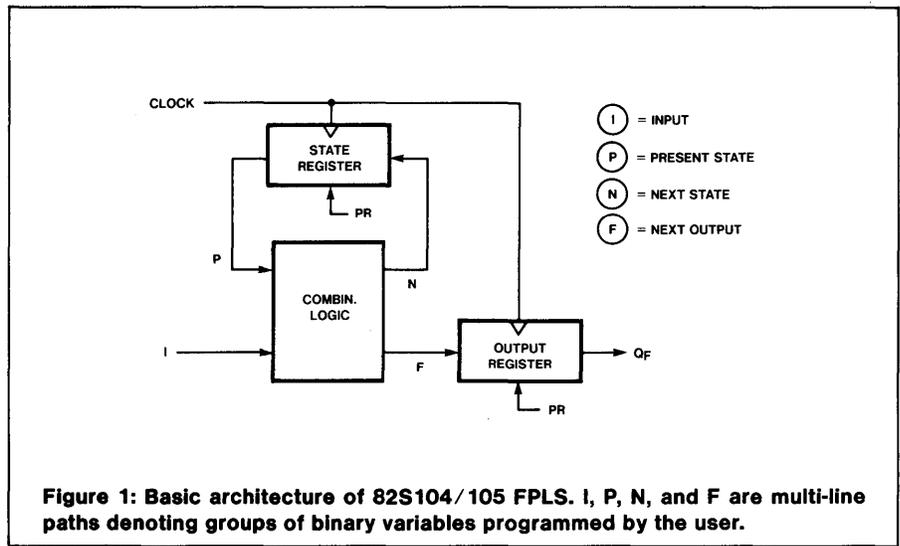


Figure 1: Basic architecture of 82S104/105 FPLS. I, P, N, and F are multi-line paths denoting groups of binary variables programmed by the user.

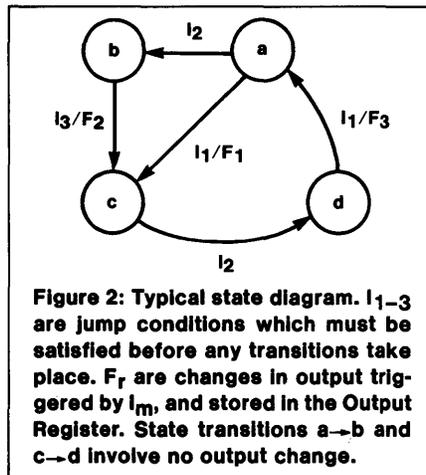


Figure 2: Typical state diagram. I_{1-3} are jump conditions which must be satisfied before any transitions take place. F_r are changes in output triggered by I_m , and stored in the Output Register. State transitions $a \rightarrow b$ and $c \rightarrow d$ involve no output change.

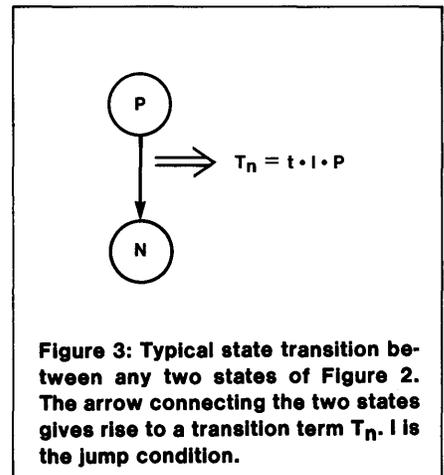


Figure 3: Typical state transition between any two states of Figure 2. The arrow connecting the two states gives rise to a transition term T_n . I is the jump condition.

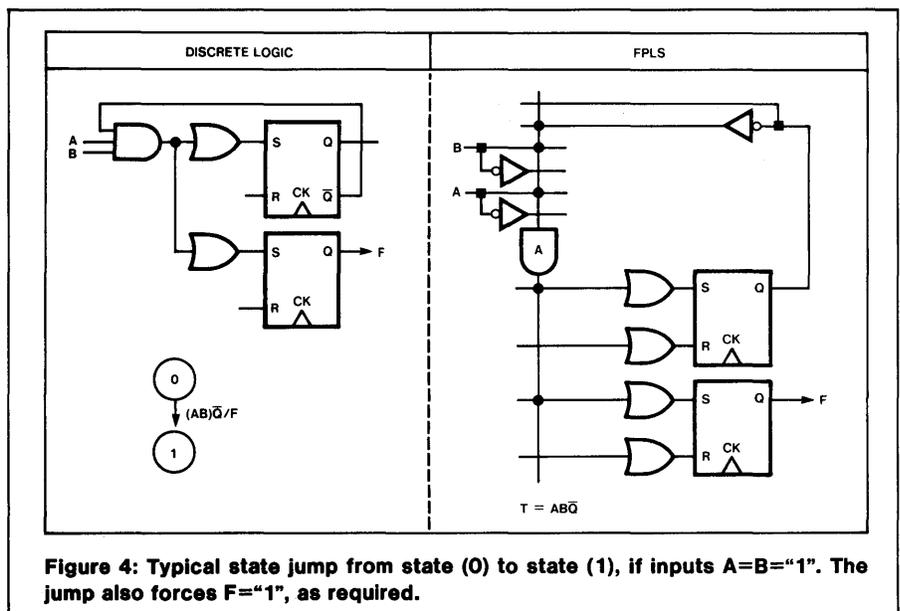
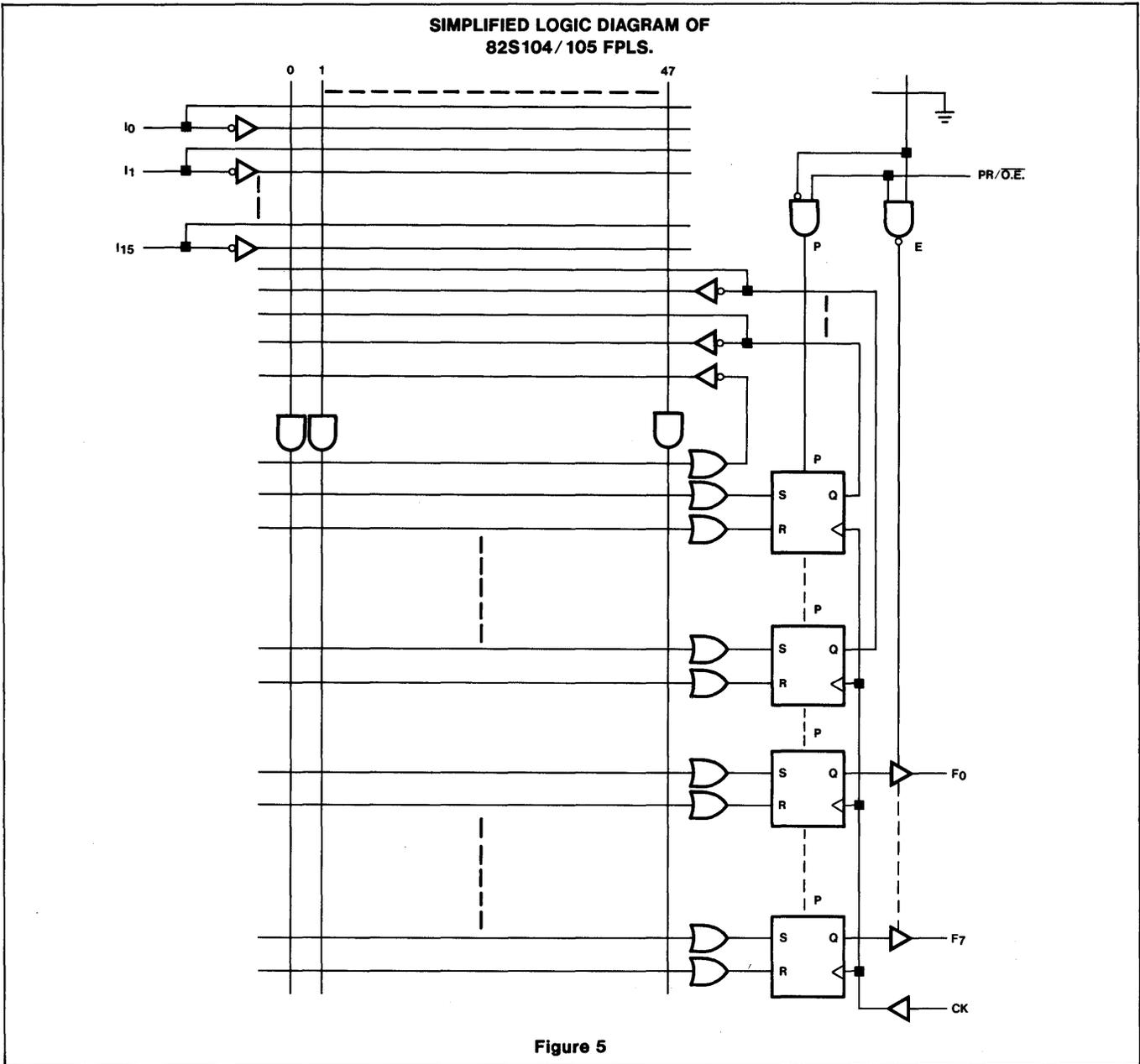


Figure 4: Typical state jump from state (0) to state (1), if inputs $A=B=1$. The jump also forces $F=1$, as required.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

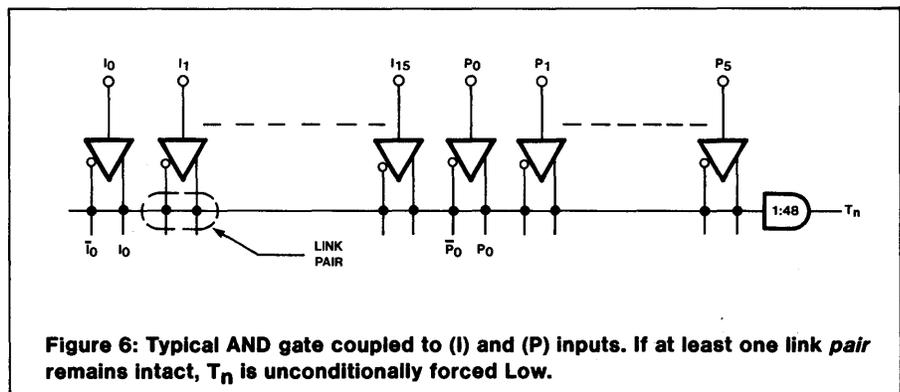
INTEGRATED FUSE LOGIC
SERIES 28



INPUT BUFFERS

16 external inputs (I_m) and 6 internal inputs (P_s), fed back from the state register, are combined in the AND array through two sets of True/Complement (T/C) buffers. There are a total of 22 T/C buffers, all connected to multi-input AND gates via fusible links which are initially intact.

Selective fusing of these links allows coupling either True, Complement, or Don't Care values of (I_m) and (P_s).



FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (I.S.)

INTEGRATED FUSE LOGIC
SERIES 28

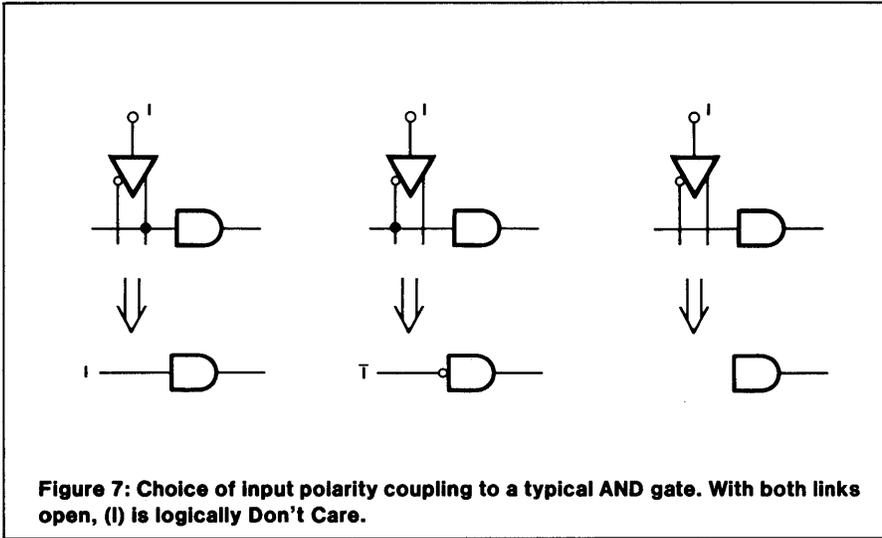


Figure 7: Choice of input polarity coupling to a typical AND gate. With both links open, (I) is logically Don't Care.

“AND” ARRAY

State jumps and output changes are triggered at clock time by valid transition terms T_n . These are logical AND functions of the present state (P) and the present input (I).

The FPLS AND array contains a total of 48 AND gates. Each gate has 45 inputs—44 connected to 22 T/C input buffers, and 1 dedicated to the Complement Array. The outputs of all AND gates are propagated through the OR array, and used at clock time (t) to force the contents of the State Register from (P) to (N). They are also used to control the Output Register, so that the FPLS 8-bit output F_r is a function of the inputs and present state.

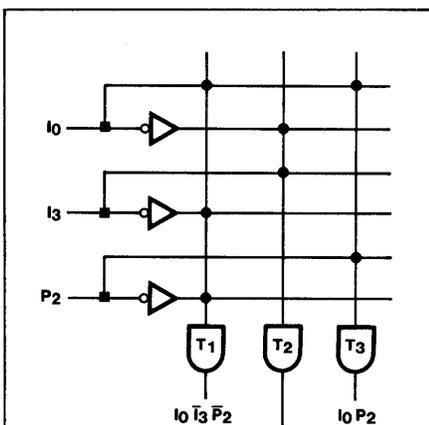


Figure 8: Typical transition terms involving arbitrary inputs and state variables. All remaining gate inputs are programmed Don't Care. Note that T_2 output is state independent.

“OR” ARRAY

In general, a clocked sequence will consist of several stable states and transitions, as determined by the complexity of the desired algorithm. All state and output changes in the state diagram imply changes in the contents of state and output registers.

Thus, each flip-flop in both registers may need to be conditionally set or reset several

times with T_n commands. This is accomplished by selectively ORing through a programmable OR array all AND gate outputs T_n necessary to activate the proper flip-flop control inputs.

The FPLS OR array consists of 14 pairs of OR gates, controlling the S/R inputs of 14 state and output register stages, and a single OR gate for the Complement Array. All gates have 48 inputs for connecting to all 48 AND gates.

COMPLEMENT ARRAY

The COMPLEMENT array provides an asynchronous feed back path from the OR array back to the AND array.

This structure enables the FPLS to perform both direct and complement sequential state jumps with a minimum of transition (AND) terms.

Typically direct jumps, such as T_1 and T_2 in Figure 11 require only a single AND gate each.

But a complement jump such as T_3 generally requires many AND gates if implemented as a direct jump. However, by using the complement array, the logic requirements for this type of jump can be handled with just one more gate from the AND array.

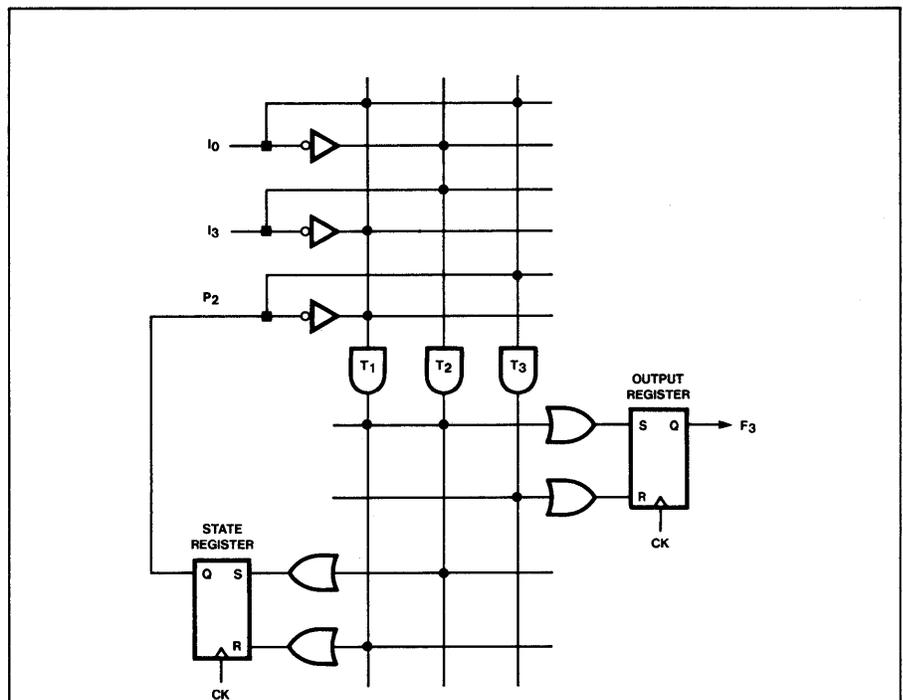


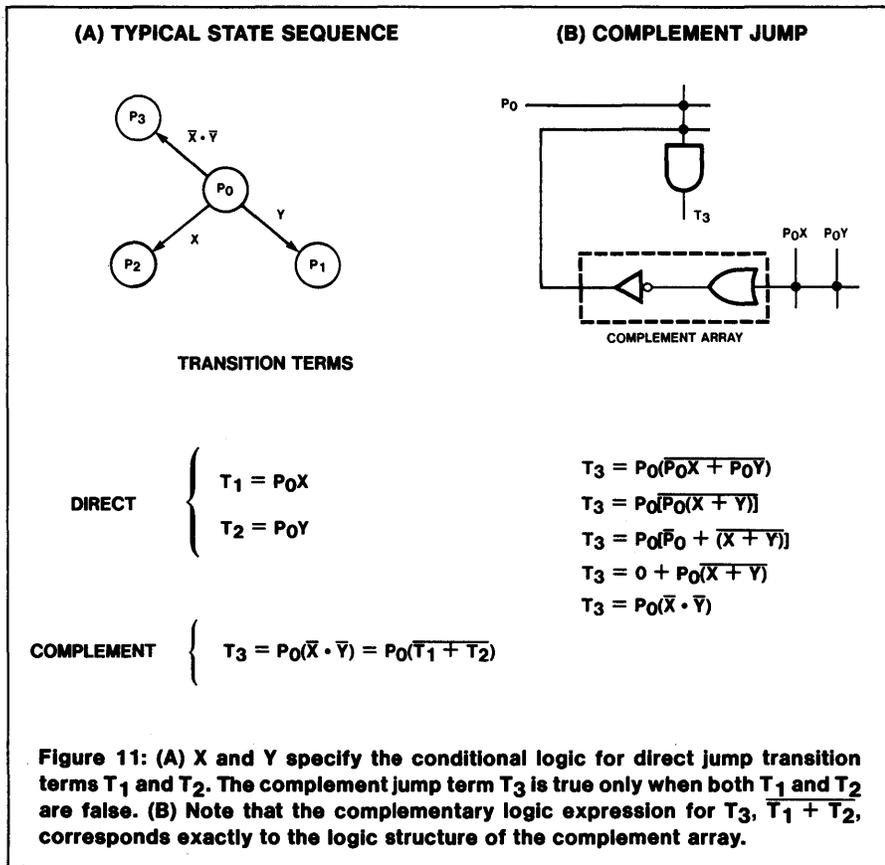
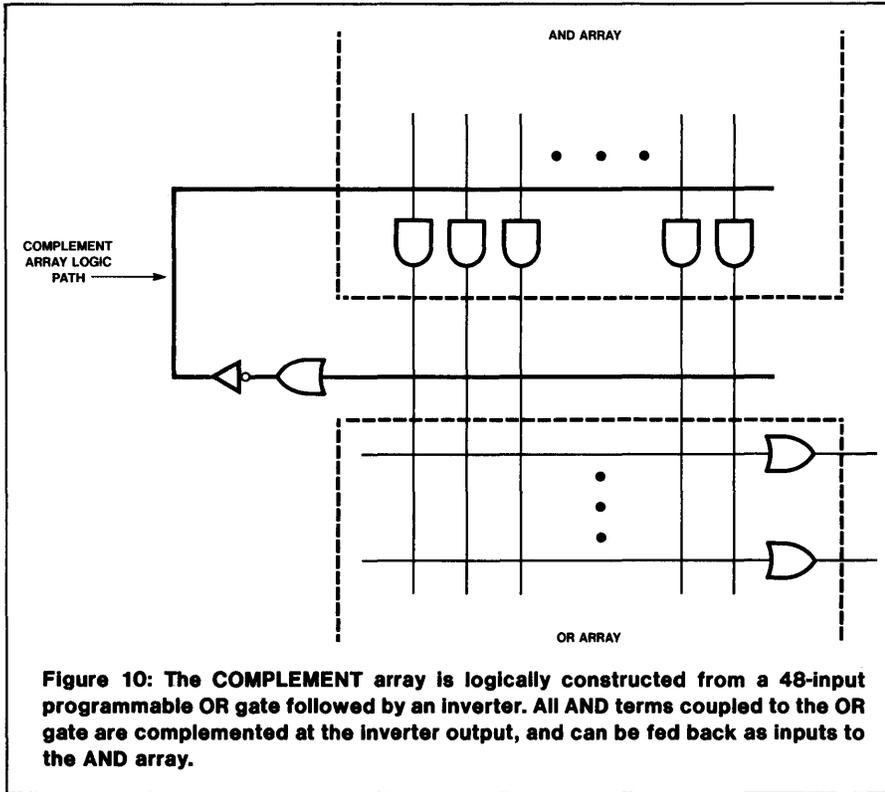
Figure 9: Typical OR array gating of transition terms $T_{1,2,3}$ controlling arbitrary state and output register stages.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

As indicated in Figure 12, the single complement array gate may be used for many states of the state diagram. This happens because all transition terms linked to the OR gate include the present state as a part of their conditional logic. In any particular state only those transition terms which are a function of that state are enabled; all other terms coupled to different states are disabled and do not influence the output of the complement array. As a general rule of thumb, the complement array can be used as many times as there are states.

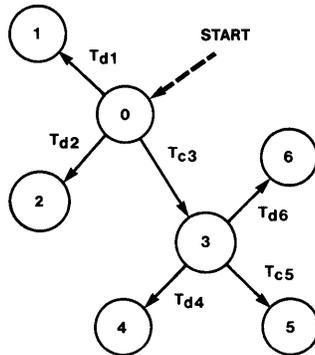


FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

(A) STATE DIAGRAM



(B) LOGIC DEFINITION

$$T_{d1} = I_0 \bar{I}_1 P_0$$

$$T_{d2} = I_2 P_0$$

$$T_{c3} = \overline{(T_{d1} + T_{d2}) P_0} = \overline{(I_0 \bar{I}_1 + I_2) P_0}$$

$$T_{d4} = \bar{I}_2 P_3$$

$$T_{d6} = I_0 I_1 P_3$$

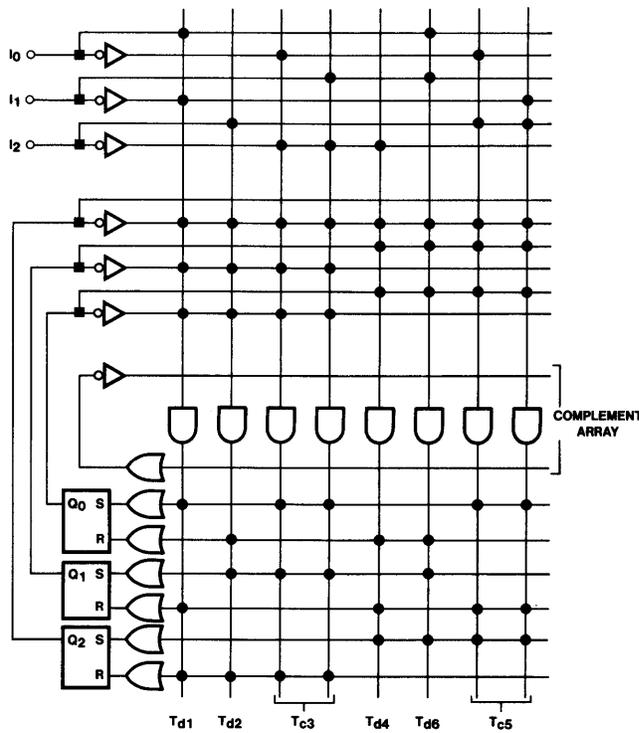
$$T_{c5} = \overline{(T_{d4} + T_{d6}) P_3} = \overline{(I_0 I_1 + \bar{I}_2) P_3}$$

T_{cn} = COMPLEMENT STATE TRANSITION TERM

T_{dn} = DIRECT STATE TRANSITION TERM

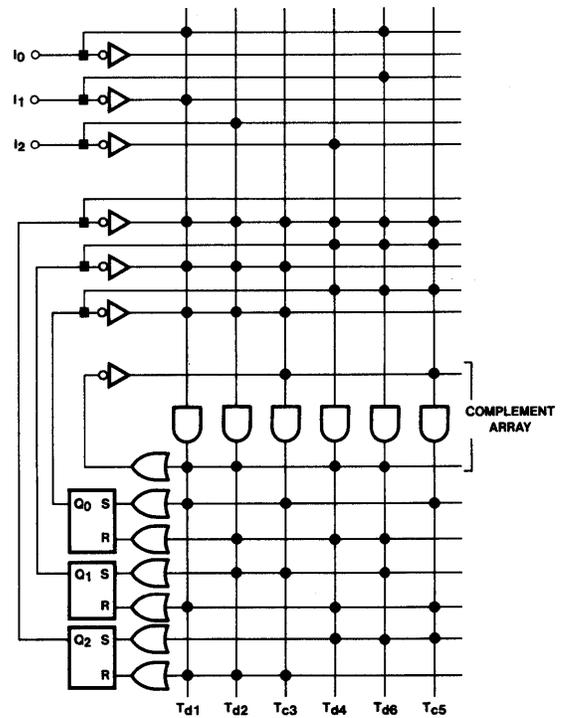
P_s = PRESENT STATE

(C) STATE LOGIC WITHOUT USING THE COMPLEMENT ARRAY



8 TRANSITION TERMS USED

(D) STATE LOGIC USING THE COMPLEMENT ARRAY



6 TRANSITION TERMS USED

Figure 12: Logic reduction with the complement array. The logic state diagram in (a) includes complement jumps T_{C3} and T_{C5} defined in (b). When using the complement array a savings of 2 transition terms results, as shown in (c) and (d).

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

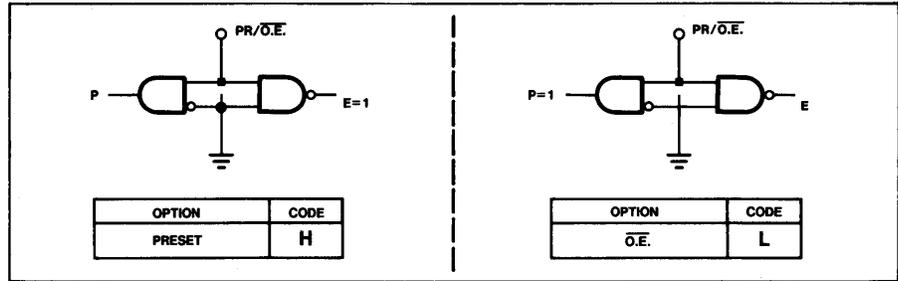
LOGIC PROGRAMMING

The FPLS can be programmed by means of Logic programming equipment.

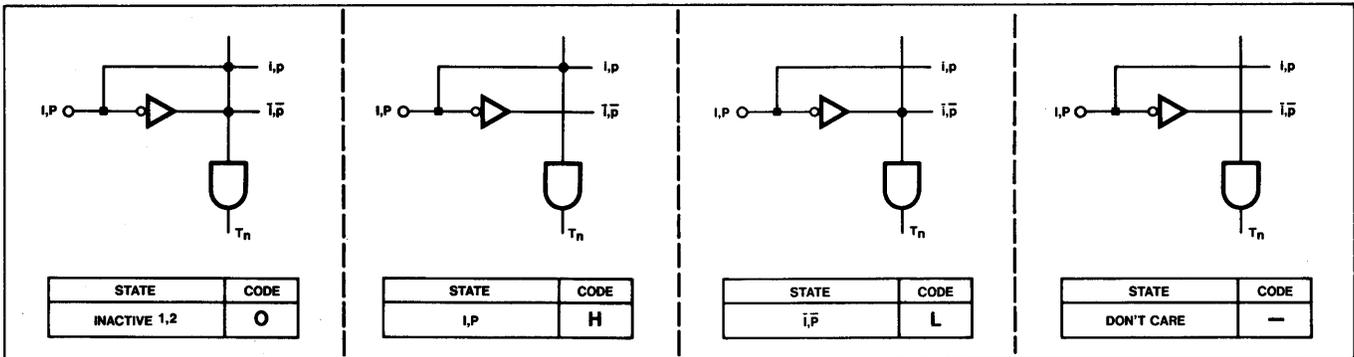
With Logic programming, the AND/OR gate input connections necessary to implement the desired logic function are coded directly from the State Diagram using the Program Table on the following page.

In this Table, the logic state or action of control variables C, I, P, N, and F, associated with each Transition Term T_n , is assigned a symbol which results in the proper fusing pattern of corresponding link pairs, defined as follows:

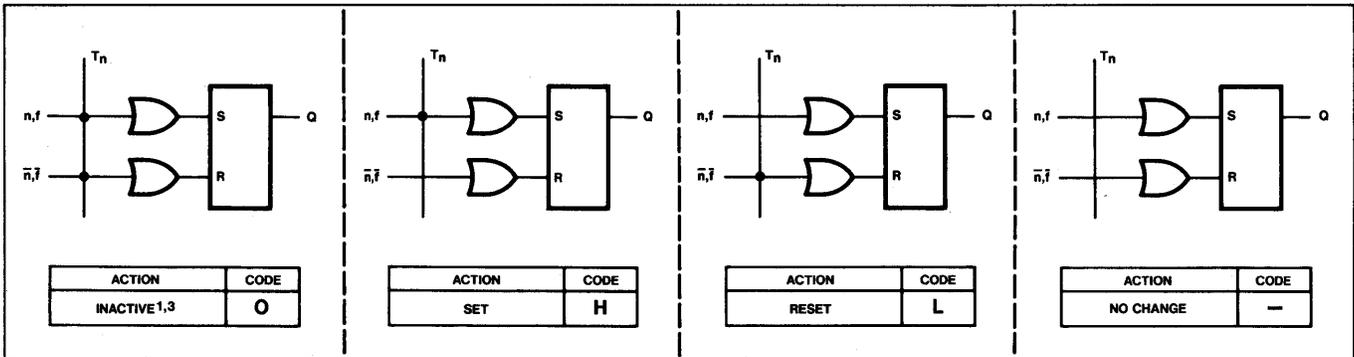
PRESET / $\overline{O.E.}$ OPTION - (P/E)



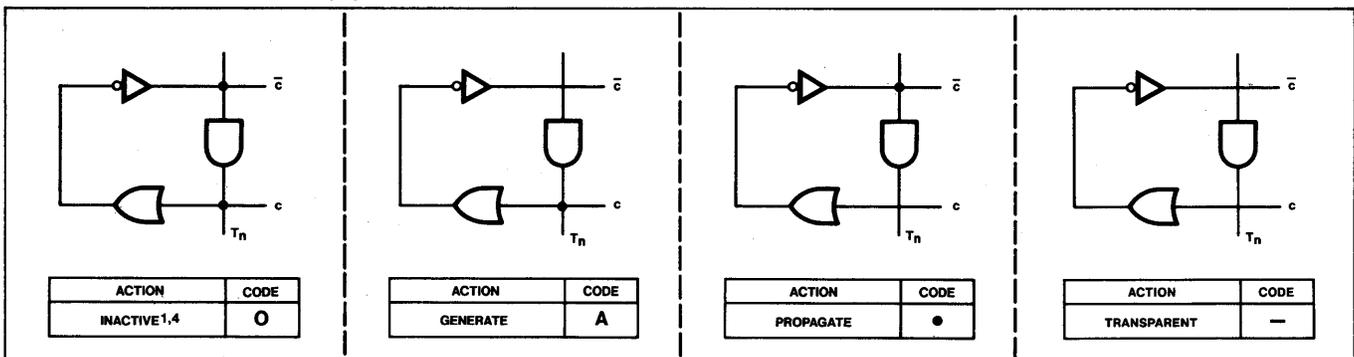
"AND" ARRAY - (I), (P)



"OR" ARRAY - (N), (F)



"COMPLEMENT ARRAY" - (C)



NOTES

1. This is the initial unprogrammed state of all link pairs. It is normally associated with all unused (inactive) AND gates T_n .
2. Any gate T_n will be unconditionally inhibited if any one of its I or P link pairs is left intact.

3. To prevent simultaneous Set and Reset flip-flop commands, this state is not allowed for N and F link pairs coupled to active gates T_n (see flip-flop truth tables).
4. To prevent oscillations, this state is not allowed for C link pairs coupled to active gates T_n .

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

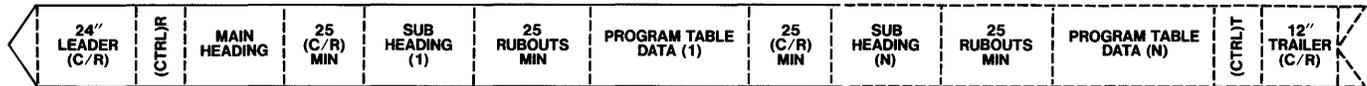
INTEGRATED FUSE LOGIC
SERIES 28

TWX TAPE CODING (LOGIC FORMAT)

The FPLS Program Table can be sent to Signetics in ASCII code format via airmail using any type of 8-level tape (paper, mylar,

fanfold, etc.), or via TWX: just dial (910) 339-9283, tell the operator to turn the paper puncher on, and acknowledge. At the end of transmission instruct the operator to send tape to Signetics Order Entry.

A number of Program Tables can be sequentially assembled on a continuous tape as follows, however, limit tape length to a roll of 1.75 inch inside diameter and 4.25 inch outside diameter.



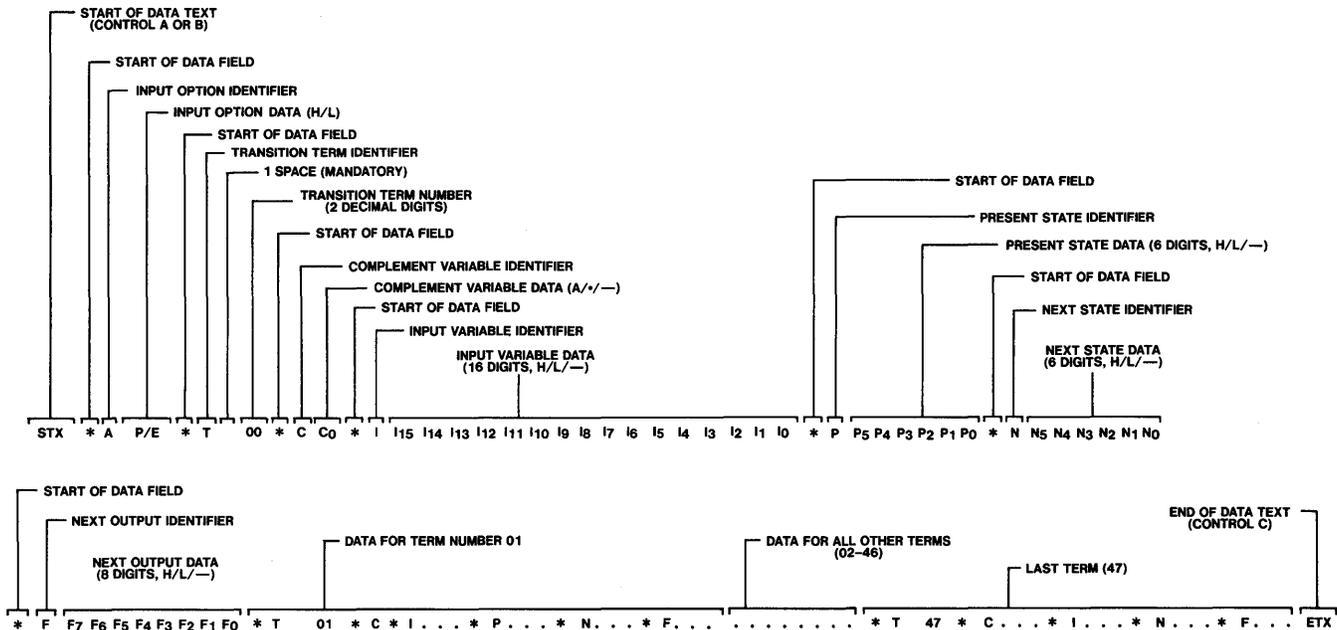
A. The MAIN HEADING at the beginning of tape includes the following information, with each entry preceded by a (\$) character, whether used or not:

1. Customer Name _____
2. Customer TWX No. _____
3. Date _____
4. Purchase Order No. _____
5. Number of Program Tables _____
6. Total Number of Parts _____

B. Each SUB HEADING should contain specific information pertinent to each Program Table as follows, with each entry preceded by a (\$) character, whether used or not:

1. Signetics Device No. _____
2. Program Table No. _____
3. Revision _____
4. Date _____
5. Customer Symbolized Part No. _____
6. Number of Parts _____

C. Program Table data blocks are initiated with an STX character, and terminated with an ETX character. The body of the data consists of preset/output enable option, transition term, and output term information separated by appropriate identifiers in accordance with the following format:



FIELD PROGRAMMABLE LOGIC SEQUENCER**82S104 (O.C.)/82S105 (T.S.)**INTEGRATED FUSE LOGIC
SERIES 28

Entries for the Data Fields are determined in accordance with the following Table:

COMPLEMENT VARIABLE (C)			PRESENT STATE (P_s)/INPUT (I_m)			NEXT STATE (N_s)/OUTPUT (F_n)			OPTION (P/E)	
GENERATE	PROPA-GATE	TRANS-PARENT	I_m, P_s	$\overline{I_m}, \overline{P_s}$	DON'T CARE	N_s, F_n	$\overline{N_s}, \overline{F_n}$	NO CHANGE	PRESET	OUTPUT ENABLE
A	•	—	H	L	—	H	L	—	H	L

Although the Transition Term data are shown entered in sequence, this is not necessary. It is possible to input only one Transition Term, if desired. Unused Transition Terms require no entry. ETX signalling end of Program Table may occur with less than the maximum number of Transition Terms entered.

NOTES

1. Corrections to any entry can be made by backspace and rubout. However, limit consecutive rubouts to less than 25.
2. T-terms can be re-entered any number of times. The last entry for a particular T-term will be interrupted as valid data.
3. To facilitate an orderly Teletype printout, carriage returns, line feeds, spaces, rubouts, etc., may be interspersed between data groups.
4. Comments are allowed between data fields provided that an asterisk (*) is not used in any Heading or Comment entry.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

ABSOLUTE MAXIMUM RATINGS¹

PARAMETER	RATING		UNIT
	Min	Max	
V _{CC}	Supply voltage	+7	Vdc
V _{IN}	Input voltage	+5.5	Vdc
V _{OUT}	Output voltage	+5.5	Vdc
I _{IN}	Input currents	-30	mA
I _{OUT}	Output currents	+100	mA
T _A	Temperature range		°C
T _A	Operating		
	N82S104 / 105	0	+75
T _{STG}	S82S104 / 105	-55	+125
	Storage	-65	+150

THERMAL RATINGS

TEMPERATURE	MILI-TARY	COM-MER-CIAL
Maximum junction	175°C	150°C
Maximum ambient	125°C	75°C
Allowable thermal rise ambient to junction	50°C	75°C

DC ELECTRICAL CHARACTERISTICS

N82S104 / 105: 0° ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S104 / 105: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TEST CONDITIONS	N82S104 / 105			S82S104 / 105			UNIT
		Min	Typ ²	Max	Min	Typ ²	Max	
V _{IH} V _{IL} V _{IC}	Input voltage ³ High Low Clamp ^{3,4} V _{CC} = Max V _{CC} = Min V _{CC} = Min, I _{IN} = -18mA	2		0.85	2		0.8	V
V _{OH} V _{OL}	Output voltage High (82S105) ^{3,5} Low ^{3,6} V _{CC} = Min I _{OH} = -2mA I _{OL} = 9.6mA	2.4	0.35	0.45	2.4	0.35	0.50	V
I _{IH} I _{IL} I _{IL}	Input current High Low Low (CK input) V _{IN} = 5.5V V _{IN} = 0.45V V _{IN} = 0.45V		<1 -10 -50	25 -100 -250		<1 -10 -50	50 -150 -350	μA
I _{OLK} I _{O(OFF)} I _{OS}	Output current Leakage ⁷ Hi-Z state (82S105) ⁷ Short circuit (82S105) ^{4,8} V _{CC} = Max V _{OUT} = 5.5V V _{OUT} = 5.5V V _{OUT} = 0.45V V _{OUT} = 0V		1 1 -1	40 40 -40 -70		1 1 -1	60 60 -60 -85	μA μA mA
I _{CC}	V _{CC} supply current ⁹ V _{CC} = Max		120	180		120	185	mA
C _{IN} C _{OUT}	Capacitance ⁷ Input Output V _{CC} = 5.0V V _{IN} = 2.0V V _{OUT} = 2.0V		8 10			8 10		pF

NOTES

- Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device of these or any other condition above those indicated in the operation of the device specifications is not implied.
- All typical values are at V_{CC} = 5V, T_A = 25°C.
- All voltage values are with respect to network ground terminal.
- Test one at a time.
- Measured with V_{IL} applied to $\overline{O.E.}$ and a logic high stored, or with V_{IH} applied to PR.
- Measured with a programmed logic condition for which the output is at a low logic level, and V_{IL} applied to PR/ $\overline{O.E.}$. Output sink current is supplied thru a resistor to V_{CC}.
- Measured with V_{IH} applied to PR/ $\overline{O.E.}$.
- Duration of short circuit should not exceed 1 second.
- I_{CC} is measured with the PR/ $\overline{O.E.}$ input grounded, all other inputs at 4.5V and the outputs open.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

AC ELECTRICAL CHARACTERISTICS

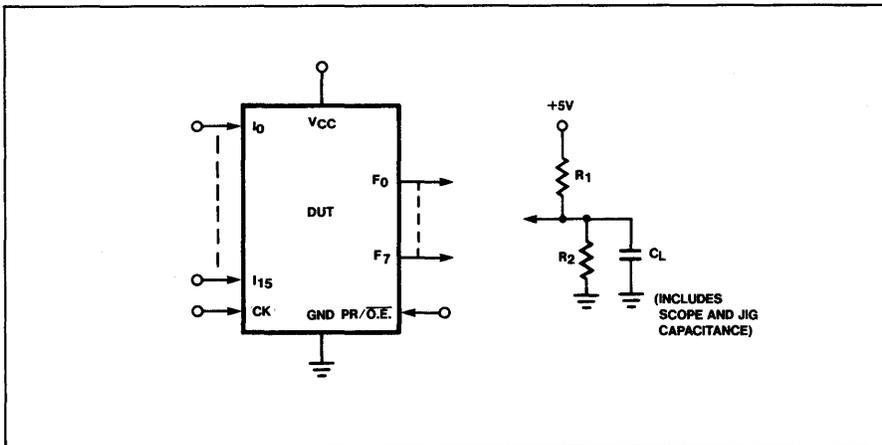
$R_1 = 470\Omega$, $R_2 = 1k\Omega$, $C_L = 30pF$
 N82S104/105: $0^\circ C \leq T_A \leq +75^\circ C$, $4.75V \leq V_{CC} \leq 5.25V$
 S82S104/105: $-55^\circ C \leq T_A \leq +125^\circ C$, $4.5V \leq V_{CC} \leq 5.5V$

PARAMETER	TO	FROM	N82S104/105			S82S104/105			UNIT
			Min	Typ ²	Max	Min	Typ ²	Max	
Pulse width TCKH Clock ³ high TCKL Clock low TCKP Period (w/o c-array) TPRH Preset pulse	CK-	CK+	30	15		40	15		ns
	CK+	CK-	30	15		40	15		
	CK+	CK+	90	65		120	65		
	PR+	PR-	25	15		40	15		
Set up time TIS1 Input TIS2 Input (through Complement array) ⁴ TVS Power-on preset TPRS Preset	CK+	Input \pm	60	40		80	40		ns
	CK+	Input \pm	90	70		120	70		
	CK-	V _{CC} +	0	-10		5	10		
	CK-	PR-	0	-10		5	-10		
TIH Hold time Input	Input \pm	CK+		-10	5		-10	10	ns
Propagation delay TCKO Clock TOE Output enable TOD Output disable TPR Preset TPPR Power-on preset	Output \pm	CK+		25	30		25	40	ns
	Output-	O.E.-		20	30		20	40	
	Output+	O.E.+		20	30		20	40	
	Output+	PR+		25	35		25	45	
	Output+	V _{CC} +		0	10		0	20	

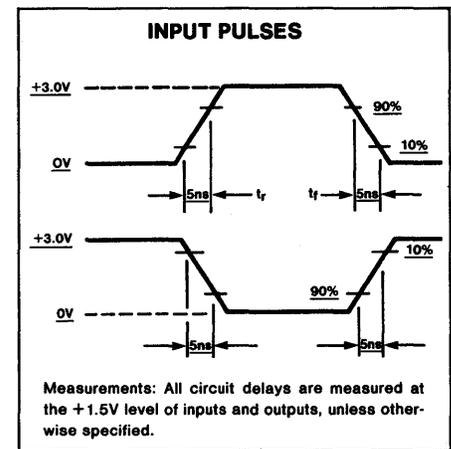
NOTE

1. All typical values are at $V_{CC} = 5V$, $T_A = 25^\circ C$.
2. Diagnostic mode only.
3. To prevent spurious clocking, clock rise time (10%-90%) $\leq 10ns$.
4. When using the Complement Array, $T_{CKP} = 120ns$ (min).

TEST LOAD CIRCUIT



VOLTAGE WAVEFORM

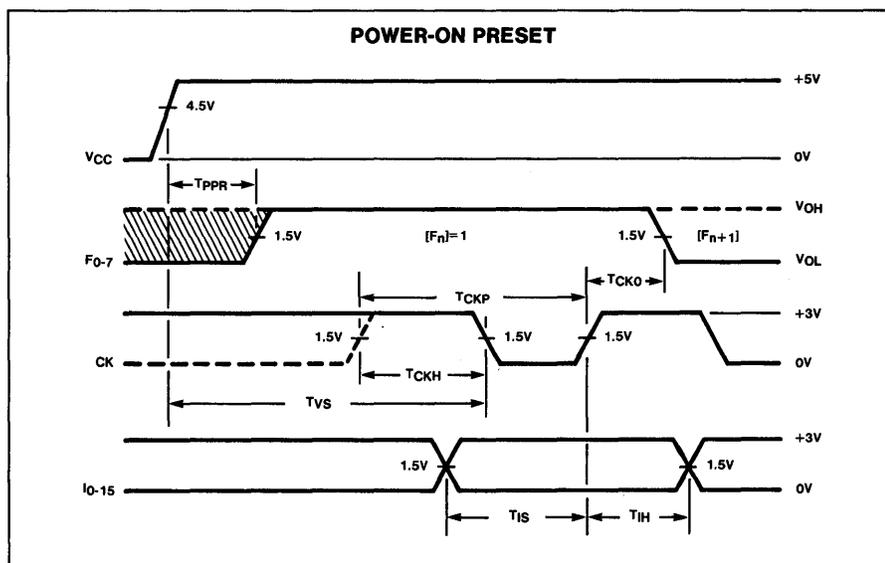
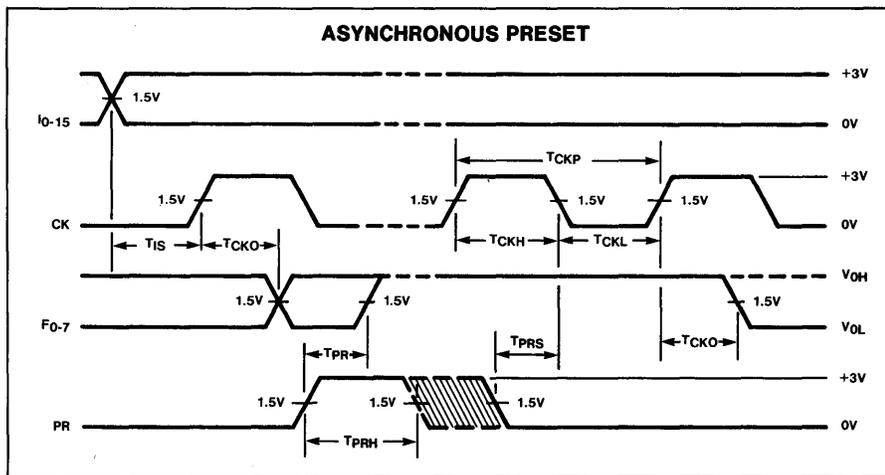
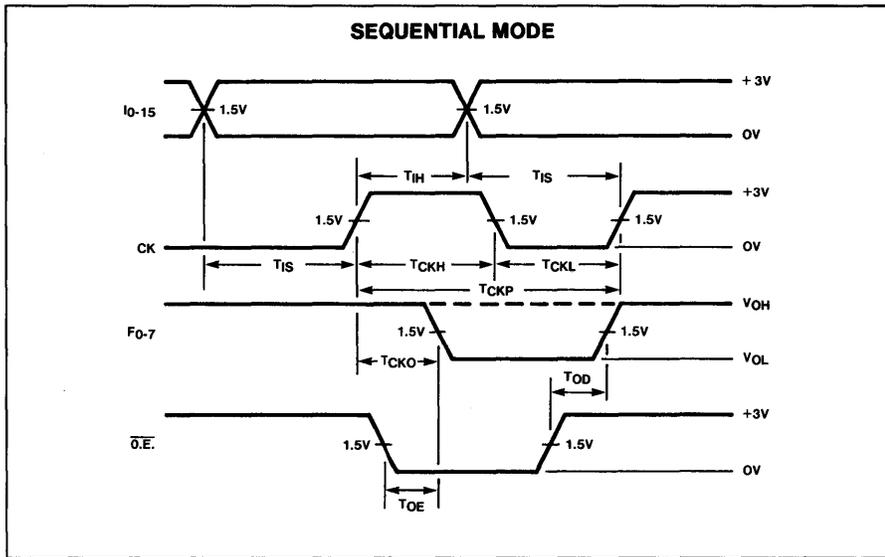


FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

TIMING DIAGRAMS

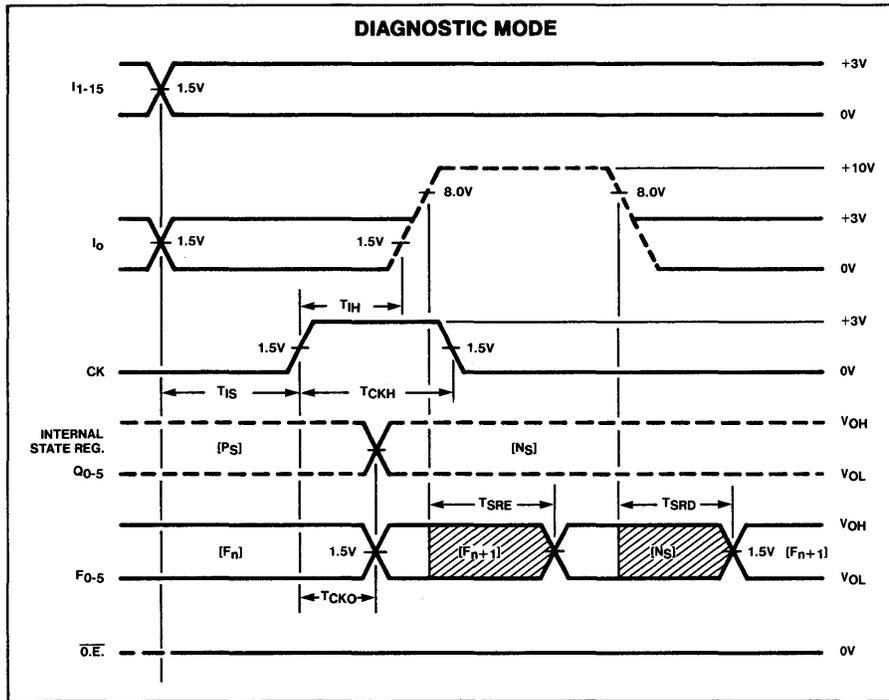


FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (I.S.)

INTEGRATED FUSE LOGIC
SERIES 28

TIMING DIAGRAMS (Cont'd)



TIMING DEFINITIONS

- TCKH** Width of input clock pulse.
- TCKL** Interval between clock pulses.
- TCKP** Clock period.
- TIS1** Required delay between beginning of valid Input and positive transition of clock.

- TIS2** Required delay between beginning of valid Input and positive transition of clock, when using optional Complement Array (two passes necessary through the AND array).
- Tvs** Required delay between V_{CC} (after power-on) and negative transition of

clock preceding first reliable clock pulse.

- TPRS** Required delay between negative transition of asynchronous Preset and negative transition of clock preceding first reliable clock pulse.
- TIH** Required delay between positive transition of clock and end of valid Input data.
- TCKO** Delay between positive transition of clock and when Outputs become valid (with $PR/\overline{O.E.}$ low).
- TOE** Delay between beginning of Output Enable Low and when Outputs become valid.
- TOD** Delay between beginning of Output Enable High and when Outputs are in the off state.
- TSRE** Delay between input I_0 transition to Diagnostic mode and when the Outputs reflect the contents of the State Register.
- TSRD** Delay between input I_0 transition to Logic mode and when the Outputs reflect the contents of the Output Register.
- TPR** Delay between positive transition of Preset and when Outputs become valid at "1".
- TPPR** Delay between V_{CC} (after power-on) and when Outputs become preset at "1".
- TPRH** Width of preset input pulse.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28**VIRGIN STATE 1,2,3**

A factory shipped virgin device contains all fusible links intact, such that:

1. PR/ \overline{OE} option is set to PR.
2. All T_n terms are disabled.
4. All S/R flip-flop inputs are disabled.
5. Test array is programmed with standard test pattern.

**RECOMMENDED PROGRAMMING
PROCEDURE**

To program the AND, OR, and Complement arrays in addition to the PR/ \overline{OE} option the following procedure should be followed. To maximize recovery from programming errors, leave all links in unused device areas intact.

SET-UP

Terminate all device outputs with a 10k Ω resistor to V_{CC} . Set GND (pin 14) to 0V.

PROGRAM PR/ \overline{OE} OPTION

1. With PR/ \overline{OE} (pin 19) at GND, raise V_{CC} to V_{CCP} .
2. After t_D delay pulse PR/ \overline{OE} to V_{ix} for a duration of t_p .
3. t_D delay after PR/ \overline{OE} has returned to GND, lower V_{CC} to V_{CCV} or GND.

VERIFY PR/ \overline{OE} OPTION

1. With PR/ \overline{OE} at GND, set V_{CC} to V_{CCV} .
2. After a delay of t_D raise PR/ \overline{OE} to V_{ix} for a minimum duration of T_{RS} .
3. Return PR/ \overline{OE} to GND with a fall time less than T_f .
4. After t_D delay, pulse PR/ \overline{OE} to V_{IH} for a minimum duration of T_{ps} .
5. After t_D delay, F_O (pin 18) indicates V_{OH} if the PR option is selected and V_{OL} if the \overline{OE} option is programmed.

NOTES

1. All outputs will be at "1", as preset by initial power-up procedure.
2. Device can be clocked via test array function.
3. Test array function MUST be deleted before incorporating user program.

PROGRAM-VERIFY "AND" ARRAY

1. **SET-UP:**
With V_{CC} at GND and CK at V_{CKV} , select the fuse to be programmed by applying TTL voltage levels to input sets I_{0-5} and I_{7-13} in accordance with the binary address map on page 21. Also set $I_{15} = V_{IH}$, and $I_{14} = V_{IL}$. After t_D delay raise V_{CC} to V_{CCP} .
2. **PROGRAM CYCLE:**
After a delay of t_D raise I_{14} to V_{IH} . Proceed after another t_D delay to raise CK to V_{CKP} . Following still another t_D delay, pulse I_{15} to V_{IL} for a duration of t_p . t_D later return CK to V_{CKV} , and then t_D after that return I_{14} to V_{IL} .
3. **VERIFY CYCLE:**
After a t_D delay lower I_{15} to V_{IL} for a duration of t_v . At the end of t_v , F_O should indicate a level of V_{OH} ; a level of V_{OL} indicates an unsuccessful fusing attempt.
4. **NEXT VARIABLE SELECT (C,Im,Ps) (SAME TERM T_n):**
After t_D delay, apply the next variable select (C,Im,Ps) address to I_{7-13} , then continue with step 2.
5. **NEXT VARIABLE SELECT (C,Im,Ps) (DIFFERENT TERM T_n):**
After t_D delay apply the next variable select (C,Im,Ps) and term (T_n) addresses to respectively I_{7-13} and I_{0-5} , then continue to step 2.

PROGRAM-VERIFY "OR" ARRAY

1. **SET-UP:**
With V_{CC} at GND and CK at V_{CKV} , select the fuse to be programmed by applying TTL voltage levels to input sets I_{0-5} and I_{7-13} in accordance with the binary address map on page 21. Also set $I_{14} = V_{IL}$, and $I_{15} = V_{IH}$. After t_D delay raise V_{CC} to V_{CCP} .
2. **PROGRAM CYCLE:**
After a delay of t_D raise I_{14} to V_{IH} . Proceed after another t_D delay to raise CK

to V_{CKP} . Following still another t_D delay pulse I_{15} to V_{IL} for a duration of t_p . t_D later return CK to V_{CKV} and then t_D after that return I_{14} to V_{IL} .

3. **VERIFY CYCLE:**
After a t_D delay lower I_{15} to V_{IL} for a duration of t_v . At the end of t_v F_O should indicate a level of V_{OH} ; a level of V_{OL} indicates an unsuccessful fusing attempt.
4. **NEXT VARIABLE SELECT (C,Ns,Fn) (SAME TERM (T_n)):**
After t_D delay apply the next variable select (C,Ns,Fn) address to I_{7-13} , then continue with step 2.
5. **NEXT VARIABLE SELECT (C,Ns,Fn) (DIFFERENT TERM (T_n)):**
After t_D delay apply the next variable select (C,Ns,Fn) and term (T_n) addresses to respectively I_{7-13} and I_{0-5} , then continue to step 2.

PROGRAM CYCLE POWER DOWN

When programming of the device is complete, after t_D delay set I_{15} to V_{IH} , I_{14} to V_{IL} and CK to V_{CKV} . After another t_D delay reduce V_{CC} to 0V.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

PROGRAM CYCLE ROW/COLUMN FUSE ADDRESSING

VARIABLE SELECT Table 1

ROW HEX ADDRESS		SELECTED VARIABLE	ROW HEX ADDRESS		SELECTED VARIABLE		
I ₁₃ I ₁₂ I ₁₁	I ₁₀ I ₉ I ₈ I ₇		I ₁₃ I ₁₂ I ₁₁	I ₁₀ I ₉ I ₈ I ₇			
0	0	N ₀	SET	4	0	AND Array	I ₀
0	1		RESET	4	1		I ₀
0	2	N ₁	SET	4	2		I ₁
0	3		RESET	4	3		I ₁
0	4	N ₂	SET	4	4		I ₂
0	5		RESET	4	5		I ₂
0	6	N ₃	SET	4	6		I ₃
0	7		RESET	4	7		I ₃
0	8	N ₄	SET	4	8		I ₄
0	9		RESET	4	9		I ₄
0	A	N ₅	SET	4	A		I ₅
0	B		RESET	4	B		I ₅
0	C	F ₀	SET	4	C		I ₆
0	D		RESET	4	D		I ₆
0	E	F ₁	SET	4	E		I ₇
0	F		RESET	4	F		I ₇
1	0	F ₂	SET	5	0		I ₈
1	1		RESET	5	1		I ₈
1	2	F ₃	SET	5	2		I ₉
1	3		RESET	5	3		I ₉
1	4	F ₄	SET	5	4		I ₁₀
1	5		RESET	5	5		I ₁₀
1	6	F ₅	SET	5	6		I ₁₁
1	7		RESET	5	7		I ₁₁
1	8	F ₆	SET	5	8		I ₁₂
1	9		RESET	5	9		I ₁₂
1	A	F ₇	SET	5	A		I ₁₃
1	B		RESET	5	B		I ₁₃
1	C	Complement Array	SET	6	C	I ₁₄	
			RESET	6	C	I ₁₄	
1	D	Empty Address Space		6	0	P ₀	
				6	1	P ₀	
				6	2	P ₁	
				6	3	P ₁	
				6	4	P ₂	
				6	5	P ₂	
				6	6	P ₃	
				6	7	P ₃	
			6	8	P ₄		
			6	9	P ₄		
			6	A	P ₅		
			6	B	P ₅		
			6	C	Complement Array		
					C		

TRANSITION TERM SELECT Table 2

COLUMN HEX ADDRESS		SELECTED TRANSITION TERM
I ₅ I ₄	I ₃ I ₂ I ₁ I ₀	
0	0	0
0	1	1
0	2	2
0	3	3
0	4	4
0	5	5
0	6	6
0	7	7
0	8	8
0	9	9
0	A	10
0	B	11
0	C	12
0	D	13
0	E	14
0	F	15
1	0	16
1	1	17
1	2	18
1	3	19
1	4	20
1	5	21
1	6	22
1	7	23
1	8	24
1	9	25
1	A	26
1	B	27
1	C	28
1	D	29
1	E	30
1	F	31
2	0	32
2	1	33
2	2	34
2	3	35
2	4	36
2	5	37
2	6	38
2	7	39
2	8	40
2	9	41
2	A	42
2	B	43
2	C	44
2	D	45
2	E	46
2	F	47
3	0	48
3	1	49

NOTES

1. A row address identifies a particular variable coupled to all transition terms.
2. With a variable selected by the row address the column address further selects a coupling fuse for each term.

FIELD PROGRAMMABLE LOGIC SEQUENCER

82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

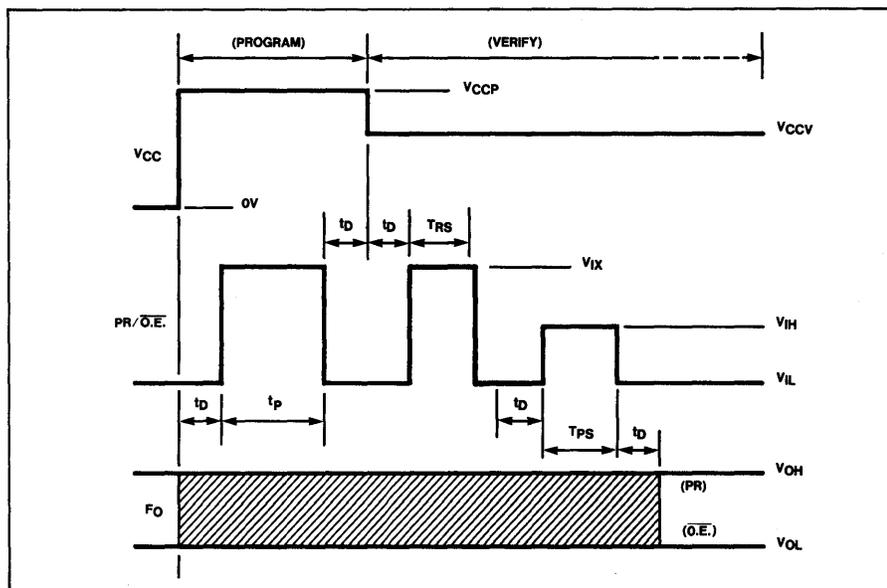
PROGRAMMING SYSTEM SPECIFICATIONS¹ (T_A = +25°C)

PARAMETER	TEST CONDITIONS	LIMITS			UNIT
		Min	Typ	Max	
V _C CP	V _{CC} supply (program)	8.25	8.5	8.75	V
V _C CV	V _{CC} supply (verify)	4.75	5.0	5.25	V
I _{CC} P	I _{CC} limit program	550		1,000	mA
V _I H	Input voltage High	2.4		5.5	V
V _I L	Input voltage Low	0	0.4	0.8	V
I _I H	Input Current High			50	μA
I _I L	Input Current Low			-500	μA
V _I X	O.E. program enable level	9.5	10	10.5	V
I _I X	O.E. program input current			10	mA
V _C CKP	CK supply (program) ³	16.0	17.0	18.0	V
V _C CKV	CK supply (idle)	1.25	1.5	1.75	V
I _{CC} KP	CK supply current limit	275	300	325	mA
t _v	Verify time	1			μs
T _{RS}	Reset pulse width	1			μs
T _{PS}	Preset pulse width	1			μs
t _p	Programming pulse width	0.3	0.4	0.5	ms
t _D	Pulse sequence delay	10			μs
T _R	CK Pulse rise time	10		50	μs
T _P VB	Program-Verify time per link		0.6		ms
PDC	Programming duty cycle			100	%
F _L	Fusing attempts per link			2	cycle
V _S	Verify threshold ⁴	1.4	1.5	1.6	V

NOTES

1. These are specifications which a Programming System must satisfy in order to be qualified by Signetics.
2. Bypass V_{CC} to GND with a 0.01μf capacitor to reduce voltage spikes.
3. Care should be taken to ensure that the voltage is maintained during the entire fusing cycle. The recommended supply is a constant current source clamped at the specified voltage limit.
4. V_S is the sensing threshold of the FPLS output voltage for a programmed link. It normally constitutes the reference voltage applied to a comparator circuit to verify a successful fusing attempt.

PR/O.E. OPTION PROGRAM-VERIFY SEQUENCE

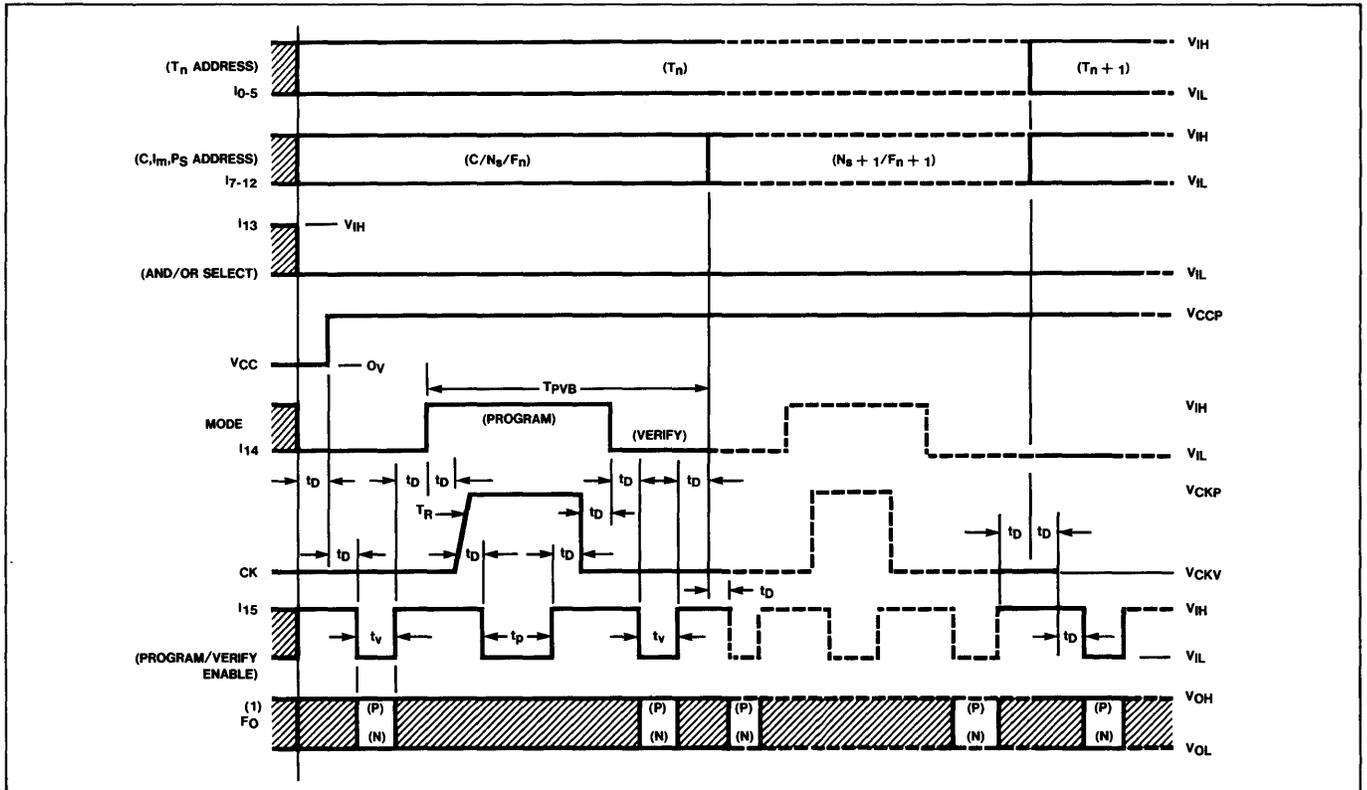


FIELD PROGRAMMABLE LOGIC SEQUENCER

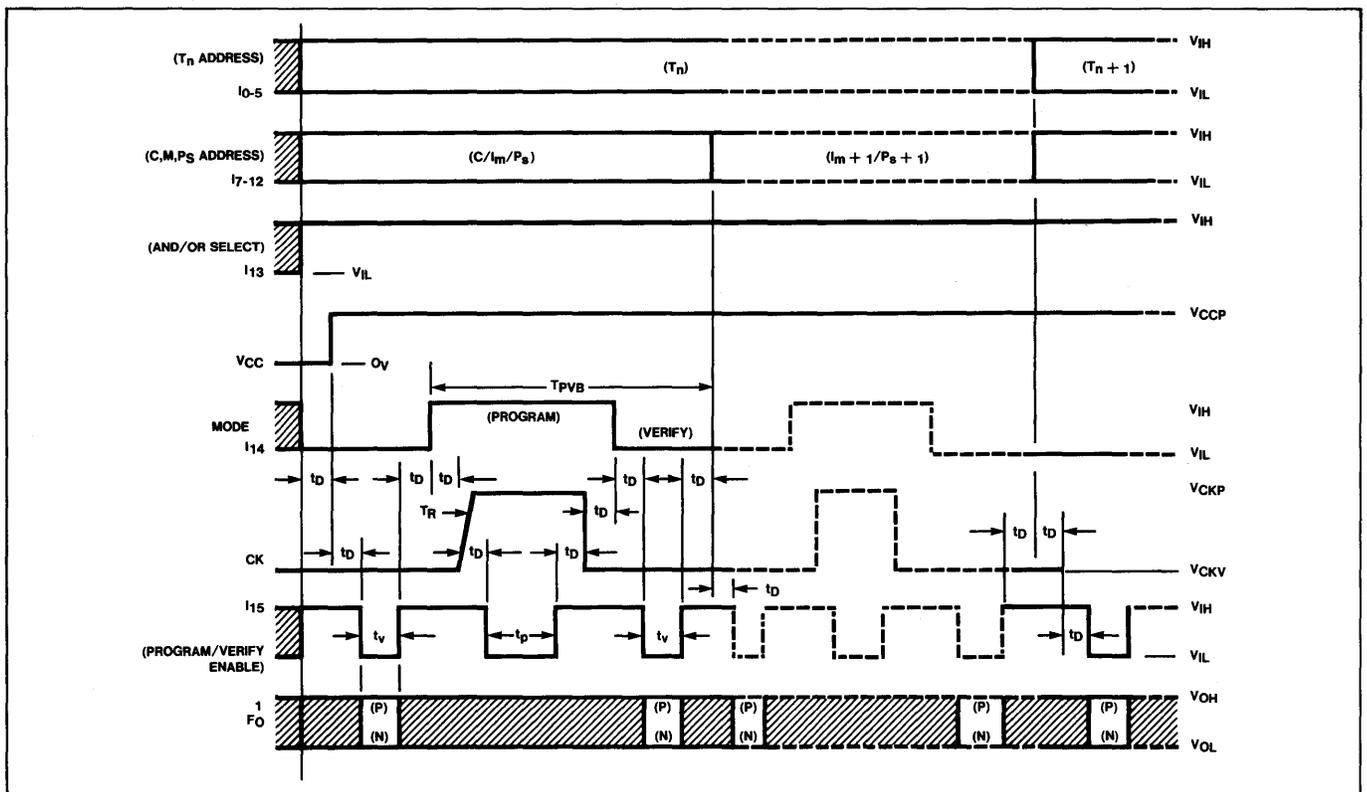
82S104 (O.C.)/82S105 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

“OR” ARRAY PROGRAM-VERIFY SEQUENCE (TYPICAL)



“AND” ARRAY PROGRAM-VERIFY SEQUENCE (TYPICAL)



NOTE

1. (P) and (N) represent respectively a programmed and non-programmed fuse, corresponding to logic "1" or "0" output voltage levels.

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

DESCRIPTION

The 82S106 (Open collector outputs) and 82S107 (3-state outputs) are bipolar Programmable ROM Patches organized as 48 words by 8 bits, addressed via a 16 bit programmable address comparator. Each word can be assigned a unique address code, P_n , within a 64K (2^{16}) address range by programming the comparator inputs High, Low, or Don't care via True/Complement input buffers.

The contents of each word are also programmable, and are enabled to the active-High Patch outputs only when a programmed address is detected, which causes the Flag output to go Low. For all unprogrammed addresses, the device outputs remain High (82S106) or Hi-Z (82S107) while the Flag output remains High. The Flag is open collector to allow wire-ANDing for expansion to more than 48 patch words.

The 82S106 and 82S107 are fully TTL compatible and can be programmed in the field by following the fusing procedure outlined in this data sheet, or by means of commercially available equipment.

Both devices are available in commercial and military temperature ranges. For the commercial range (0°C to +75°C) specify N82S106/107, F or N, and for the military temperature range (-55°C to +125°C) specify S82S106/107, F, G, or R.

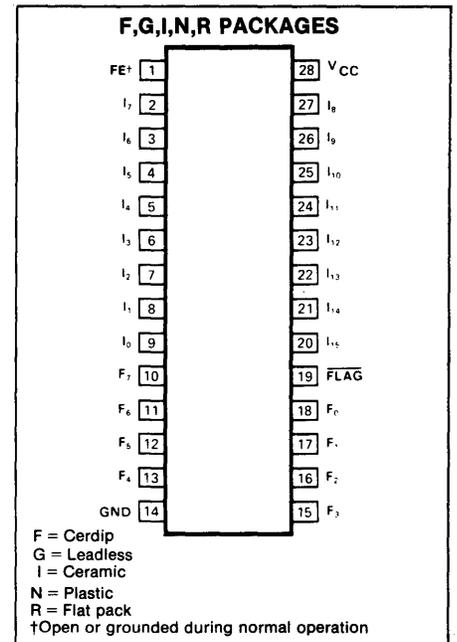
FEATURES

- Field programmable (Ni-Cr link)
- Address Inputs: 16
- Data Outputs: 8
- Patch Words: 48
- Address access time:
S82S106/107—100ns Max
N82S106/107—70ns Max
- Power dissipation: 600mW typ
- Input loading:
S82S106/107: -150µA Max
N82S106/107: -100µA Max
- Open collector Flag
- Output option:
82S106: Open collector
82S107: 3-state
- Output disabled state
3-state—Hi-Z
Open collector—Hi

APPLICATIONS

- ROM data modifications
- Memory address trap
- Digital filter
- Interrupt request/vector generator
- Data security encoder

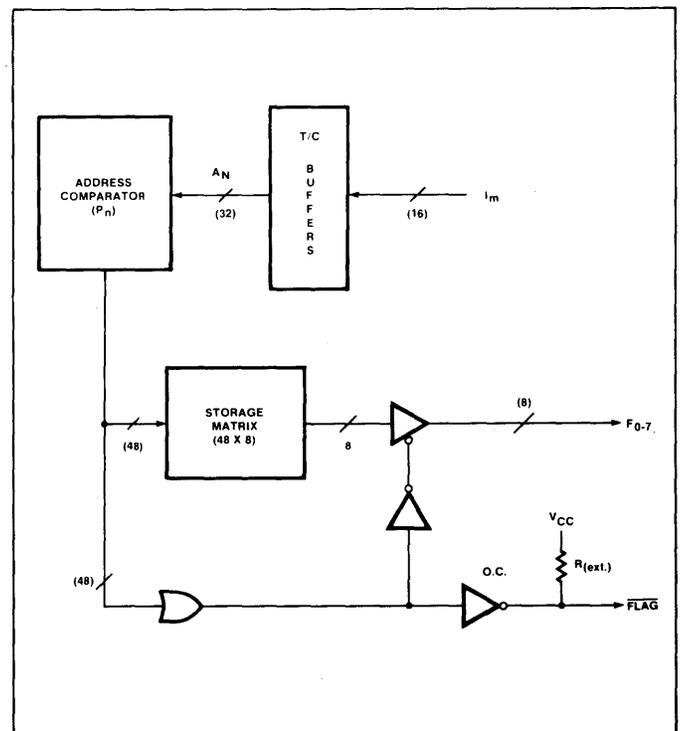
PIN CONFIGURATION



TRUTH TABLE

?	$\overline{\text{Flag}}$	F0-7	
		82S106	82S107
NO	1	1	Hi-Z
YES	0	Stored Data	

LOGIC DIAGRAM

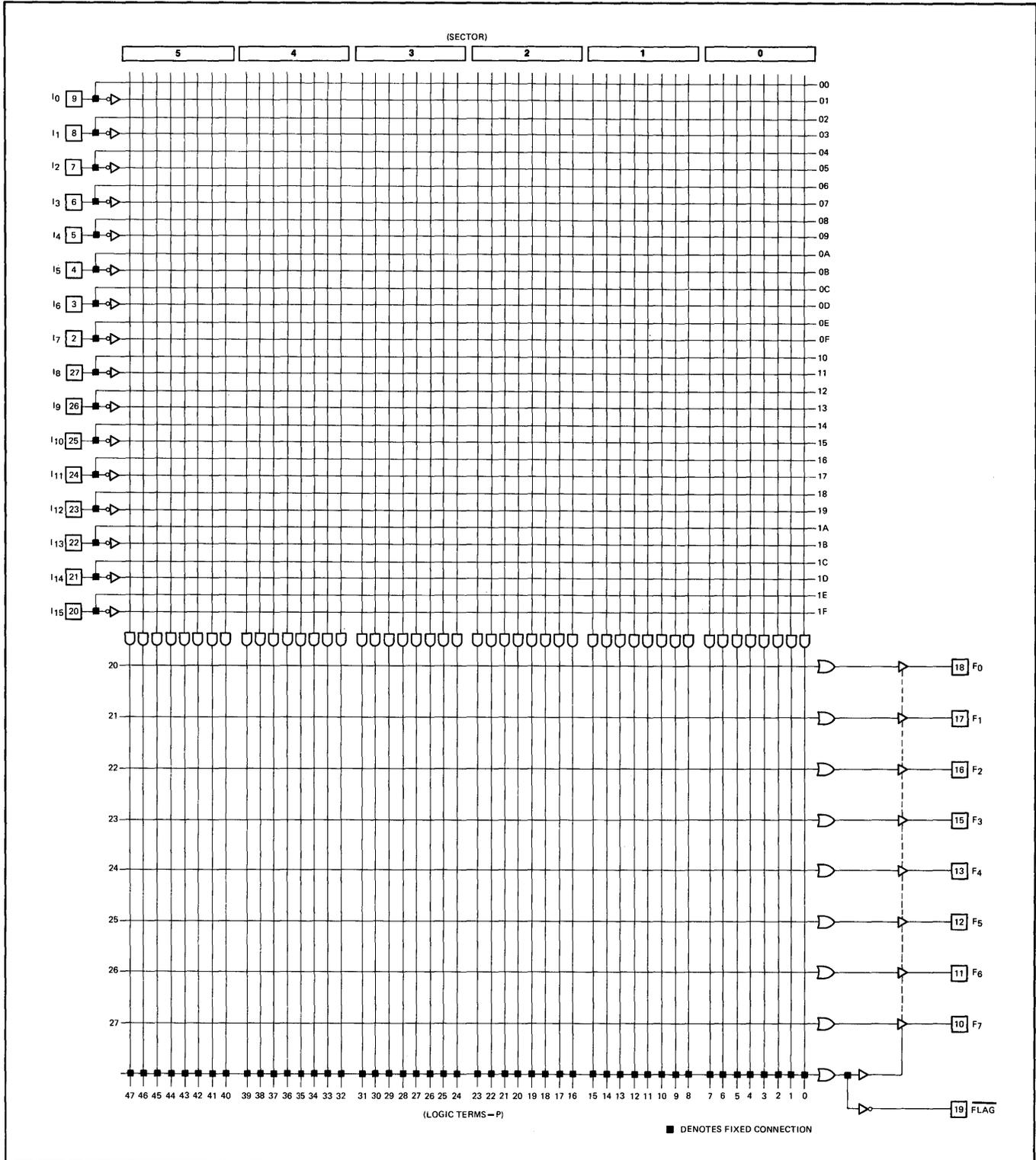


FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

FPRP LOGIC DIAGRAM



FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

ABSOLUTE MAXIMUM RATINGS¹

PARAMETER		RATING		UNIT
		Min	Max	
V _{CC}	Supply voltage		+7	Vdc
V _{IN}	Input voltage		+5.5	Vdc
V _{OUT}	Output voltage		+5.5	Vdc
I _{IN}	Input currents	-30	+30	mA
I _{OUT}	Output currents		+100	mA
T _A	Temperature range Operating			°C
	N82S106/107	0	+75	
	S82S106/107	-55	+125	
T _{STG}	Storage	-65	+150	

THERMAL RATINGS

TEMPERATURE	MILI-TARY	COM-MER-CIAL
Maximum junction	175°C	150°C
Maximum ambient	125°C	75°C
Allowable thermal rise ambient to junction	50°C	75°C

DC ELECTRICAL CHARACTERISTICS N82S106/107: 0° ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S106/107: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TEST CONDITIONS	N82S106/107			S82S106/107			UNIT
		Min	Typ ²	Max	Min	Typ ²	Max	
V _{IH} V _{IL} V _{IC}	Input voltage ² High Low Clamp ^{2,3} V _{CC} = Max V _{CC} = Min V _{CC} = Min, I _{IN} = -18mA	2		0.85 -1.2	2		0.8 -1.2	V
V _{OH} V _{OL} V _{OL}	Output voltage High (82S107) ^{2,4} Low ^{2,5} (F ₀₋₇) Low ^{2,5} (Flag) V _{CC} = Min I _{OH} = -2mA I _{OL} = 9.6mA I _{OL} = 4.8mA	2.4		0.35 0.45	2.4		0.35 0.50	V
I _{IH} I _{IL}	Input current High Low V _{IN} = 5.5V V _{IN} = 0.45V		<1 -10	25 -100		<1 -10	50 -150	μA
I _{OLK} I _{O(OFF)} I _{OS}	Output current Leakage ⁷ Hi-Z state (82S107) ⁶ Short circuit (82S107) ^{3,7} V _{CC} = Max V _{OUT} = 5.5V V _{OUT} = 5.5V V _{OUT} = 0.45V V _{OUT} = 0V		1 1 -1	40 40 -40 -70		1 1 -1	60 60 -60 -85	μA μA mA
I _{CC}	V _{CC} supply current ⁸ V _{CC} = Max		120	170		120	180	mA
C _{IN} C _{OUT}	Capacitance ⁶ Input Output V _{CC} = 5.0V V _{IN} = 2.0V V _{OUT} = 2.0V		8 17			8 17		pF

AC ELECTRICAL CHARACTERISTICS R₁ = 470Ω, R₂ = 1kΩ, C_L = 30pF
N82S106/107: 0°C ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S106/107: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TO	FROM	N82S106/107			S82S106/107			UNIT
			Min	Typ	Max	Min	Typ	Max	
T _{IA} T _{FL}	Access time Address Enable	Output Flag Input Input		45 40	70 55		100 40	100 80	ns

NOTES on following page.

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

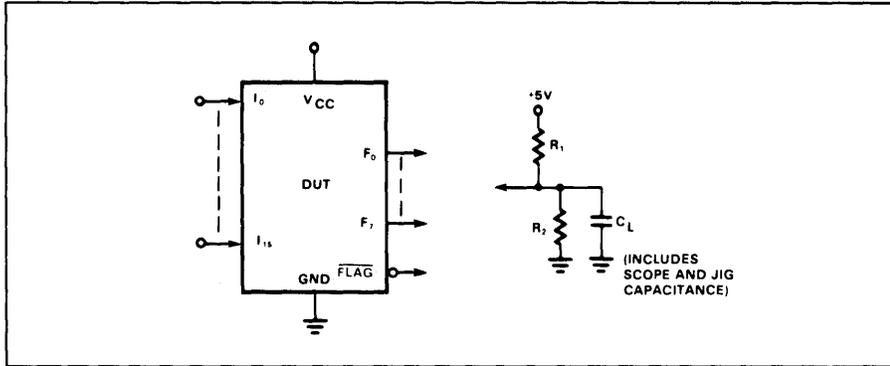
82S106 (O.C.)/82S107 (T.S.)

**INTEGRATED FUSE LOGIC
SERIES 28**

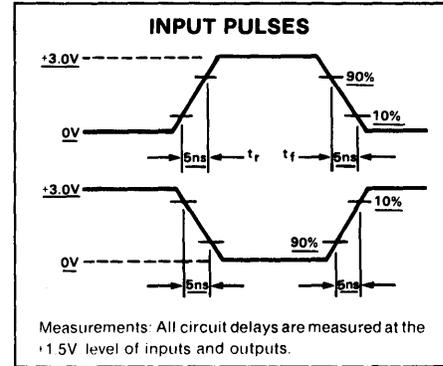
NOTES

1. Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device of these or any other condition above those indicated in the operation of the device specification is not implied.
2. All typical values are at $V_{CC} = 5V$, $T_A = 25^\circ C$.
3. All voltage values are with respect to network ground terminal.
4. Test one at the time.
5. Measured with the Patch enabled ($A_N = P_N$) and a logic high stored.
6. Measured with a programmed logic condition for which the output under test is at a low logic level when the Patch is enabled ($A_N = P_N$). Output sink current is applied thru a resistor to V_{CC} .
7. Measured with the Patch disabled ($A_N \neq P_N$).
8. Duration of short circuit should not exceed 1 second.
9. I_{CC} is measured with all inputs at 4.5V and the outputs open.

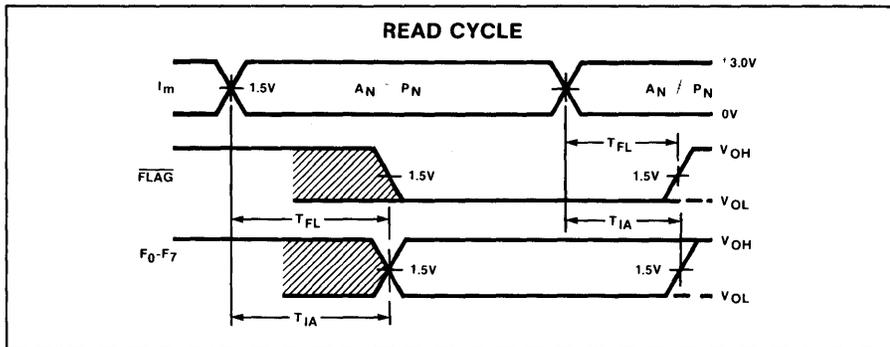
TEST LOAD CIRCUIT



VOLTAGE WAVEFORM



TIMING DIAGRAM



TIMING DEFINITIONS

T_{IA} Delay between latest Address variable change and when Data Output becomes stable.

4. The polarity of each output is set to active high.

5. All outputs are at a low logic level.

T_{FL} Delay between latest Address variable change and when \overline{Flag} output becomes stable.

VIRGIN DEVICE

The 82S106/107 are shipped in an unprogrammed state, characterized by:

1. All internal Ni-Cr links are intact.
2. Each comparator address (P-term) contains both true and complement values of every input variable I_m (P-terms always logically "false").
3. The storage Matrix contains all "1".

RECOMMENDED PROGRAMMING PROCEDURE
To program up to 48 address-data pair locations, follow the program/verify procedures outlined below. To maximize recovery from programming errors, leave all links corresponding to unused address-data pairs intact.

SET-UP

Terminate all device outputs with a 10K resistor to +5V. Set GND (pin 14) to 0V.

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (I.S.)

**INTEGRATED FUSE LOGIC
SERIES 28**

ADDRESS COMPARATOR

Program P_n Address

Program one input at the time and one P-term at the time. Unused comparator inputs must be programmed as Don't Care for all programmed P-terms.

1. Set FE (pin 1) to V_{FEL}, and V_{CC} (pin 28) to V_{CCP}.
2. Disable all device outputs by setting $\overline{\text{Flag}}$ (pin 19) to V_{IH}.
3. Disable all comparator inputs by applying V_{I_X} to inputs I₀ through I₁₅.
4. Address the P-term to be programmed (No. 0 through 47) by forcing the corresponding binary code on outputs F₀ through F₅ with F₀ as LSB. Use standard TTL logic levels V_{OHF} and V_{OL_F}.
- 5a. If the P-term contains neither I₀ nor $\overline{I_0}$ (input is a Don't Care), fuse both I₀ and $\overline{I_0}$ links by executing both steps 5b and 5c, before continuing with step 7.
- 5b. If the P-term contains I₀, set to fuse the $\overline{I_0}$ link by lowering the input voltage at I₀ from V_{I_X} to V_{IH}. Execute step 6.
- 5c. If the P-term contains $\overline{I_0}$, set to fuse the I₀ link by lowering the input voltage at I₀ from V_{I_X} to V_{IL}. Execute step 6.
- 6a. After t_D delay, raise FE from V_{FEL} to V_{FEH}.
- 6b. After t_D delay, pulse the $\overline{\text{Flag}}$ input from V_{IH} to V_{I_X} for a period t_p.
- 6c. After t_D delay, return FE input to V_{FEL}.
7. Disable programmed input by returning I₀ to V_{I_X}.
8. Repeat steps 5 through 7 for all other input variables.
9. Repeat steps 4 through 8 for all other P-terms.
10. Remove V_{I_X} from all input variables.

VERIFY P_n ADDRESS

1. Set FE to V_{FEL}, and V_{CC} to V_{CCP}.
2. Enable F₇ output by setting $\overline{\text{Flag}}$ to V_{I_X}.
3. Disable all comparator inputs by applying V_{I_X} to inputs I₀ through I₁₅.
4. Address the P-term to be verified (No. 0 through 47) by forcing the corresponding binary code on outputs F₀ through F₅.

5. Interrogate Input I₀ as follows:
 - A. Lower the input voltage at I₀ from V_{I_X} to V_{IH}, and sense the logic state of output F₇.
 - B. Lower the input voltage at I₀ from V_{IH} to V_{IL}, and sense the logic state output F₇.

The state of I₀ contained in the P-term is determined in accordance with the following truth table:

I ₀	F ₇	COMPARATOR INPUT STATE CONTAINED IN P-TERM
0	1	$\overline{I_0}$
1	0	I ₀
0	0	I ₀
1	1	$\overline{I_0}$
0	1	Don't Care
1	1	Don't Care
0	0	(I ₀ , $\overline{I_0}$)
1	0	(I ₀ , $\overline{I_0}$)

Note that 2 tests are required to uniquely determine the state of the input contained in the P-term.

6. Disable verified input by returning I₀ to V_{I_X}.
7. Repeat steps 5 and 6 for all other input variables.
8. Repeat steps 4 through 7 for all other P-terms.
9. Remove V_{I_X} from all comparator inputs.

STORAGE MATRIX

Program Output Data

Program one output at the time for one P-term at the time.

1. Set FE to V_{FEL}.
2. Disable the chip by setting $\overline{\text{Flag}}$ to V_{IH}.
3. After t_D delay, set V_{CC} to V_{CCS}, and inputs I₆ through I₁₅ to V_{IH}, V_{IL}, or V_{I_X}.
4. Address the P-term to be programmed (No. 0 through 47) by applying the corresponding binary code to comparator inputs I₀ through I₅, with I₀ as LSB.

5. To program a logic "0" at output F₀, force F₀ to V_{OPF}.
- 6a. After t_D delay, raise FE (pin 1) from V_{FEL} to V_{FEH}.
- 6b. After t_D delay, pulse the $\overline{\text{Flag}}$ input from V_{IH} to V_{I_X} for a period t_p.
- 6c. After t_D delay, return FE input to V_{FEL}.
- 6d. After t_D delay, remove V_{OPF} from output F₀.
7. Repeat steps 5 and 6 for all other output functions.
8. Repeat steps 4 through 7 for all other P-terms.
9. Remove V_{CCS} from V_{CC}.

Verify Output Data

1. Set FE to V_{FEL}.
2. Disable the chip by setting $\overline{\text{Flag}}$ to V_{IH}.
3. After t_D delay, set V_{CC} to V_{CCS}, and inputs I₀ through I₁₅ to V_{IH}, V_{IL}, or V_{I_X}.
4. Address the P-term to be verified (No. 0 through 47) by applying the corresponding binary code to comparator inputs I₀ through I₅.
5. After t_D delay, enable the chip by setting $\overline{\text{Flag}}$ to V_{IL}.
6. To determine the status of each output link in the Storage Matrix, sense the state of outputs F₀ through F₇. The status of the link is given by the following truth table:

F _p	LINK
0	Fused
1	Present

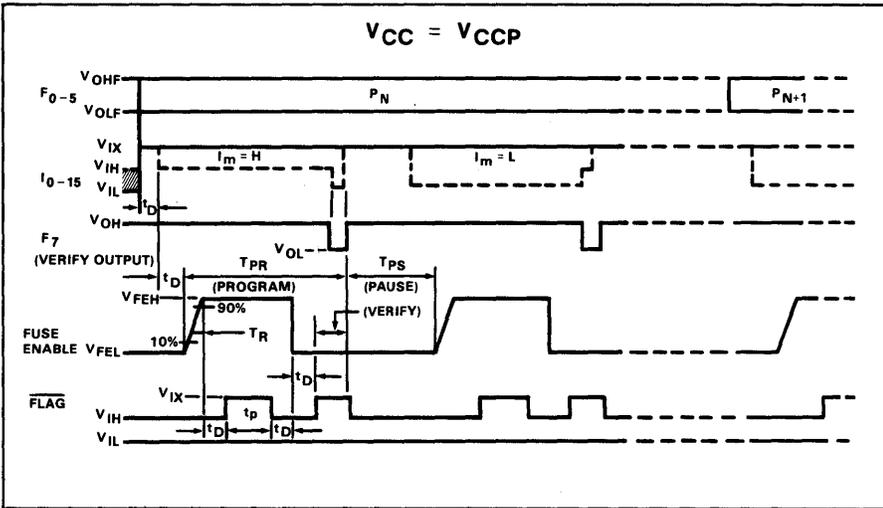
7. Repeat steps 4 through 6 for all other P-terms.
8. Remove V_{CCS} from V_{CC}.

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

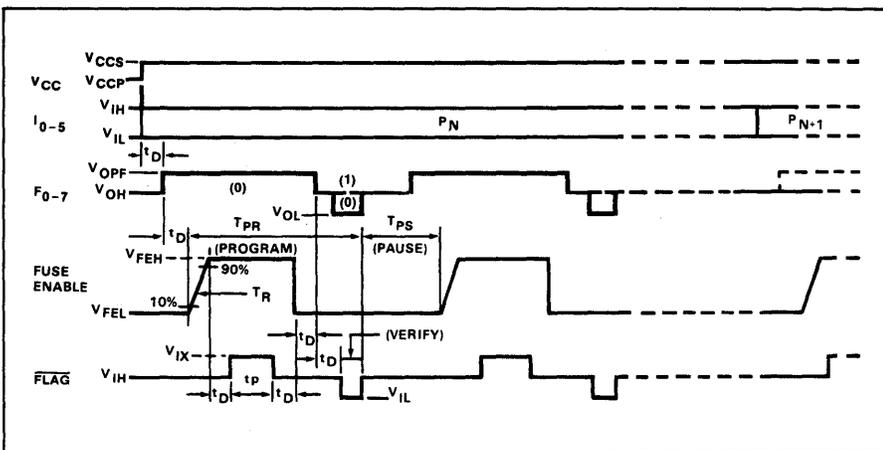
82S106 (O.C.)/82S107 (I.S.)

INTEGRATED FUSE LOGIC
SERIES 28

ADDRESS COMPARATOR PROGRAM-VERIFY SEQUENCE (TYPICAL)



STORAGE MATRIX PROGRAM-VERIFY SEQUENCE (TYPICAL)



FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

PROGRAMMING SYSTEM SPECIFICATIONS¹ (T_A = +25°C)

PARAMETER		TEST CONDITIONS	LIMITS			UNIT
			Min	Typ	Max	
V _{CCS}	V _{CC} supply (program/verify Storage Matrix) ²	I _{CCS} = 550mA, min. Transient or steady state	8.25	8.5	8.75	V
I _{CCS}	I _{CC} limit	V _{CCS} = +8.50 ± .25V	550		1,000	mA
Input voltage						V
V _{IH}	High		2.4		5.5	
V _{IL}	Low		0	0.4	0.8	
Input current						μA
I _{IH}	High	V _{IH} = +5.5V			50	
I _{IL}	Low	V _{IL} = 0V			-500	
Forced output voltage						V
V _{OHF}	High		2.4		5.5	
V _{OLF}	Low		0	0.4	0.8	
Output current						μA
I _{OHF}	High	V _{OHF} = +5.5V			100	
I _{OLF}	Low	V _{OLF} = 0V			-1	mA
V _{IX}	Flag program enable level		9.5	10	10.5	V
I _{IX1}	Input current	V _{IX} = +10V			10	mA
I _{IX2}	Flag input current	V _{IX} = +10V			10	mA
V _{FEH}	FE supply (program) ³	I _{FEH} = 300 ± 25mA, Transient or steady state	16.0	17.0	18.0	V
V _{FEL}	FE supply (idle)	I _{FEL} = -1mA, max	1.25	1.5	1.75	V
I _{FEH}	FE supply current limit	V _{FEH} = +17 ± 1V	275	300	325	mA
V _{CCP}	V _{CC} supply (program/verify Address Comparator)	I _{CCP} = 550mA, min. Transient or steady state	4.75	5.0	5.25	V
I _{CCP}	I _{CC} limit	V _{CCP} = +5.0 ± .25V	550		1,000	mA
V _{OPF}	Forced output (program)		9.5	10	10.5	V
I _{OPF}	Output current (program)				10	mA
T _R	FE pulse rise time	10% to 90%	10		50	μs
t _p	Flag programming pulse width		0.3	0.4	0.5	ms ⁵
t _d	Pulse sequence delay		10			μs
T _{PR}	Programming time			0.6		ms
$\frac{T_{PR}}{T_{PR} + T_{PS}}$	Programming duty cycle				50	%
FL	Fusing attempts per link				2	cycle
V _S	Verify threshold ⁴		1.4	1.5	1.6	V

NOTES

- These are specifications which a Programming System must satisfy in order to be qualified by Signetics.
- Bypass V_{CC} to GND with a 0.01μf capacitor to reduce voltage spikes.
- Care should be taken to ensure that the voltage is maintained during the entire fusing cycle. The recommended supply is a constant current source clamped at the specified voltage limit.
- V_S is the sensing threshold of the FPRP output voltage for a programmed link. It normally constitutes the reference voltage applied to a comparator circuit to verify a successful fusing attempt.
- These are new limits resulting from device improvements, and which supersede, but do not obsolete the performance requirements of previously manufactured programming equipment.

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

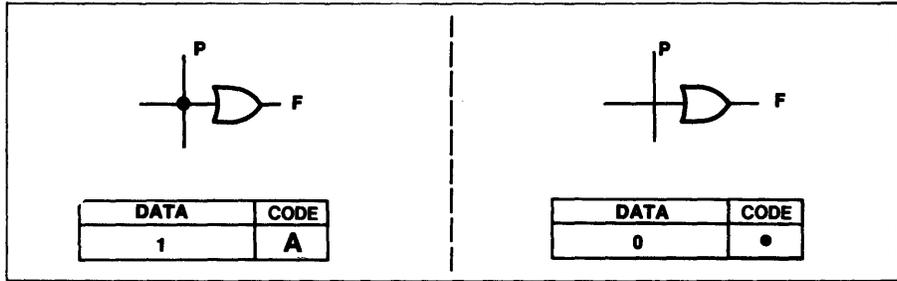
LOGIC PROGRAMMING

The FPRP can be programmed by means of Logic programming equipment.

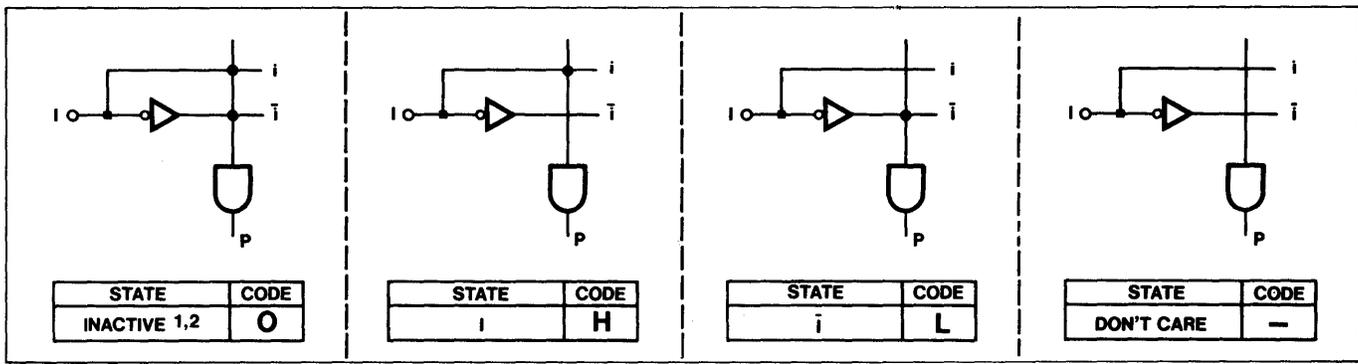
With Logic programming, the AND/OR gate input connections necessary to implement the desired logic function are coded directly from memory patch specifications using the Program Table on the following page.

In this Table, the logic state of variables I and F associated with each Patch address P_n is assigned a symbol which results in the proper fusing pattern of corresponding link pairs, defined as follows:

"OR" ARRAY - (F)



"AND" ARRAY - (I),



NOTES

1. This is the initial unprogrammed state of all link pairs. It is normally associated with all unused (inactive) AND gates P_n .
2. Any gate P_n will be unconditionally inhibited if any one of its (I) link pairs is left intact.

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

FPRP PROGRAM TABLE (Logic)

NOTES

1. Unused inputs and outputs are FPRP terminals left floating.
2. Input and output fields of inactive P-terms can be left blank.

<p>THIS PORTION TO BE COMPLETED BY SIGNETICS</p>	PROGRAM TABLE ENTRIES																								
	COMPARATOR INPUT	OUTPUT FUNCTION																							
I_m	\bar{I}_m	Don't care																							
H	L	— (dash)																							
NOTE Enter (-) for unused inputs of all active P-terms.		NOTE Enter (A) for unused outputs of all active P-terms.																							
<p>CF:XXXX</p> <p>CUSTOMER SYMBOLIZED PART # _____</p> <p>DATE RECEIVED _____</p> <p>COMMENTS _____</p>	PRODUCT TERM																								
	INPUT VARIABLE																ACTIVE LEVEL								
NO	1	1	1	1	1	1	9	8	7	6	5	4	3	2	1	0	H	H	H	H	H	H	H	H	
	5	4	3	2	1	0											7	6	5	4	3	2	1	0	
0																									
1																									
2																									
3																									
4																									
5																									
6																									
7																									
8																									
9																									
10																									
11																									
12																									
13																									
14																									
15																									
16																									
17																									
18																									
19																									
20																									
21																									
22																									
23																									
24																									
25																									
26																									
27																									
28																									
29																									
30																									
31																									
32																									
33																									
34																									
35																									
36																									
37																									
38																									
39																									
40																									
41																									
42																									
43																									
44																									
45																									
46																									
47																									
<p>CUSTOMER NAME _____</p> <p>PURCHASE ORDER # _____</p> <p>SIGNETICS DEVICE # _____</p> <p>TOTAL NUMBER OF PARTS _____</p> <p>PROGRAM TABLE # _____</p> <p>REV _____ DATE _____</p>																									

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC SERIES 28

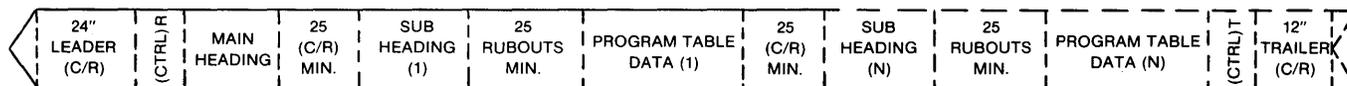
TWX TAPE CODING FORMAT

The FPRP Program Table can be sent to Signetics in ASCII code format via airmail using any type of 8-level tape (paper, mylar; fanfold, etc.), or via TWX: just dial (910) 339-

9283, tell the operator to turn the paper puncher on, and acknowledge. At the end of transmission instruct the operator to send tape to Signetics Order Entry.

quentially assembled on a continuous tape as follows, however limit tape length to a roll of 1.75 inch inside diameter, and 4.25 inch outside diameter:

A number of Program Tables can be se-



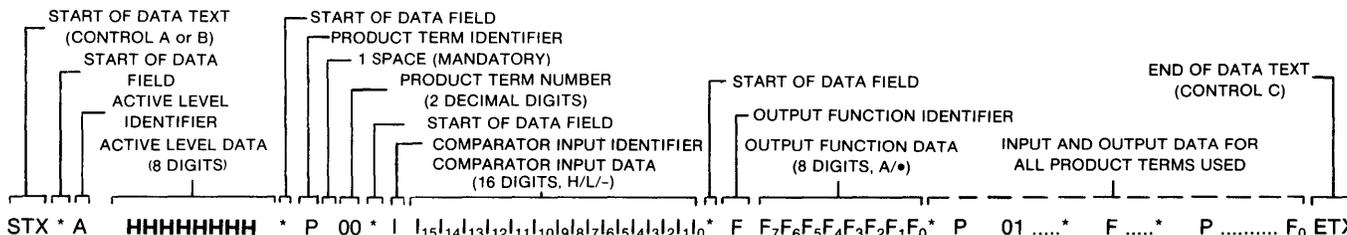
A. The MAIN HEADING at the beginning of tape includes the following information, with each entry preceded by a (\$) character, whether used or not:

- 1. Customer Name _____
- 2. Customer TWX No. _____
- 3. Date _____
- 4. Purchase Order No. _____
- 5. Number of Program Tables _____
- 6. Total Number of Parts _____

B. Each SUB HEADING should contain specific information pertinent to each Program Table as follows, with each entry preceded by a (\$) character, whether used or not:

- 1. Signetics Device No. _____
- 2. Program Table No. _____
- 3. Revision _____
- 4. Date _____
- 5. Customer Symbolized Part No. _____
- 6. Number of Parts _____

C. Program Table data blocks are initiated with an STX character, and terminated with an ETX character. The body of the data consists of Output Active Level, Product Term, and Output Function information separated by appropriate identifiers in accordance with the following format:



COMPARATOR INPUT		
I _m	I _m	Don't care
H	L	—(dash)

OUTPUT FUNCTION	
"1"	"0"
A	• (period)

- NOTES
1. Enter (-) for unused inputs of all active P-terms.
 2. Enter (A) for unused outputs of all active P-terms.
 3. Unused inputs and outputs are FPRP terminals left floating.

Although the Product Term data are shown entered in sequence, this is not necessary. It is possible to input only one Product Term, if desired. Unused Product Terms require no entry. ETX signalling end of Program Table may occur with less than the maximum number of Product Terms entered.

- NOTES
1. Corrections to any entry can be made by backspace and rubout. However, limit consecutive rubouts to less than 25.
 2. Terms can be re-entered any number of times. The last entry for a particular P-Term will be interpreted as valid data.
 3. To facilitate an orderly Teletype print out, carriage returns, line feeds, spaces, rubouts etc. may be interspersed between data groups.
 4. Comments are allowed between data fields, provided that an asterisk (*) is not used in any Heading or Comment entry.

FIELD PROGRAMMABLE ROM PATCH (16X48X8)

82S106 (O.C.)/82S107 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 28

TYPICAL APPLICATION

PATCH SPECIFICATIONS

ADDRESS	NEW DATA
750	A9
5FE	7F
OA4	B4
OA5	
OA6	
OA7	

FPRP PROGRAM TABLE

INPUT ADDRESS	NO.	PRODUCT TERM																ACTIVE LEVEL								OUTPUT DATA
		COMPARATOR INPUT																OUTPUT FUNCTION								
		1	1	1	1	1	1	0	9	8	7	6	5	4	3	2	1	0	H	H	H	H	H	H	H	
750	0	-	-	-	-	L	H	H	H	L	H	L	H	L	L	L	L	A	*	A	*	A	*	*	A	A9
5FE	1	-	-	-	-	L	H	L	H	H	H	H	H	H	H	H	L	*	A	A	A	A	A	A	A	7F
OA4-OA7	2	-	-	-	-	L	L	L	L	H	L	H	L	L	H	-	-	A	*	A	A	*	A	*	*	B4

I/O ASSIGNMENT: I/O ASSIGNMENT, UNUSED, A₁₁ to A₀, D₇ to D₀

Since Patch inputs I₁₂₋₁₅ are unused, they are programmed Don't Care (-), and left open in the circuit. Note however that I₀ and I₁ are programmed as (-) in P-term 2 because they define an address block of 4 memory locations.

EXPANSION

When more than 48 memory locations need to be patched, several devices can be paralleled by wire-ANDing the $\overline{\text{Flag}}$ outputs.

FIELD PROGRAMMABLE GATE ARRAY (18X12)

82S150 (O.C.)/82S151 (T.S.)

Preview

DESCRIPTION

The 82S150 and the 82S151 are single level logic elements, consisting of 12 AND gates with fusible link connections for programming I/O polarity, I/O direction and output enable control.

All gates are linked to 6 inputs (I) and 12 bidirectional I/O lines (B). These yield variable I/O gate configurations via 3 direction control gates (D), ranging from 18 inputs to 12 outputs.

On chip T/C buffers couple either True (I, B) or Complement (\bar{I} , \bar{B}) input polarities to each AND gate. The polarity of all gate outputs is individually programmable through a set of EX-OR gates for implementing AND/NAND logic functions. Alternately, if desired, OR/NOR logic functions can also be realized by programming for each gate the complement of its inputs and output (DeMorgan's Theorem).

The 82S150 and the 82S151 are field programmable, enabling the user to quickly generate custom patterns using standard programming equipment.

Both devices are available in a 20-pin slim line package. For the commercial temperature range (0°C to +75°C) specify N82S150/151 N or F. For the military temperature range (-55°C to +125°C) specify S82S150/151 F only.

FEATURES

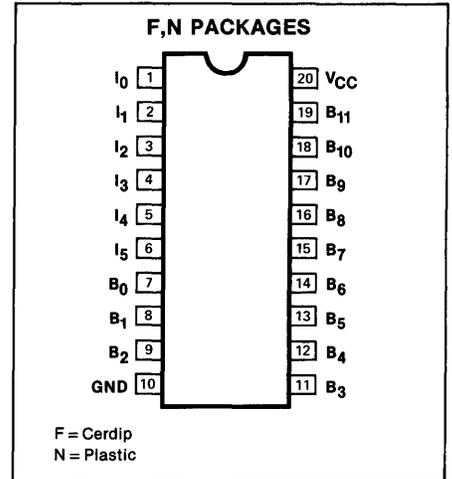
- Field Programmable (Ni-Cr link)
- 6 inputs
- 12 AND gates
- 12 bidirectional I/O lines
- Active high or low outputs
- Programmable output enable
- Power dissipation: 650mW (typ)
- I/O propagation delay: 30ns (max)
- Input loading
N82S150/151: -100µA (max)
S82S150/151: -150µA (max)
- Output options
82S150: open collector
82S151: tri-state
- TTL compatible

APPLICATIONS

- Random gating functions
- Address decoding
- Code detectors
- Memory mapped I/O
- Fault monitors
- I/O port decoders

INTEGRATED FUSE LOGIC
SERIES 20

PIN CONFIGURATION



LOGIC FUNCTIONS

Typical Gate Functions:

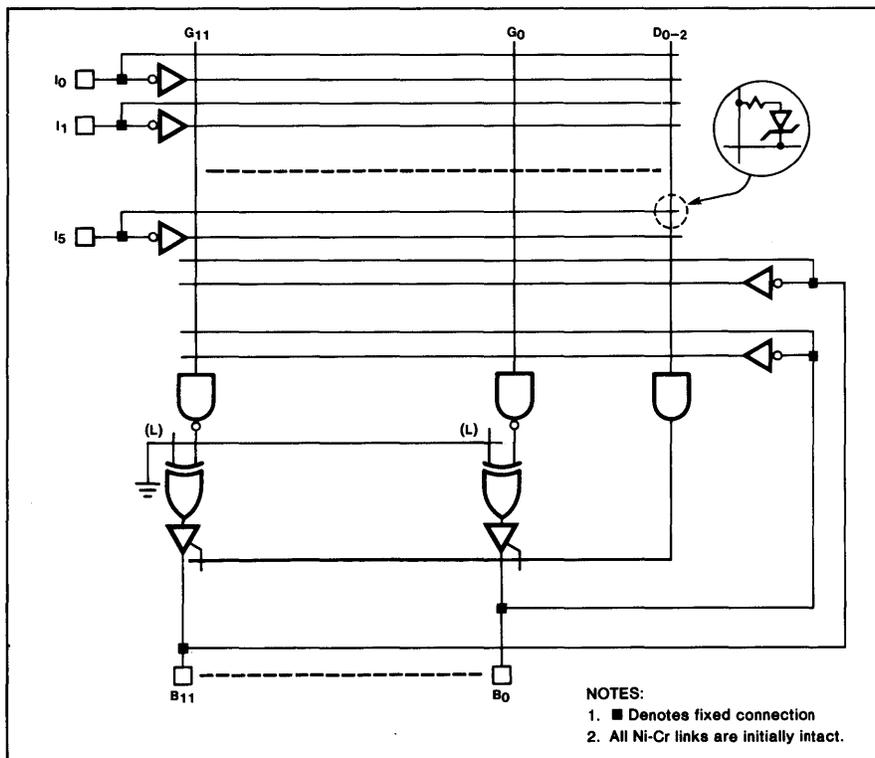
At L = Open
 $X = A \cdot \bar{B} \cdot C \cdot \dots$

At L = Closed
 $X = A \cdot \bar{B} \cdot C \cdot \dots$
 $X = \bar{A} + B + \bar{C} + \dots$

NOTES:

1. For each of the 12 outputs, either function X (active-high) or \bar{X} (active-low) is available, but not both. The desired output polarity is programmed via link (L).
2. X, A, B, C, etc. are user defined connections to fixed inputs (I) and bidirectional pins (B).

FUNCTIONAL DIAGRAM



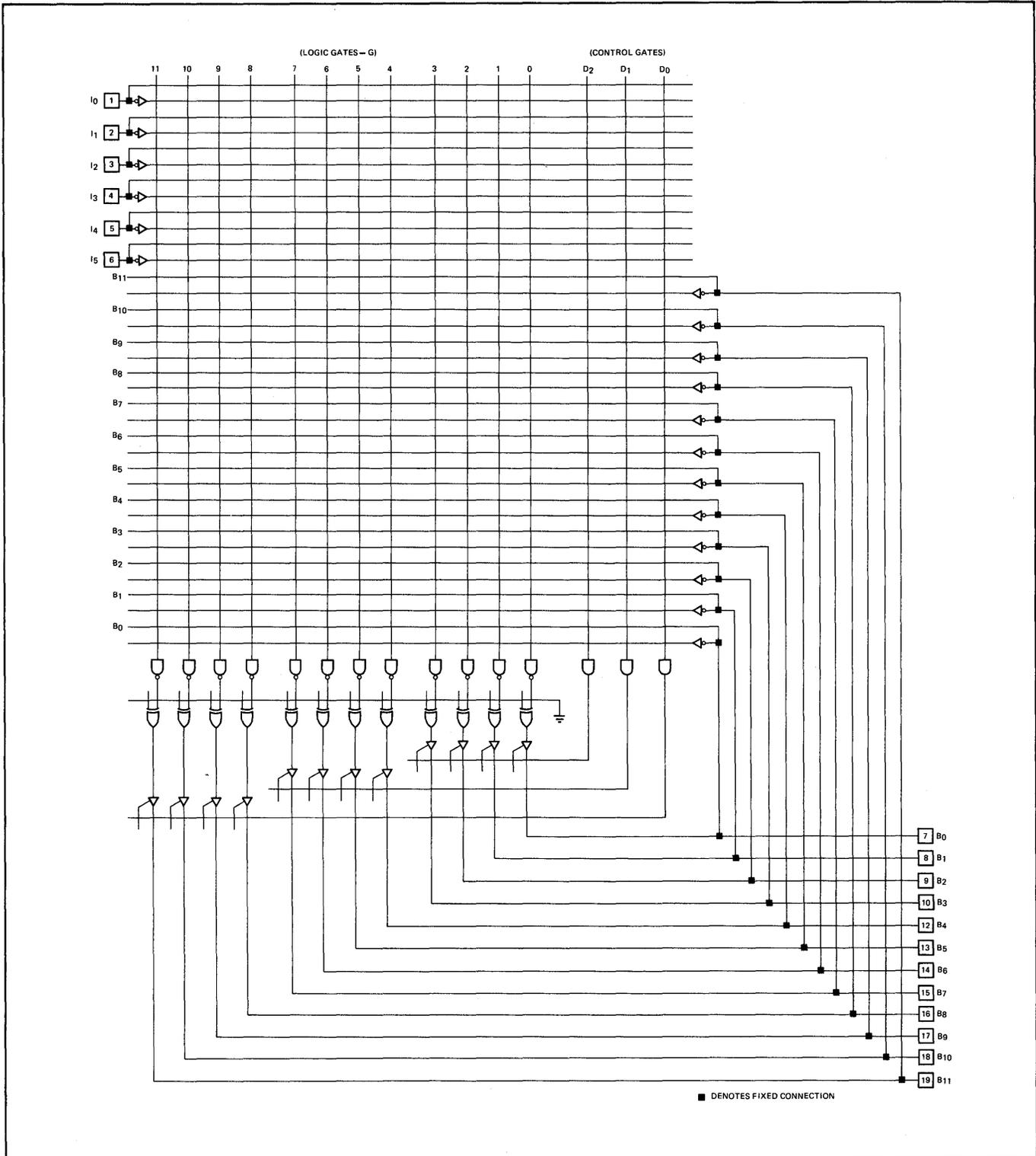
FIELD PROGRAMMABLE GATE ARRAY (18X12)

82S150 (O.C.)/82S151 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

FPGA LOGIC DIAGRAM



FIELD PROGRAMMABLE GATE ARRAY (18X12)

82S150 (O.C.)/82S151 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING		UNIT
	Min	Max	
V _{CC} Supply voltage		+7	Vdc
V _{IN} Input voltage		+5.5	Vdc
V _{OUT} Output voltage		+5.5	Vdc
I _{IN} Input currents	-30	+30	mA
I _{OUT} Output currents		+100	mA
T _A Temperature range			C°
Operating			
	N82S150/151	0	+75
S82S150/151			
		-55	+125
T _{STG} Storage	-65	+150	

THERMAL RATINGS

TEMPERATURE	Military	Commercial
Maximum junction	175°C	150°C
Maximum ambient	125°C	75°C
Allowable thermal rise ambient to junction	50°C	75°C

DC ELECTRICAL CHARACTERISTICS N82S150/151: 0°C ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S150/151: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TEST CONDITION	N82S150/151			S82S150/151			UNIT
		Min	Typ ²	Max	Min	Typ ²	Max	
V _{IL} Input voltage ³ Low	V _{CC} = Min V _{CC} = Max V _{CC} = Min, I _{IN} = -18mA			.85			.80	V
V _{IH} High		2.0			2.0			
V _{IC} Clamp ^{3,4}			.8	-1.2		.8	-1.2	
V _{OL} Output voltage Low ^{3,5}	V _{CC} = Min I _{OL} = 10mA I _{OL} = 8mA I _{OH} = -2mA			.5			.5	V
V _{OL} Low ^{3,5}		2.4			2.4			
V _{OH} High ^{3,6}								
I _{IL} Input Current Low	V _{IN} = 0.45V V _{IN} = 5.5V			-100			-150	μA
I _{IH} High				40			50	
I _{OLK} Output Current Leakage (82S150)	V _{CC} = max V _{OUT} = 5.5V V _{OUT} = 5.5V V _{OUT} = .45V V _{OUT} = 0V			40			60	μA
I _{O(OFF)} Hi-Z state (82S151)				40			60	μA
I _{OS} Short circuit (82S151) ^{4,6,7}		-20		-70	-15		-85	mA
I _{CC} V _{CC} supply current ⁸	V _{CC} = max		130	155		130	155	mA
C _{IN} Capacitance Input	V _{CC} = 5V V _{IN} = 2.0V V _B = 2.0V		8			8		pF
C _B I/O			15			15		

AC ELECTRICAL CHARACTERISTICS R₁ = 470Ω, R₂ = 1KΩ
N82S150/151: 0°C ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S150/151: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TO	FROM	TEST CONDITIONS	N82S150/151			S82S150/151			UNIT
				Min	Typ ²	Max	Min	Typ ²	Max	
T _{PD} Propagation delay	Output ±	Input ±	C _L = 30pF		25	30		25		ns
T _{OE} Output enable	Output-	Input ±			25	30		25		ns
T _{OD} Output disable ⁹	Output+	Input ±	C _L = 5pF		25	30		25		ns

NOTES

- Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device of these or any other condition above those indicated in the operation of the device specifications is not implied.
- All typical values are at V_{CC} = 5V, T_A = 25°C.
- All voltage values are with respect to network ground terminal.
- Test one at a time.
-
-
- Duration of short circuit should not exceed 1 second.
-
- Measured at V_T = V_{OL} + 0.5V.

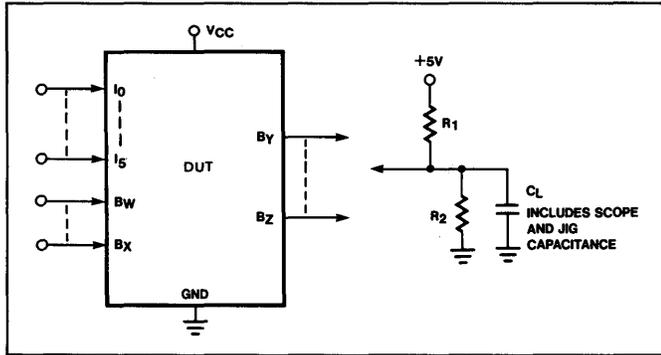
FIELD PROGRAMMABLE GATE ARRAY (18X12)

82S150 (O.C.)/82S151 (T.S.)

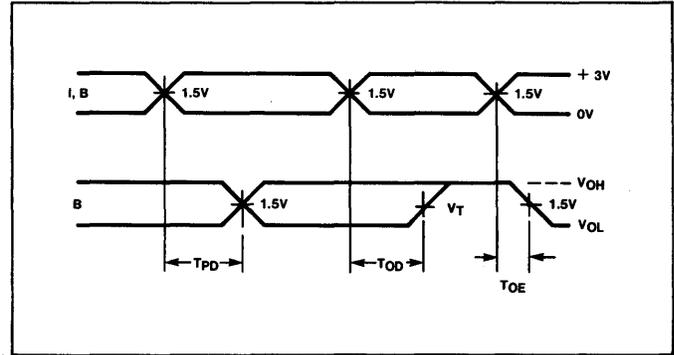
Preview

INTEGRATED FUSE LOGIC
SERIES 20

TEST LOAD CIRCUIT



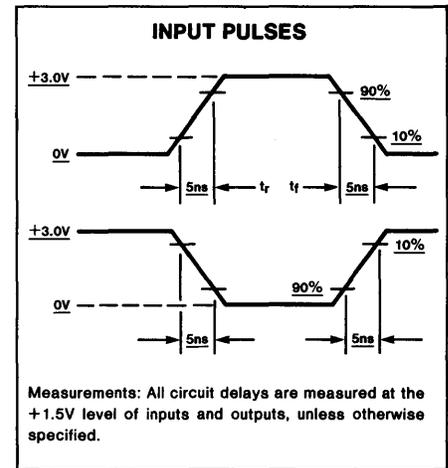
TIMING DIAGRAM



TIMING DEFINITIONS

- TPD** Propagation delay between input and output.
- TOD** Delay between input change and when output is off (Hi-Z or High).
- TOE** Delay between input change and when output reflects specified output level.

VOLTAGE WAVEFORM



FIELD PROGRAMMABLE GATE ARRAY (18X12)

82S150 (O.C.)/82S151 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

LOGIC PROGRAMMING

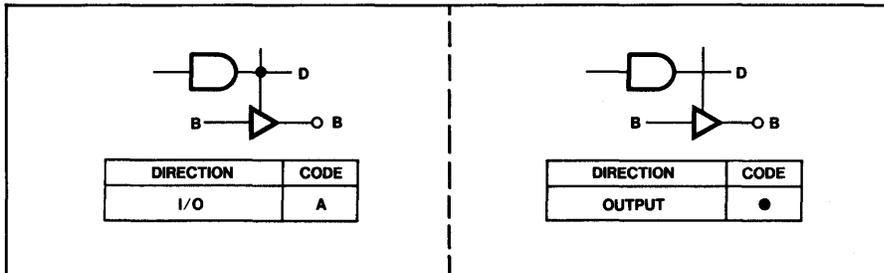
In a virgin device all Ni-Cr links are intact.

The FPGA can be programmed by means of Logic programming equipment.

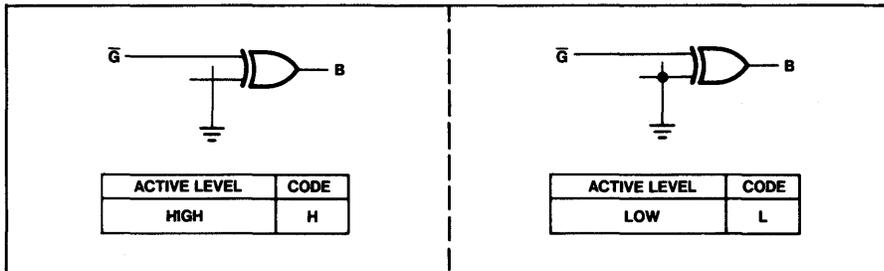
With Logic programming, the AND/EX-OR gate input connections necessary to implement the desired logic function are coded directly from logic equations using the Program Table on the following page.

In this Table the logic state or action of variables I and B associated with each gate Gn, Dn is assigned a symbol which results in the proper fusing pattern of corresponding links defined as follows:

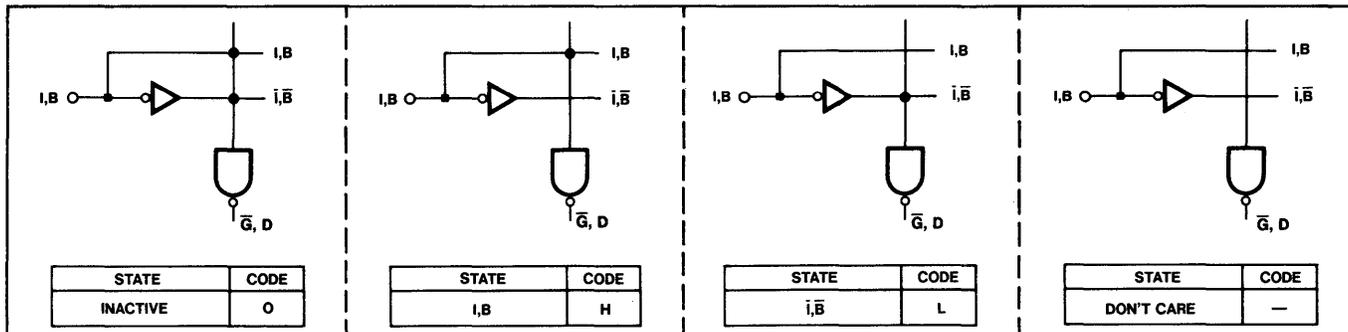
I/O DIRECTION —(B)



EX-OR ARRAY —(B)



“AND” ARRAY —(I,B)



NOTES

1. This is the initial unprogrammed state of all link pairs. It is normally associated with all unused (inactive) AND gates Gn, Dn.
2. Any gate Gn, Dn will be unconditionally inhibited if any one of its (I, B) link pairs is left intact.

FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

DESCRIPTION

The 82S152 and 82S153 are two-level logic elements, consisting of 32 AND gates and 10 OR gates with fusible link connections for programming I/O polarity and direction.

All AND gates are linked to 8 inputs (I) and 10 bidirectional I/O lines (B). These yield variable I/O gate configurations via 10 direction control gates (D), ranging from 18 inputs to 10 outputs.

On chip T/C buffers couple either True (I, B) or Complement (\bar{I} , \bar{B}) input polarities to all AND gates, whose outputs can be optionally linked to all OR gates. Their output polarity, in turn, is individually programmable through a set of EX-OR gates for implementing AND-OR or AND-NOR logic functions.

The 82S152 and the 82S153 are field programmable, enabling the user to quickly generate custom patterns using standard programming equipment.

Both devices are available in a 20 pin slim line package. For the commercial temperature range (0°C to +75°C) specify N82S152/153 N or F. For the military temperature range (-55°C to +125°C) specify S82S152/153 F only.

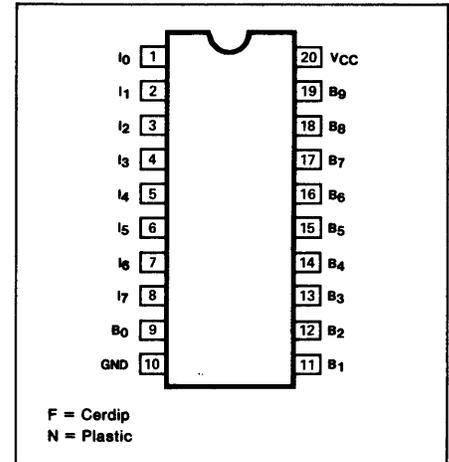
FEATURES

- Field programmable (Ni-Cr links)
- 8 inputs
- 32 AND gates
- 10 OR gates
- 10 bidirectional I/O lines
- Active high or low outputs
- I/O propagation delay:
N82S152/153: 40ns (max)
S82S152/153: 60ns (max)
- Input loading
N82S152/153: -100µA (max)
S82S152/153: -150µA (max)
- Power dissipation:
650mW (typ)
- Output options:
82S152: open collector
82S153: tri-state
- TTL compatible

APPLICATIONS

- Random logic
- Code converters
- Fault detectors
- Function generators
- Address mapping
- Multiplexing

PIN CONFIGURATION



LOGIC FUNCTION

Typical product term:

$$P_n = A \cdot \bar{B} \cdot C \cdot D \cdot \dots$$

Typical logic function:

At L = Closed

$$X = P_0 + P_1 + P_2 \dots$$

At L = Open

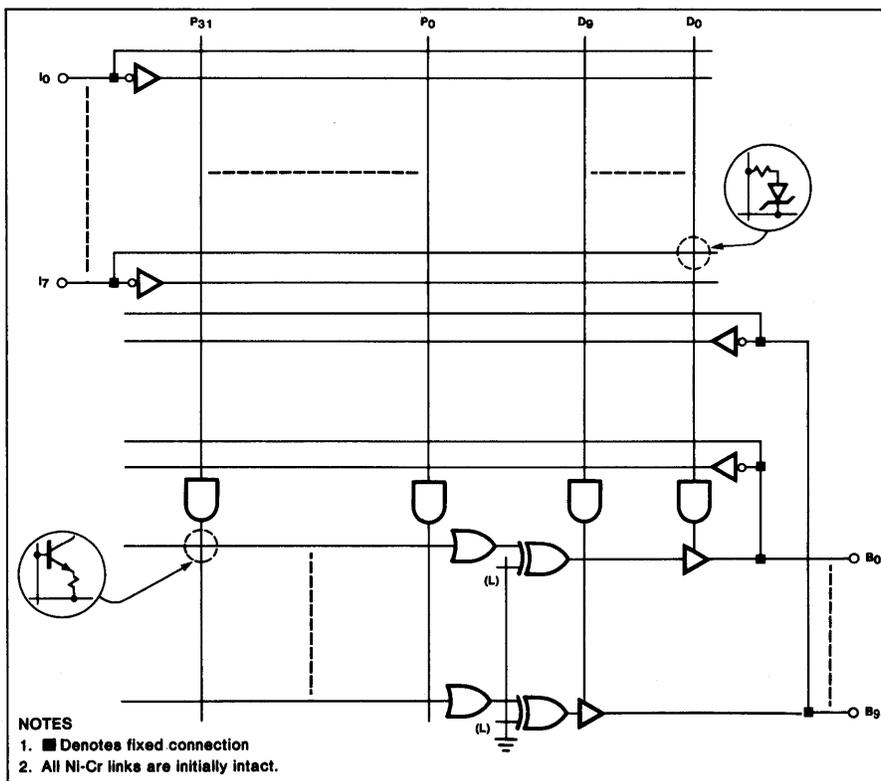
$$X = \bar{P}_0 + \bar{P}_1 + \bar{P}_2 + \dots$$

$$X = \bar{P}_0 \cdot \bar{P}_1 \cdot \bar{P}_2 \dots$$

NOTES

1. For each of the 10 outputs, either function X (active high) or \bar{X} (active low) is available, but not both. The desired output polarity is programmed via link (L).
2. X, A, B, C, etc. are user defined connections to fixed inputs (I) and bidirectional pins (B).

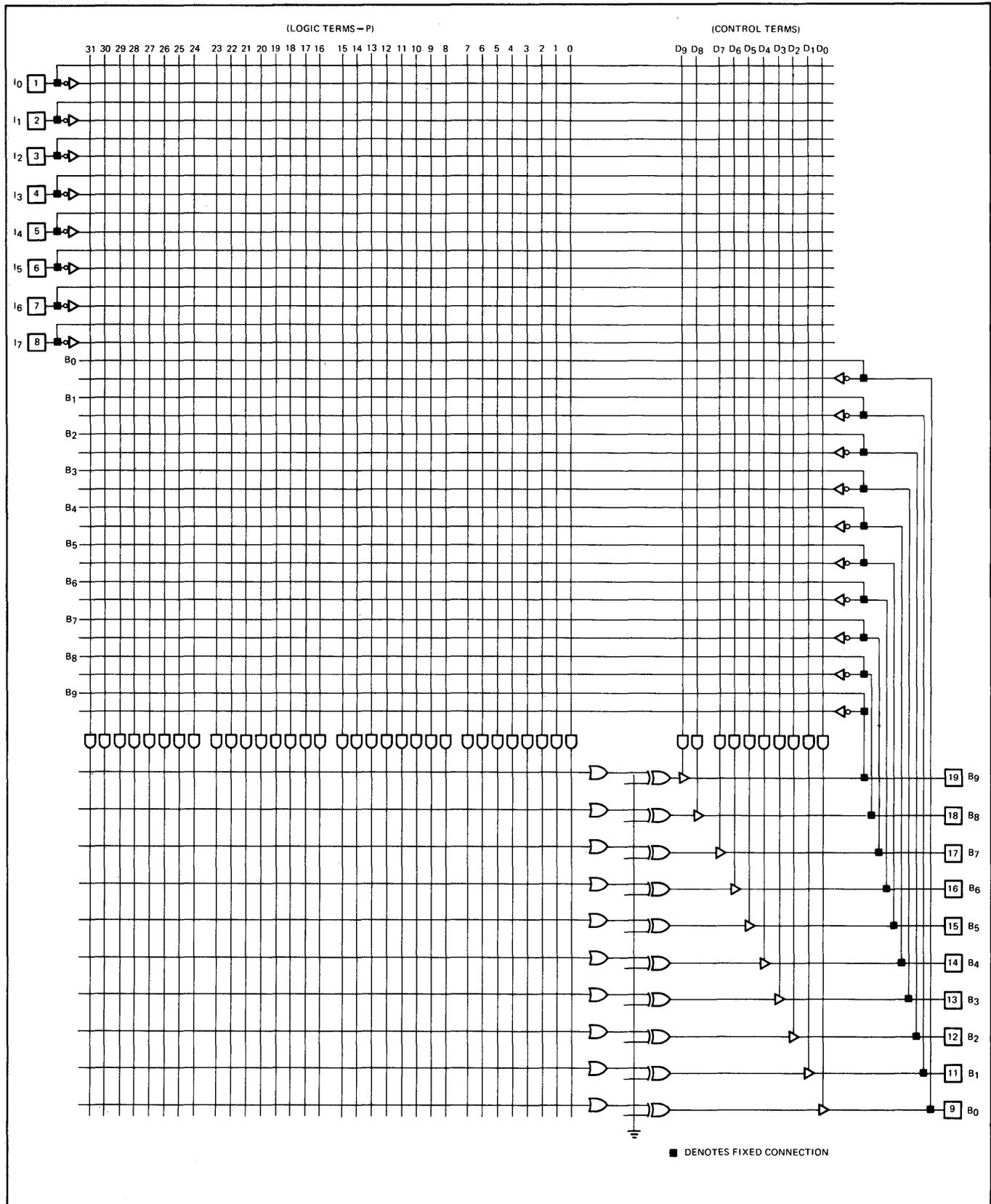
FUNCTIONAL DIAGRAM



FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

FPLA LOGIC DIAGRAM



FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

ABSOLUTE MAXIMUM RATINGS¹

THERMAL RATINGS

PARAMETER	RATING		UNIT
	Min	Max	
V _{CC}	Supply voltage	+7	Vdc
V _{IN}	Input voltage	+5.5	Vdc
V _{OUT}	Output voltage	+5.5	Vdc
I _{IN}	Input currents	-30	mA
I _{OUT}	Output currents	+100	mA
T _A	Temperature range		C°
T _{STG}	Operating	0	+75
	N82S152/153	-55	+125
	S82S152/153	-65	+150
	Storage		

TEMPERATURE	Military	Commercial
Maximum junction	175°C	150°C
Maximum ambient	125°C	75°C
Allowable thermal rise ambient to junction	50°C	75°C

DC ELECTRICAL CHARACTERISTICS

N82S152/153: 0°C ≤ T_A ≤ +75°C, 4.75 ≤ V_{CC} ≤ 5.25V
S82S152/153: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TEST CONDITION	N82S152/153			S82S152/153			UNIT
		Min	Typ ²	Max	Min	Typ ²	Max	
V _{IL}	Input voltage ³ Low	2.0	-	.85	2.0	-	.80	V
V _{IH}	High							
V _{IC}	Clamp ^{3,4}							
		V _{CC} = min, I _{in} = -18mA						
V _{OL}	Output voltage Low ^{3,5}	2.4		.5	2.4		.5	V
V _{OL}	Low ^{3,5}							
V _{OH}	High ^{3,6}							
		V _{CC} = min I _{OL} = 15mA I _{OL} = 12mA I _{OH} = -2mA						
I _{IL}	Input current Low			-100			-150	μA
I _{IH}	High							
		V _{IN} = 0.45V V _{IN} = 5.5V						
I _{OLK}	Output current Leakage (82S152)	-20		40			60	μA
I _{O(OFF)}	Hi-Z state (82S153)							
I _{OS}	Short circuit (82S153) ^{4,6,7}							
		V _{CC} = max V _{OUT} = 5.5V V _{OUT} = 5.5V V _{OUT} = .45V V _{OUT} = 0V						
I _{CC}	V _{CC} supply current ⁸		130	155		130	165	mA
C _{IN}	Capacitance Input		8			8		pF
C _B	I/O		15			15		pF
		V _{CC} = 5V V _{IN} = 2.0V V _B = 2.0V						

AC ELECTRICAL CHARACTERISTICS

R₁ = 470Ω, R₂ = 1KΩ
N82S152/153: 0°C ≤ T_a ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
S82S152/153: -55°C ≤ T_a ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TO	FROM	TEST CONDITIONS	N82S152/153			S82S152/153			UNIT
				Min	Typ	Max	Min	Typ	Max	
T _{PD}	Propagation delay	Output ±	Input ±		30	40		30	55	ns
T _{OE}	Output enable	Output-	Input ±		25	35		25	45	ns
T _{OD}	Output disable ⁹	Output+	Input ±		25	35		25	45	ns
				C _L = 30pF				C _L = 5pF		

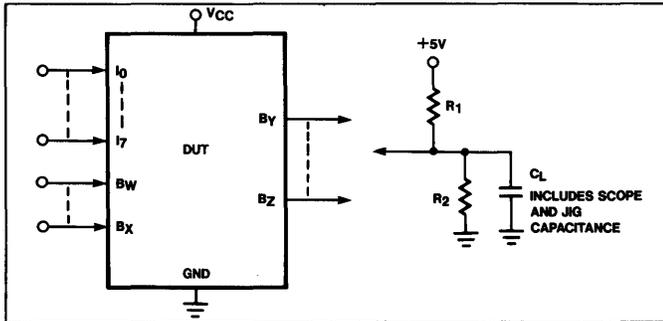
NOTES

- Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device of these or any other condition above those indicated in the operation of the device specifications is not implied.
- All typical values are at V_{CC} = 5V, T_A = 25°C
- All voltage values are with respect to network ground terminal.
- Test one at a time.
- Measured with +10V applied to I₇.
- Measured with +10V applied to I₀₋₇. Output sink current is supplied thru a resistor to V_{CC}.
- Duration of short circuit should not exceed 1 second.
- I_{CC} is measured with I₀₋₇ and B₀₋₉ at 4.5V.
- Measured at V_T = V_{OL} + 0.5V.

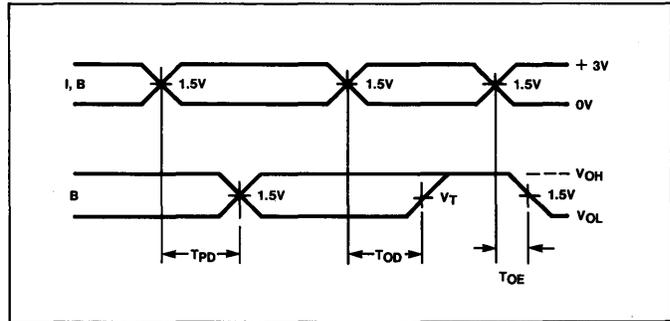
FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

TEST LOAD CIRCUIT



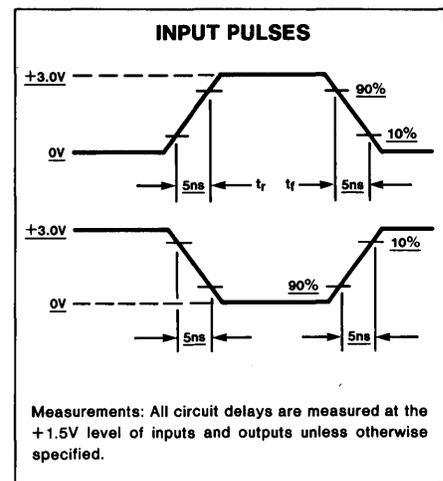
TIMING DIAGRAM



TIMING DEFINITIONS

- TPD** Propagation delay between input and output.
- TOD** Delay between input change and when output is off (Hi-Z or High).
- TOE** Delay between input change and when output reflects specified output level.

VOLTAGE WAVEFORM



FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

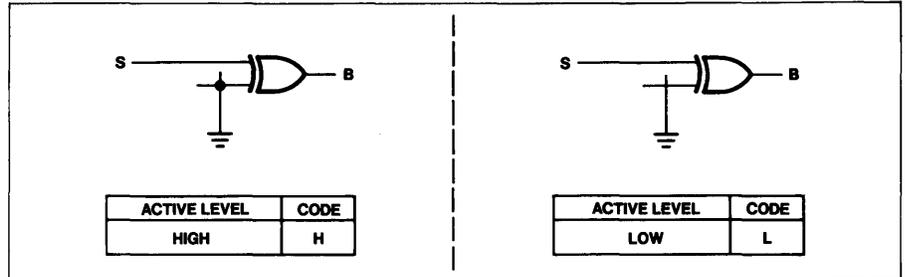
LOGIC PROGRAMMING

The FPLA can be programmed by means of Logic programming equipment.

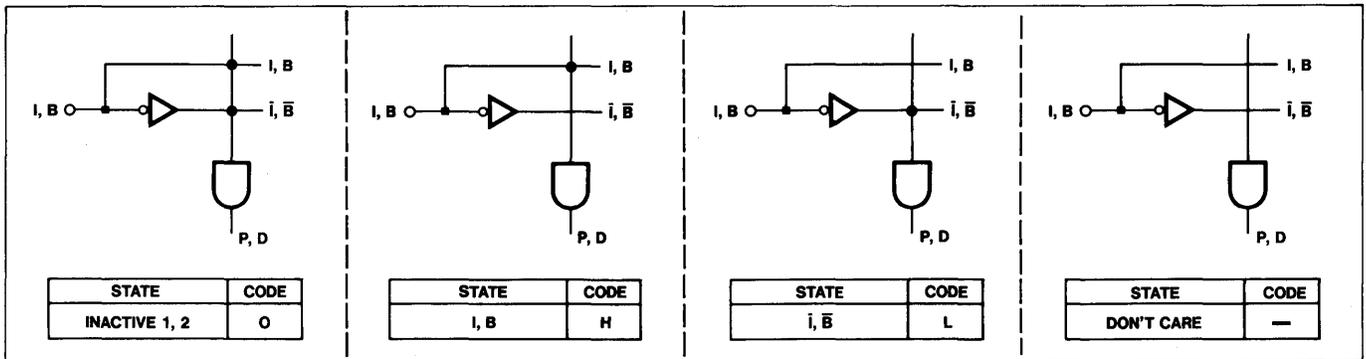
With Logic programming, the AND/OR/EX-OR gate input connections necessary to implement the desired logic function are coded directly from logic equations using the Program Table on the following page.

In this Table the logic state or action of variables I, P, and B associated with each Sum Term S is assigned a symbol which results in the proper fusing pattern of corresponding link pairs, defined as follows:

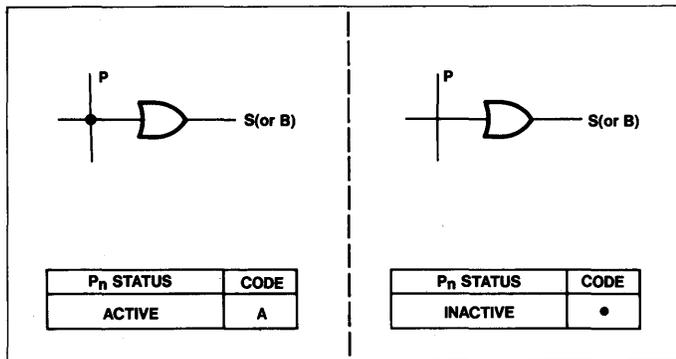
EX-OR ARRAY - (B)



“AND” ARRAY - (I,B)



“OR” ARRAY - (B)



NOTES

1. This is the initial unprogrammed state of all link pairs. It is normally associated with all unused (inactive) AND gates P_n, D_n.
2. Any gate P_n, D_n will be unconditionally inhibited if any one of its (I, B) link pairs is left intact.

FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

VIRGIN STATE

A factory shipped virgin device contains all fusible links intact, such that:

1. All outputs at "H" polarity.
2. All P_n terms are disabled.
3. All P_n terms are active on all outputs.
4. Test array is programmed with standard test pattern.

RECOMMENDED PROGRAMMING PROCEDURE

To program the AND, OR, and polarity arrays, the following procedure should be followed. To maximize recovery from programming errors, leave all links in unused device areas intact.

SET-UP

Terminate all device outputs with a 10k Ω resistor to V_{CC} . Set GND (pin 10) to 0V.

PROGRAM-VERIFY

1. SET-UP:

With V_{CC} at GND and B_8 to V_{FSV} select the fuse to be programmed by applying TTL voltage levels to the input sets in accordance with the binary address map on page 8. Also set $B_1 = V_{IH}$, and $B_7 = V_{IL}$. After t_D delay raise V_{CC} to V_{CCP} .

2. PROGRAM CYCLE:

After a delay of t_D raise B_7 to V_{IH} . After another t_D , raise B_8 to V_{FSP} . Following t_D delay, pulse B_1 to V_{IL} for a duration of t_p . Wait t_D and return B_8 to V_{FSV} , and then after t_D return B_7 to V_{IL} .

3. VERIFY CYCLE:

After a t_D delay lower B_1 to V_{IL} for a duration of t_v . At the end of t_v , B_8 should indicate a level of V_{OH} ; a level of V_{OL} indicates an unsuccessful fusing attempt.

4. NEXT VARIABLE SELECT (I_m , D_s , X_R) (SAME TERM P_n):

After t_D delay, apply the next variable select (I, D, X) address to the input set and continue with step 2.

5. NEXT VARIABLE SELECT (I_m , D_s , X_R) (DIFFERENT TERM (P_n)):

After t_D delay apply the next variable select (I, D, X) and term (P_n) addresses to the input set then continue to step 2.

FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

**PROGRAM CYCLE ROW/COLUMN FUSE ADDRESSING
VARIABLE SELECT Table¹**

ROW HEX ADDRESS		SELECTED VARIABLE	
I ₆ I ₇ B ₀	B ₂ B ₃ B ₄ B ₅		
0	0	AND Array	
0	1		
0	2		
0	3		
0	4		
0	5		
0	6		
0	7		
0	8		
0	9		
0	A		
0	B		
0	C		
0	D		
0	E		
0	F		
1	0	B ₉ B ₉	
1	1		
1	2		B ₈ B ₈
1	3		
1	4		B ₇ B ₇
1	5		
1	6		B ₆ B ₆
1	7		
1	8	B ₅ B ₅	
1	9		
1	A	B ₄ B ₄	
1	B		
1	C		B ₃ B ₃
1	D		
1	E	B ₂ B ₂	
1	F		
2	0	B ₁ B ₁	
2	1		
2	2	B ₀ B ₀	
2	3		
2	4	Empty Address Space	
2	5		
2	6		
2	7		
2	8		
2	9		
2	A		
2	B		
2	C		
2	D		
2	E		
2	F		

TERM SELECT Table²

ROW HEX ADDRESS		SELECTED VARIABLE
I ₆ I ₇ B ₀	B ₂ B ₃ B ₄ B ₅	
3	0	OR Array
3	1	
3	2	
3	3	
3	4	
3	5	
3	6	
3	7	
3	8	
3	9	
3	A	Polarity Enable
3	B	Empty Address Space
3	C	
3	D	
3	E	
3	F	

COLUMN HEX ADDRESS		SELECTED PRODUCT TERM
I ₀ I ₁	I ₂ I ₃ I ₄ I ₅	
0	0	Logic Terms
0	1	
0	2	
0	3	
0	4	
0	5	
0	6	
0	7	
0	8	
0	9	
0	A	
0	B	
0	C	
0	D	
0	E	
0	F	
1	0	
1	1	
1	2	
1	3	
1	4	
1	5	
1	6	
1	7	
1	8	
1	9	
1	A	
1	B	
1	C	
1	D	
1	E	
1	F	
2	0	Control Terms
2	1	
2	2	
2	3	
2	4	
2	5	
2	6	
2	7	
2	8	
2	9	
2	A	Polarity Terms
2	B	
2	C	
2	D	
2	E	
2	F	
3	0	
3	1	
3	2	
3	3	

NOTES

1. A row address identifies a particular variable coupled to all product terms.
2. With a variable selected by the row address the column address further selects a coupling fuse for each term.

FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

PROGRAMMING SYSTEM SPECIFICATIONS¹ (T_A = + 25°C)

PARAMETER	TEST CONDITIONS	LIMITS			UNIT	
		Min	Typ	Max		
V _{CCP} I _{CCP}	V _{CC} supply (program) I _{CC} limit program	I _{CCP} = 550mA min V _{CCP} = + 8.50 ± .25V	8.25 550	8.5	8.75 1,000	V mA
V _{IH} V _{IL}	Input voltage High Low		2.4 0	0.4	5.5 0.8	V
I _{IH} I _{IL}	Input Current High Low	V _{IH} = + 5.5V V _{IL} = 0V			50 - 500	μA
V _{FSP}	Fuse supply (program) ³	I _{FSP} = 300 ± 25mA Transient or steady state	16.0	17.0	18.0	V
V _{FSV}	Fuse supply (idle)	I _{FSV} = 1mA max	1.25	1.5	1.75	V
I _{FSP}	Fuse supply current limit	V _{FSP} = + 17 ± 1V	275	300	325	mA
t _v	Verify time		1			μs
T _{RS}	Reset pulse width		1			μs
T _{PS}	Preset pulse width		1			μs
t _p	Programming pulse width		0.3	0.4	0.5	ms
t _D	Pulse sequence delay		10			μs
T _R	Fuse pulse rise time	10% to 90%	10		50	μs
T _{PVB}	Program-Verify time per link			0.6		ms
P _{DC}	Programming duty cycle				100	%
F _L	Fusing attempts per link				2	cycle
V _S	Verify threshold ⁴		1.4	1.5	1.6	V

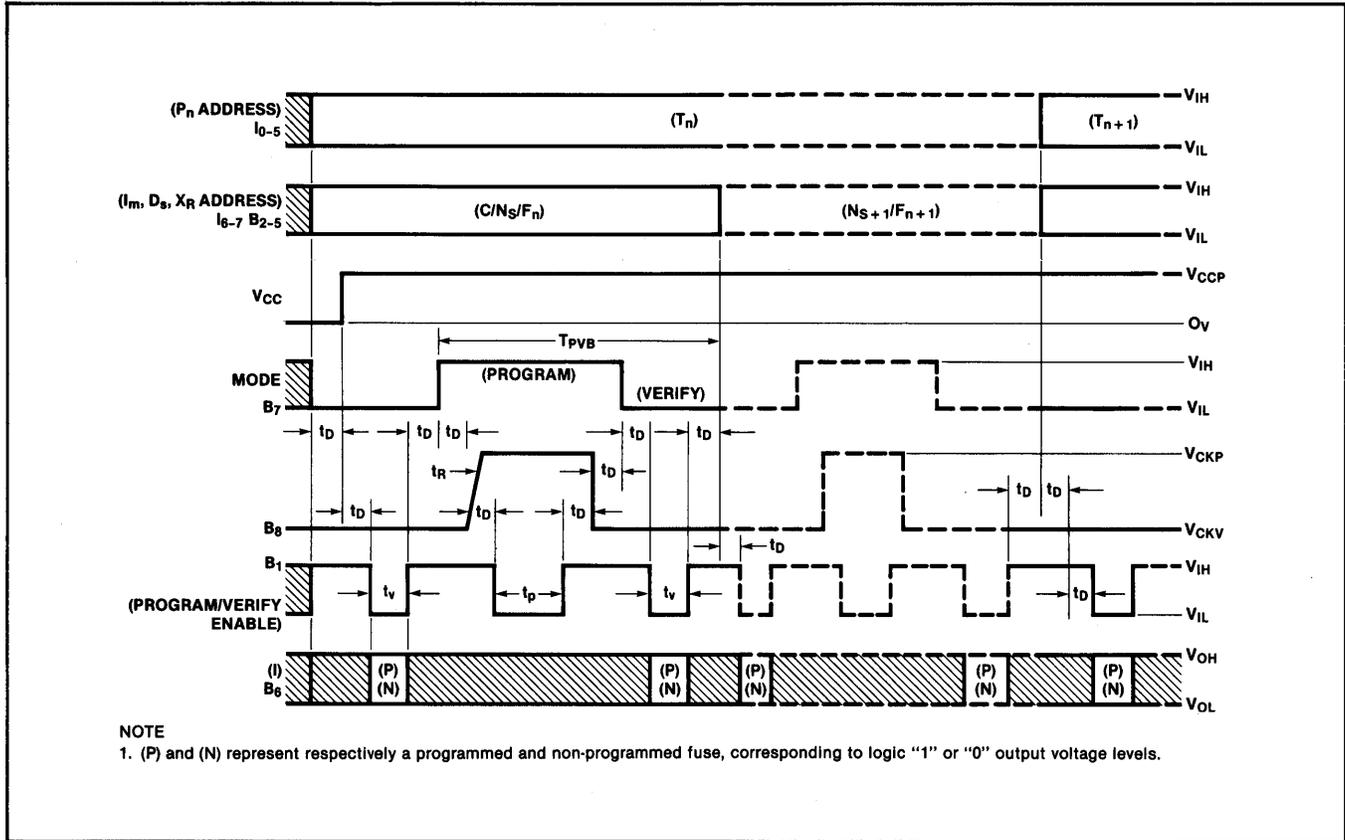
NOTES

1. These are specifications which a Programming System must satisfy in order to be qualified by Signetics.
2. Bypass V_{CC} to GND with a 0.01μf capacitor to reduce voltage spikes.
3. Care should be taken to ensure that the voltage is maintained during the entire fusing cycle. The recommended supply is a constant current source clamped at the specified voltage limit.
4. V_S is the sensing threshold of the FPLA output voltage for a programmed link. It normally constitutes the reference voltage applied to a comparator circuit to verify a successful fusing attempt.

FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

INTEGRATED FUSE LOGIC
SERIES 20

ARRAY PROGRAM-VERIFY SEQUENCE (TYPICAL)



FIELD PROGRAMMABLE LOGIC ARRAY (18X32X10) 82S152 (O.C.)/82S153 (T.S.)

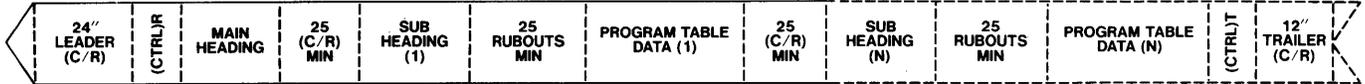
INTEGRATED FUSE LOGIC SERIES 20

TWX TAPE CODING (LOGIC FORMAT)

The FPLA Program Table can be sent to Signetics in ASCII code format via airmail using any type of 8-level tape (paper, mylar,

fanfold, etc.), or via TWX: just dial (910) 339-9283, tell the operator to turn the paper puncher on, and acknowledge. At the end of transmission instruct the operator to send tape to Signetics Order Entry.

A number of Program Tables can be sequentially assembled on a continuous tape as follows, however, limit tape length to a roll of 1.75 inch inside diameter and 4.25 inch outside diameter.



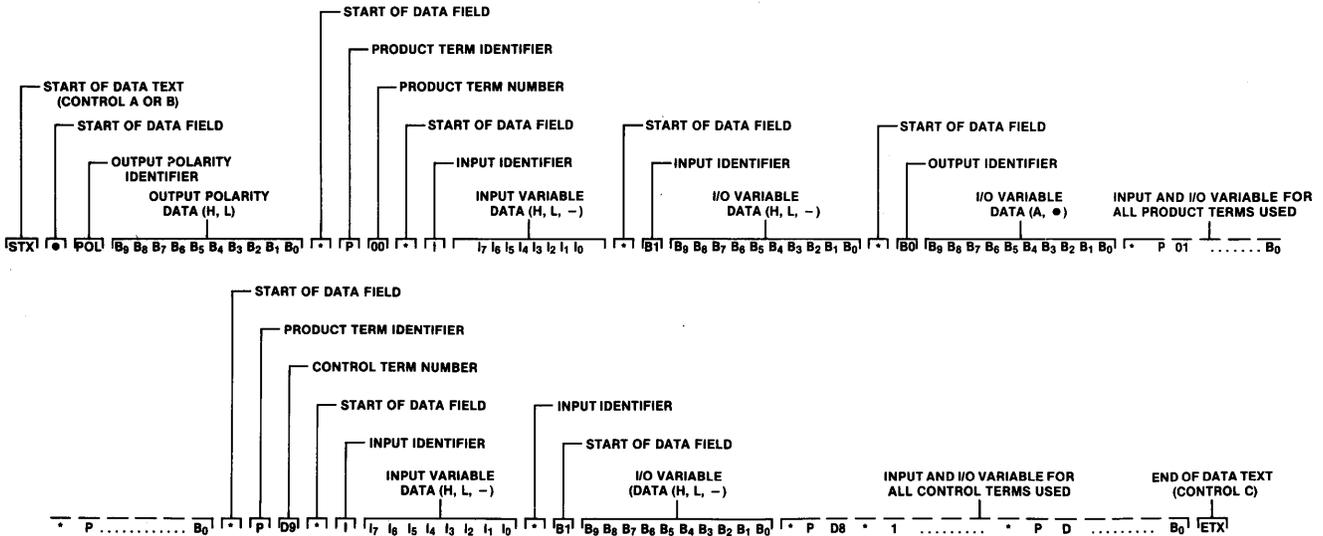
A. The MAIN HEADING at the beginning of tape includes the following information, with each entry preceded by a (\$) character, whether used or not:

- 1. Customer Name _____
- 2. Customer TWX No. _____
- 3. Date _____
- 4. Purchase Order No. _____
- 5. Number of Program Tables _____
- 6. Total Number of Parts _____

B. Each SUB HEADING should contain specific information pertinent to each Program Table as follows, with each entry preceded by a (\$) character, whether used or not:

- 1. Signetics Device No. _____
- 2. Program Table No. _____
- 3. Revision _____
- 4. Date _____
- 5. Customer Symbolized Part No. _____
- 6. Number of Parts _____

C. Program Table data blocks are initiated with an STX character, and terminated with an ETX character. The body of the data consists of output polarity, product term, and output information separated by appropriate identifiers in accordance with the following format:



Entries for the Data Field are determined in accordance with the following tables:

I, B (I)	
Inactive	0
I, B	H
I, B	L
Don't Care	-

(AND)

B (0)	
Active	A
Inactive	•

(OR)

B (0)	
High	H
Low	L

(POL.)

**FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)**

82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

**INTEGRATED FUSE LOGIC
SERIES 20**

DESCRIPTION

The 82S154/155/156/157/158/159 are Open Collector and Tri-state registered logic elements combining AND/OR gate arrays with clocked J/K flip-flops, optionally convertible to D-type via a "foldback" inverting buffer. They all have similar organization, featuring respectively 4, 8, or 8 registered I/O outputs (F), in conjunction with 8, 6, or 4 bidirectional I/O lines (B). These yield variable I/O gate and register configurations via control gates (D, L) ranging from 16 inputs to 12 outputs.

The AND/OR arrays consist of 32 AND gates and 21 OR gates with fusible link connections for programming I/O polarity and direction. All AND gates are linked to 4 inputs (I), bidirectional I/O lines (B), internal flip-flop outputs (Q), and Complement Array output (C). The Complement Array consists of a NOR gate optionally linked to all AND gates for generating and propagating complementary AND terms.

On chip T/C buffers couple either True (I, B, Q) or Complement (I, B, Q, C) input polarities to all AND gates, whose outputs can be optionally linked to all OR gates. One group of OR gates drives bidirectional I/O lines (B), whose output polarity is individually programmable thru a set of EX-OR gates for implementing AND-OR or AND-NOR logic functions. Another group drives the J-K inputs of all flip-flops, as well as asynchronous Preset and Reset lines (P, R), (except the 82S158/159, where AND functions are provided).

All flip-flops are positive edge trigger and can be used as input, output, or I/O (for interfacing with a bidirectional data bus) in conjunction with load control gates (L), steering inputs (I), (B), (Q) and programmable output select lines (E).

The 82SXXX are field programmable, enabling the user to quickly generate custom patterns using standard programming equipment.

FLIP-FLOP TRUTH TABLE

V _{CC}	O.E.	L	C	K	P	R	J	K	Q	F
	H									H/Hi-Z
↑	L	X	X	L	X	X	X	X	L	H
+5	L	X	X	H	L	X	X	X	H	L
	L	X	X	L	H	X	X	X	L	H
	L	L	↑	L	L	L	L	L	Q	Q̄
	L	L	↑	L	L	L	H	H	L	H
	L	L	↑	L	L	H	L	L	H	L
	L	L	↑	L	L	H	H	H	Q	Q
H	H	↑	L	L	L	H	L	L	L	H*
	H	↑	L	L	H	L	L	L	H	L*
+10V	X	↑	X	X	L	H	L	L	L	H**
	X	↑	X	X	H	L	L	L	L	L**

NOTES

- Positive Logic:
 $J/K = T_0 + T_1 + T_2 \dots T_{47}$
 $T_n = \bar{C} \cdot (I_0 \cdot I_1 \cdot I_2 \dots) \cdot (Q_0 \cdot Q_1 \dots) \cdot (B_0 \cdot B_1 \dots)$
- ↑ denotes transition from Low to High level.
- X = Don't Care
- * = Forced at F_n pin for loading J/K flip-flop in I/O mode. L must be enabled, and other active T_n disabled via steering input(s) I, B, or Q.
- At P = R = H, Q = H. The final state of Q depends on which is released first.
- ** = Forced at F_n pin to load J/K flip-flop independent of program code (Diagnostic mode).

All devices are available in a 20-pin, slim line package. For the commercial temperature range (0°C to +75°C) specify N82SXXX N or F. For the military temperature range (-55°C to +125°C) specify S82SXXX F only.

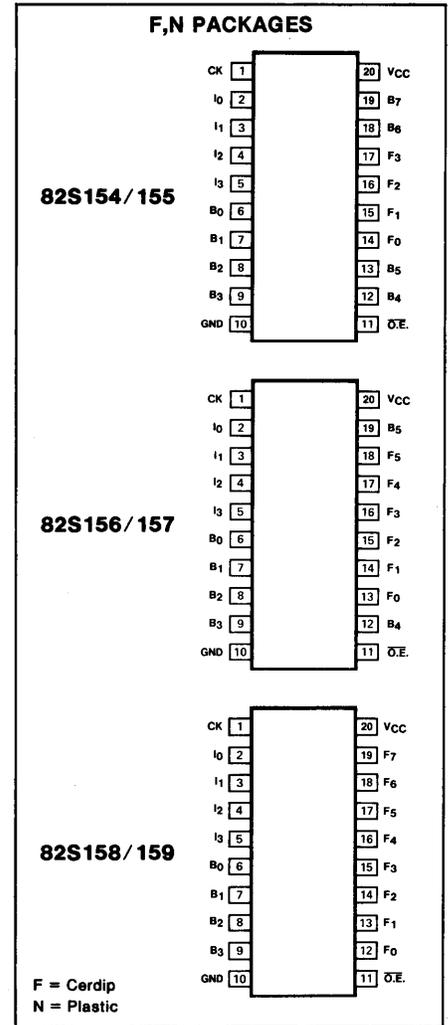
FEATURES

- Field programmable (Ni-Cr link)
- 4 Inputs
- 32 AND gates
- 21 OR gates
- Bidirectional I/O lines: 82S154/155—8
82S156/157—6
82S158/159—4
- Bidirectional Registers: 82S154/155—4
82S156/157—6
82S158/159—8
- J/K, T, or D-type flip-flops
- Asynchronous Preset/Reset
- Complement Array
- Active high or low outputs
- Programmable O.E. control
- Positive edge trigger clock
- Power-on reset of all flip-flops (F_n = "1")
- Clock frequency: N82SXXX: 15 MHz (max)
S82SXXX: MHz (max)
- Input loading: N82SXXX: -100µA (max)
S82SXXX: -150µA (max)
- Power dissipation: 650mW (typ)
- TTL Compatible

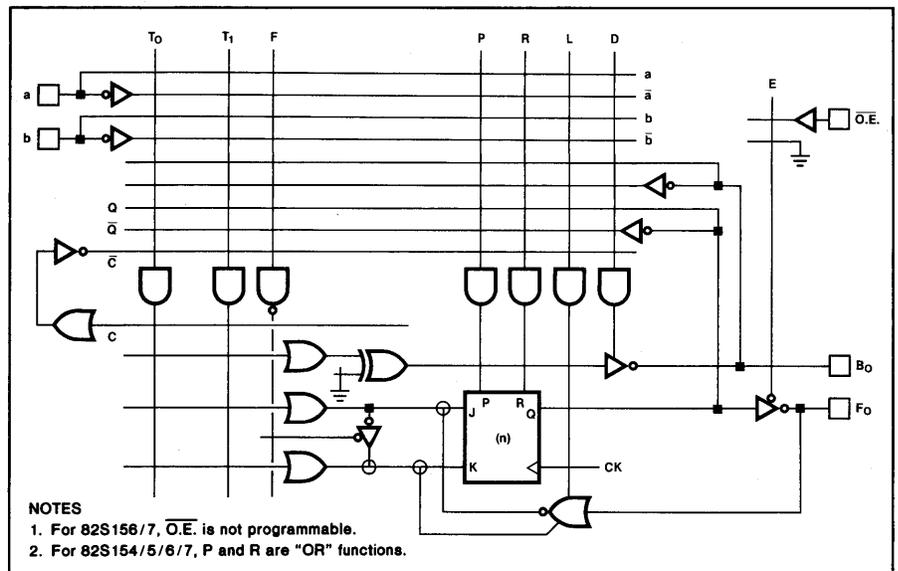
APPLICATIONS

- Random sequential logic
- Synchronous up/down counters
- Shift registers
- Bidirectional data buffers
- Timing function generators
- System controllers/synchronizers
- Priority encoder/registers

PIN CONFIGURATION



FUNCTIONAL DIAGRAM



- NOTES**
- For 82S156/7, O.E. is not programmable.
 - For 82S154/5/6/7, P and R are "OR" functions.

**FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)**

82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

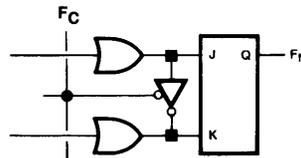
PIN DESIGNATION

PIN NO.	SYMBOL	NAME AND FUNCTION	POLARITY
1	CK	CLOCK The clock input to all flip-flops. A Low-to-High transition on this line is necessary to update the contents of flip-flops.	Active-High
2-5	I ₀₋₃	INPUTS Fixed logic inputs to the AND array	Active-High/Low (user defined)
6-9	B ₀₋₃	STATIC I/O PINS Bidirectional external inputs to the AND array, or outputs from the OR array, programmable via control gates D ₀₋₃ .	Active-High/Low (user defined)
11	O.E.	OUTPUT ENABLE Provides output enable functions E _A and E _B to flip-flop banks F ₀₋₃ and F ₄₋₇ respectively. May be programmed for external control, enable, or disable of flip-flop outputs.	Active-Low
12, 13	(B _n /F _n)*	STATIC OR REGISTERED I/O PINS Bidirectional static or registered I/O pins, dependent on device configuration.	Active-High/Low (user defined)
14-17	(F _n)*	REGISTERED I/O PINS Bidirectional flip-flop outputs or direct load inputs, selected via control gates L _{A-B} in conjunction with E _{A-B} output enables.	Active-Low
18, 19	(B _n /F _n)*	STATIC OR REGISTERED I/O PINS Same as 12, 13.	Active-High/Low (user defined)

(* Value of (n) is device dependent. Refer to circuit diagrams.

FLIP-FLOP FUNCTION

The output flip-flops (F_N) are programmable via the Flip-Flop Control Term (F_C). A tri-state inverter is positioned between the J-K inputs as shown. If (F_C) is programmed as active (A), then F_C controls the output state of the tri-state inverter.



When F_C = High, then flip-flop becomes a J-K type. When F_C = Low, the flip-flop becomes a D-type.

When the F_C is programmed as a • (i.e., disabled), the flip-flop is permanently defined as a J-K type.

LOGIC FUNCTION

COMBINATORIAL										
Typical Product Term:	$P_n = A \cdot \bar{B} \cdot \bar{C} \cdot D \cdot \bar{E} \cdot \dots$									
Typical Logic Function: At link (X) = Open at D _Y = "1"	$Y = P_0 + P_1 + P_2 + \dots$									
At link (X) = Closed	$Y = \overline{P_0 + P_1 + P_2 + \dots}$ $= \bar{P}_0 \cdot \bar{P}_1 \cdot \bar{P}_2 \cdot \dots$									
<hr/>										
SEQUENTIAL (J/K type)										
Typical State Transition:										
<table border="1"> <tr> <td>Q₂</td> <td>Q₁</td> <td>Q₀</td> </tr> <tr> <td>0</td> <td>1</td> <td>0</td> </tr> </table> <p>State Register</p> <table border="1"> <tr> <td>0</td> <td>0</td> <td>1</td> </tr> </table>	Q ₂	Q ₁	Q ₀	0	1	0	0	0	1	<p>Present State S_n</p> <p>$\bar{A} \cdot \bar{B} \cdot C \cdot \dots$</p> <p>Next State S_{n+1}</p>
Q ₂	Q ₁	Q ₀								
0	1	0								
0	0	1								
	<p>SET Q₀: J₀ = $(\bar{Q}_2 \cdot Q_1 \cdot \bar{Q}_0) \cdot \bar{A} \cdot \bar{B} \cdot C \dots$ K₀ = 0</p> <p>RESET Q₁: J₁ = 0 K₁ = $(\bar{Q}_2 \cdot Q_1 \cdot \bar{Q}_0) \cdot \bar{A} \cdot \bar{B} \cdot C \dots$</p> <p>HOLD Q₂: J₂ = 0 K₂ = 0</p>									

NOTES

- For each of the combinatorial outputs, either function Y (active-high) or \bar{Y} (active-low) is available, but not both. The desired output polarity is programmed via link (X).
- Y, A, B, C, etc. are user defined connections to fixed inputs (I), bidirectional pins (B), "foldback" register outputs (Q), and Complement Array (C).
- Sequential state transitions occur on the positive edge of clock. External flip-flop outputs are given by F_n = \bar{Q}_n .
- For D-type flip-flops, K_n = \bar{J}_n . For T-type flip-flops, K_n = J_n.

FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)

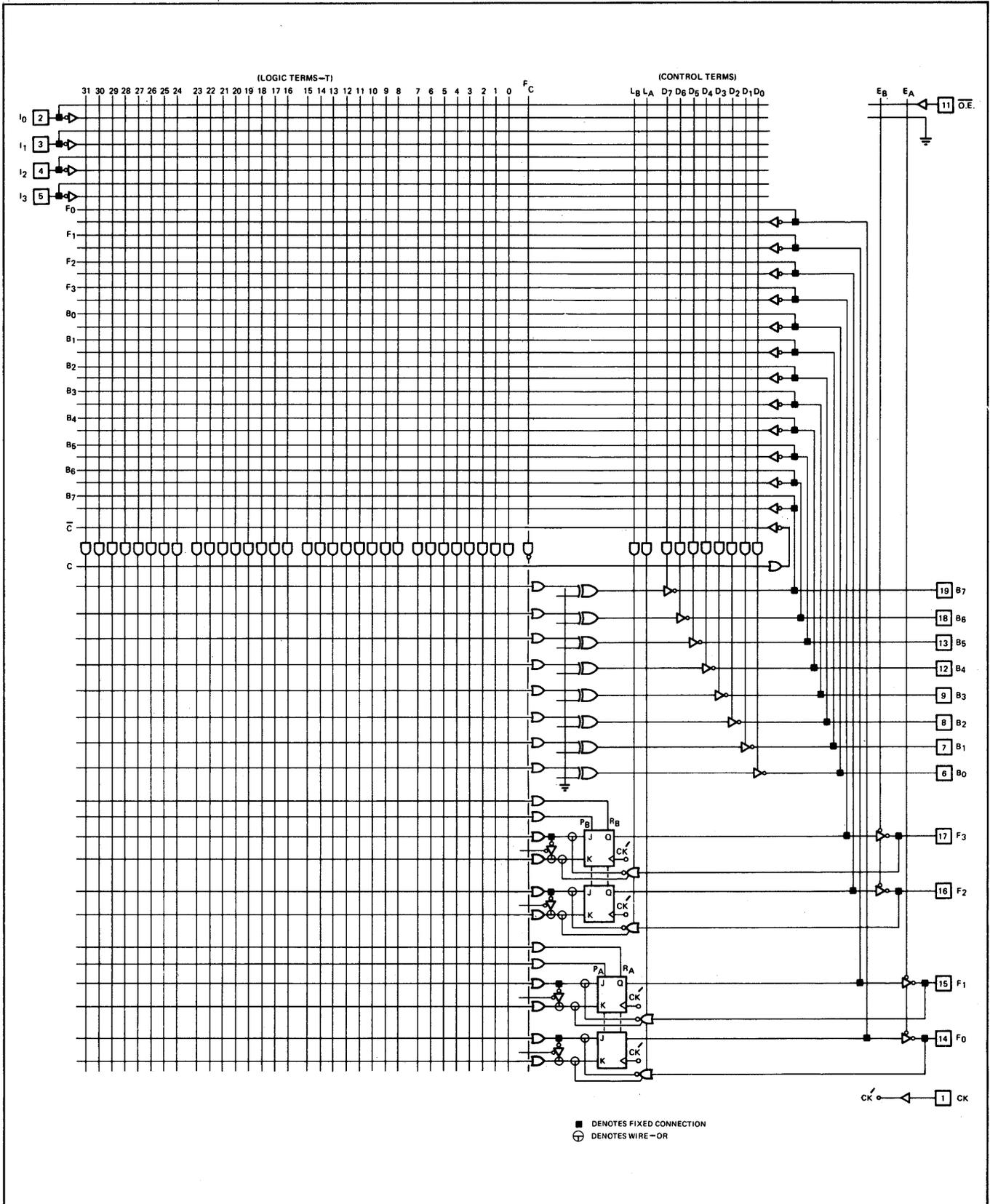
82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

FPLS LOGIC DIAGRAM

82S154/155



FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)

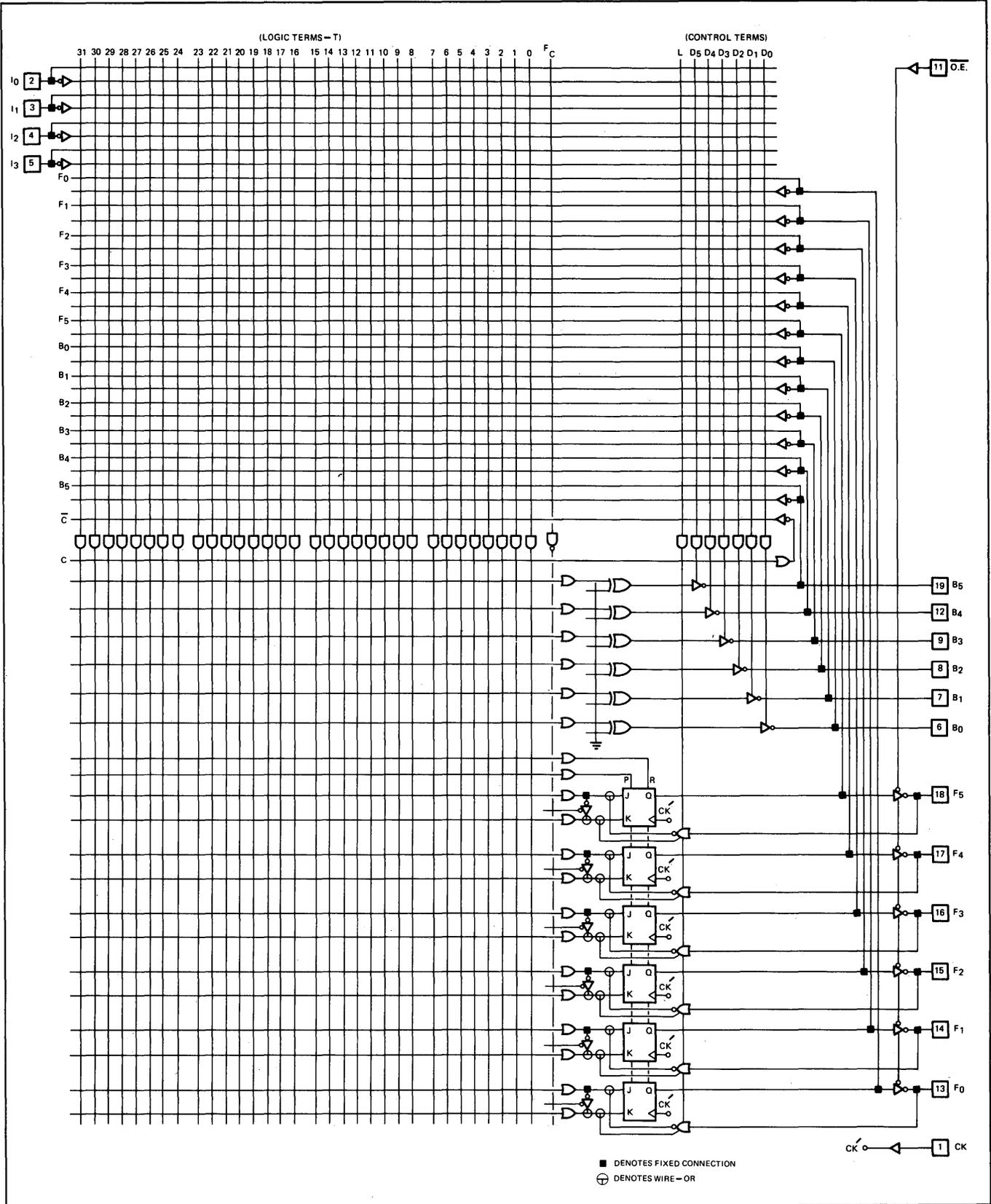
82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

FPLS LOGIC DIAGRAM

82S156/157



FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)

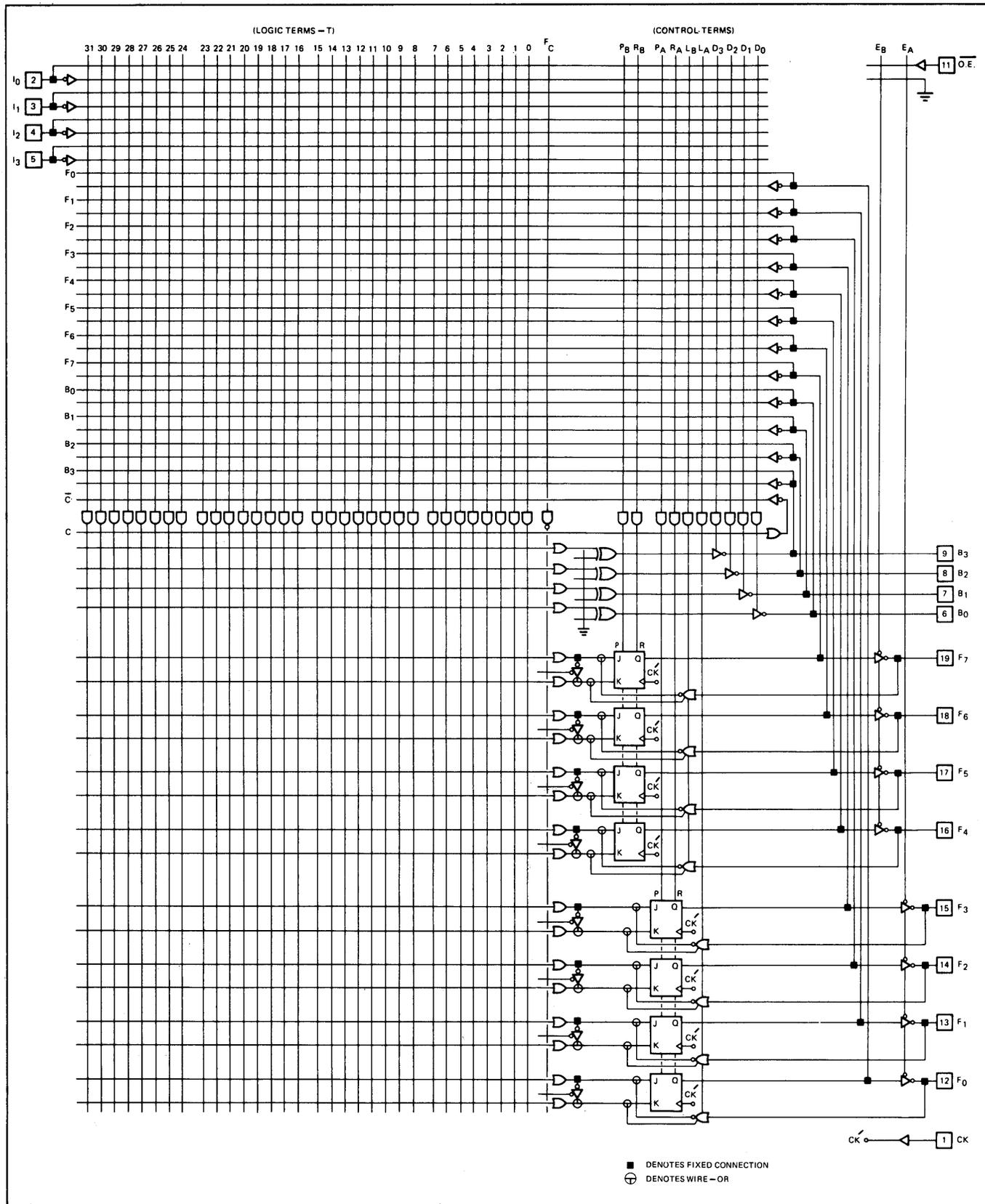
82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

FPLS LOGIC DIAGRAM

82S158/159



**FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)**

82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

ABSOLUTE MAXIMUM RATINGS¹

PARAMETER	RATING		UNIT
	Min	Max	
V _{CC} Supply voltage		+7	Vdc
V _{IN} Input voltage		+5.5	Vdc
V _{OUT} Output voltage		+5.5	Vdc
I _{IN} Input currents	-30	+30	mA
I _{OUT} Output currents		+100	mA
T _A Temperature range			°C
	Operating		
	N82S154/5/6/7/8/9	0	+75
	S82S154/5/6/7/8/9	-55	+125
T _{STG} Storage	-65	+150	

THERMAL RATINGS

TEMPERATURE	MILITARY	COMMERCIAL
Maximum junction	175°C	150°C
Maximum ambient	125°C	75°C
Allowable thermal rise ambient to junction	50°C	75°C

DC ELECTRICAL CHARACTERISTICS

N82S154/5/6/7/8/9: 0° ≤ T_A ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V
 S82S154/5/6/7/8/9: -55°C ≤ T_A ≤ +125°C, 4.5V ≤ V_{CC} ≤ 5.5V

PARAMETER	TEST CONDITIONS	N82S154/5/6/7/8/9			S82S154/5/6/7/8/9			UNIT
		Min	Typ ²	Max	Min	Typ ²	Max	
V _{IH} Input voltage ³ High	V _{CC} = Max V _{CC} = Min V _{CC} = Min, I _{IN} = -18mA	2			2			V
V _{IL} Low				0.85			0.8	
V _{IC} Clamp ^{3,4}			-0.8	-1.2		-0.8	-1.2	
V _{OH} Output voltage High (82S155/7/9) ^{3,5}	V _{CC} = Min I _{OH} = -2mA I _{OL} = 10mA I _{OL} = 10mA	2.4			2.4			V
V _{OL} Low ^{3,6}			0.35	0.5		0.35	0.5	
V _{OL} Low ^{3,6}								
I _{IH} Input current High	V _{IN} = 5.5V V _{IN} = 0.45V V _{IN} = 0.45V		<1	40		<1	50	μA
I _{IL} Low			-10	-100		-10	-150	
I _{IL} Low (CK input)			-50	-250		-50	-350	
I _{OLK} Output current Leakage ⁷	V _{CC} = Max V _{OUT} = 5.5V V _{OUT} = 5.5V V _{OUT} = 0.45V V _{OUT} = 0V		1	40		1	60	μA
I _{O(OFF)} Hi-Z state (82S155/7/9) ⁷			1	40		1	60	μA
I _{OS} Short circuit (82S155/7/9) ^{4,6,7}			-20	-1	-40	-15	-1	-60
I _{CC} V _{CC} supply current ⁹	V _{CC} = Max		130	155		130	155	mA
C _{IN} Capacitance ⁷ Input	V _{CC} = 5.0V V _{IN} = 2.0V V _{OUT} = 2.0V		8			8		pF
C _{OUT} Output				15			15	

NOTES

- Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device of these or any other condition above those indicated in the operation of the device specifications is not implied.
- All typical values are at V_{CC} = 5V, T_A = 25°C.
- All voltage values are with respect to network ground terminal.
- Test one at a time.
-
-
- Measured with V_{IH} applied to $\overline{O.E.}$.
- Duration of short circuit should not exceed 1 second.
- I_{CC} is measured with the $\overline{O.E.}$ input grounded, all other inputs at 4.5V and the outputs open.

**FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)**

82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

INTEGRATED FUSE LOGIC
SERIES 20

AC ELECTRICAL CHARACTERISTICS

$R_1 = 470\Omega, R_2 = 1k\Omega$

N82S154/5/6/7/8/9: $0^\circ\text{C} \leq T_A \leq +75^\circ\text{C}, 4.75\text{V} \leq V_{CC} \leq 5.25\text{V}$

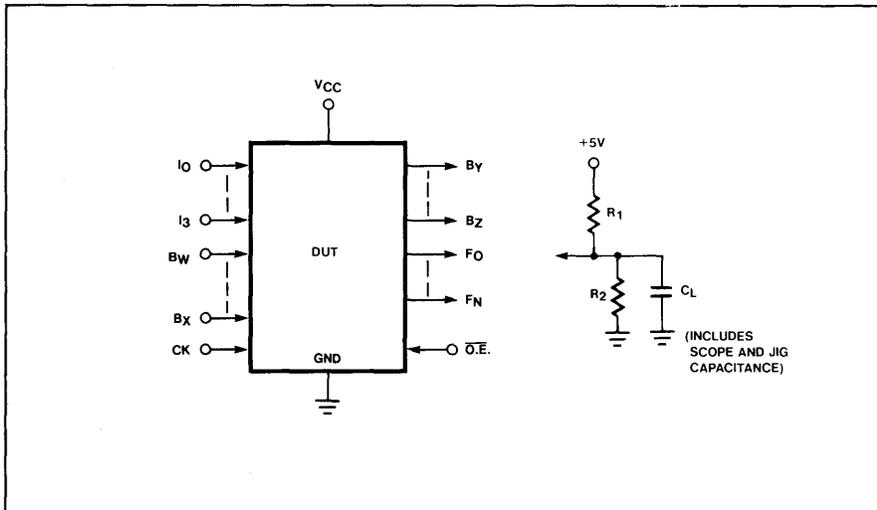
S82S154/5/6/7/8/9: $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}, 4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$

PARAMETER	TO	FROM	TEST CONDITIONS	N82S154/5/6/7/8/9/			S82S154/5/6/7/8/9			UNIT
				Min	Typ ¹	Max	Min	Typ ¹	Max	
T _{CKH} T _{CKL} T _{CKP} T _{PRH}	Pulse width									ns
	Clock ² high	CK-	CK+	25	20			20		
	Clock low	CK+	CK-	25	20			20		
	Period	CK+	CK+	65	50			50		
T _{IS1} T _{IS2} T _{IS3}	Set up time			C _L = 30pF						ns
Input	CK+	(I,B) ±	35		30			30		
Input (through F _n)	CK+	F ±	10		5			5		
	Input (through Complement array) ⁴	CK+	(I,B) ±					40		
T _{IH1} T _{IH2}	Hold time									ns
Input	CK+	(I,B) ±		-10	0			-10		
		CK+	F ±		-5	0		-5		
T _{CKO} T _{OE1} T _{OD1} T _{PD} T _{OE2} T _{OD2} T _{PRO} T _{PPR}	Propagation delay									ns
Clock	F ±	CK+		25	30			25		
Output enable	F-	O.E.-		20	25			20		
Output disable ³	F+	O.E.+	C _L = 5pF	20	25			20		
Output	B ±	(I,B) ±	C _L = 30pF	35	40			35		
Output enable	B ±	(I,B) +		35	40			35		
Output disable ³	B +	(I,B) -	C _L = 5pF	35	40			35		
Preset / Reset	F ±	(I,B) +	C _L = 30pF	50	65			50		
Power-on preset	F-	V _{CC} +		0	10			0		

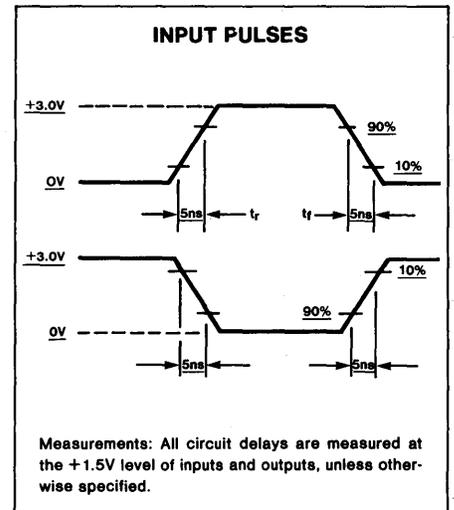
NOTE

1. All typical values are at V_{CC} = 5V, T_A = 25°C.
2. To prevent spurious clocking, clock rise time (10%-90%) ≤ 10ns.
3. Measured at V_T = V_{OL} + 0.5 V.
4. When using the Complement Array T_{CKP} = 75ns (min).

TEST LOAD CIRCUIT



VOLTAGE WAVEFORM



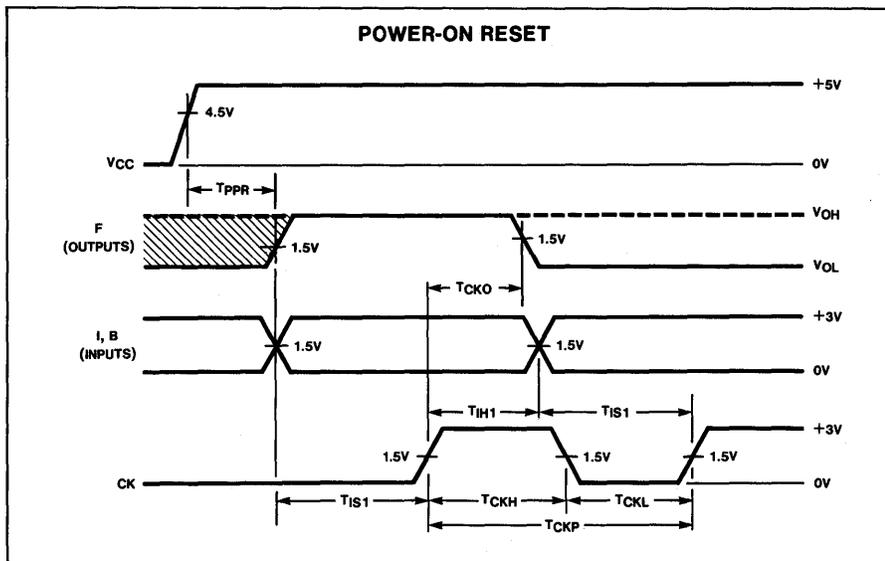
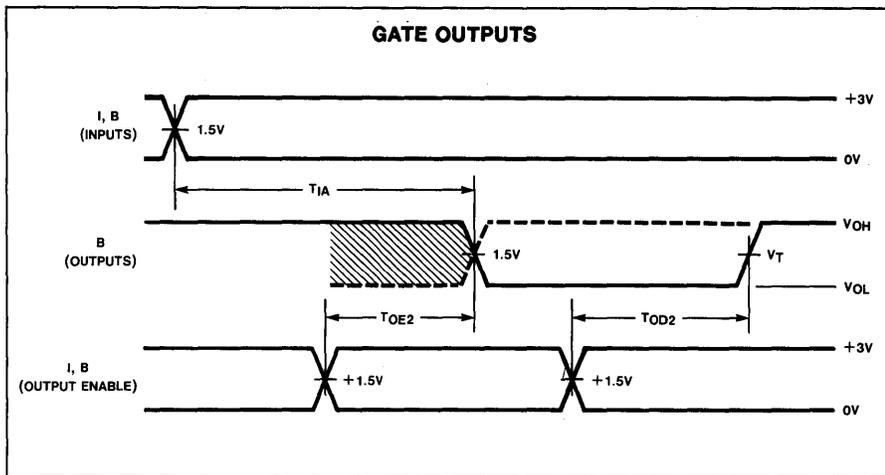
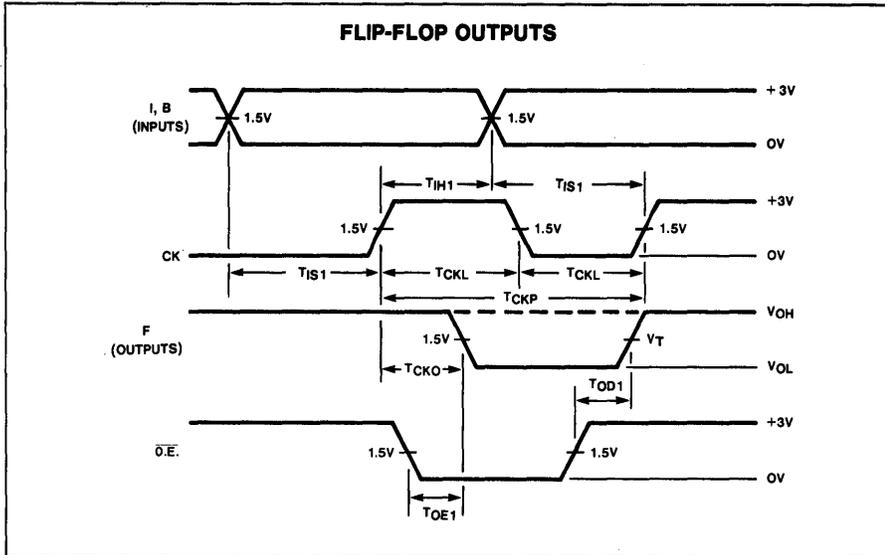
**FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)**

82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

**INTEGRATED FUSE LOGIC
SERIES 20**

TIMING DIAGRAMS



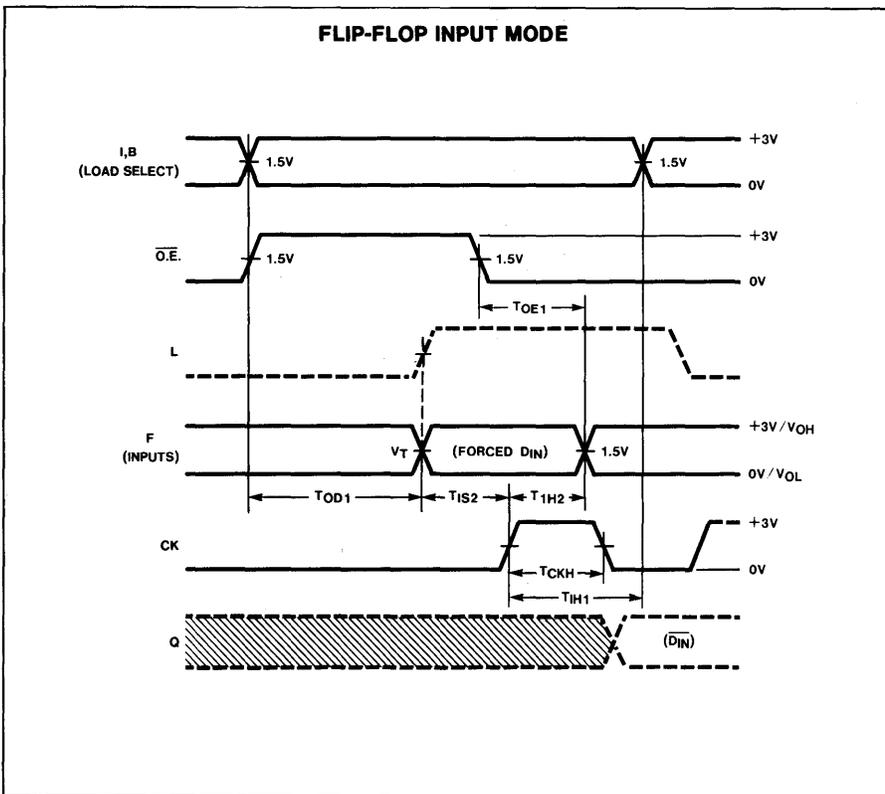
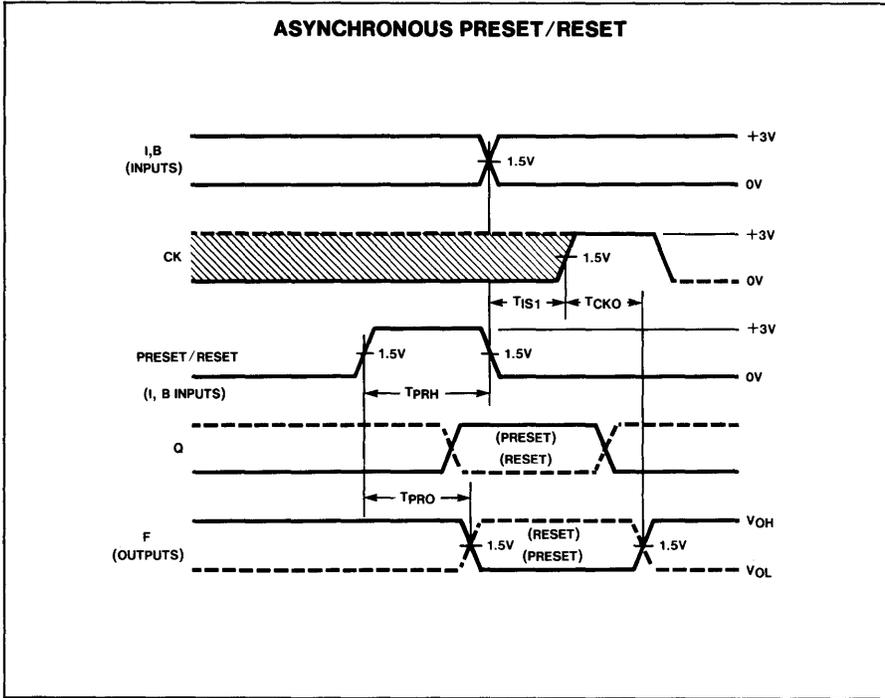
MEMORY TIMING DEFINITIONS

- TCKH** Width of input clock pulse.
- TCKL** Interval between clock pulses.
- TCKP** Clock period.
- TPRH** Width of preset input pulse.
- TIS1** Required delay between beginning of valid input and positive transition of clock.
- TIS2** Required delay between beginning of valid input forced at flip-flop output pins, and positive transition of clock.
- TIH1** Required delay between positive transition of clock and end of valid input data.
- TIH2** Required delay between positive transition of clock and end of valid input data forced at flip-flop output pins.
- TCKO** Delay between positive transition of clock and when Outputs become valid (with O.E. low).
- TOE1** Delay between beginning of Output Enable Low and when Outputs become valid.
- TOD1** Delay between beginning of Output Enable High and when Outputs are in the off state.
- TPD** Propagation delay between combinational inputs and outputs.
- TOE2** Delay between predefined Output Enable High, and when combinational Outputs become valid.
- TOD2** Delay between predefined Output Enable Low and when combinational Outputs are in the off state.
- TPRO** Delay between positive transition of predefined Preset/Reset input, and when flip-flop outputs become valid.
- TPPR** Delay between VCC (after power-on) and when flip-flop outputs become preset at "1" (internal Q outputs at "0").

Preview

INTEGRATED FUSE LOGIC
SERIES 20

TIMING DIAGRAMS (Cont'd)



**FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)**

82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

**INTEGRATED FUSE LOGIC
SERIES 20**

LOGIC PROGRAMMING

The FPLS can be programmed by means of Logic Programming equipment.

OR input connections necessary to implement the desired logic function are coded directly from the State Diagram using the Program Tables on the following pages.

In this Table, the logic state or action of all I/O, control, and state variables is assigned a symbol which results in the proper fusing pattern of corresponding links defined as follows:

With Logic programming, the AND/OR/EX-

"AND" ARRAY = (I), (B), (Qp)

<table border="1"> <tr><th>STATE</th><th>CODE</th></tr> <tr><td>INACTIVE 1,2</td><td>O</td></tr> </table>	STATE	CODE	INACTIVE 1,2	O	<table border="1"> <tr><th>STATE</th><th>CODE</th></tr> <tr><td>I, B, Q</td><td>H</td></tr> </table>	STATE	CODE	I, B, Q	H	<table border="1"> <tr><th>STATE</th><th>CODE</th></tr> <tr><td>i, B-bar, Q-bar</td><td>L</td></tr> </table>	STATE	CODE	i, B-bar, Q-bar	L	<table border="1"> <tr><th>STATE</th><th>CODE</th></tr> <tr><td>DON'T CARE</td><td>-</td></tr> </table>	STATE	CODE	DON'T CARE	-
STATE	CODE																		
INACTIVE 1,2	O																		
STATE	CODE																		
I, B, Q	H																		
STATE	CODE																		
i, B-bar, Q-bar	L																		
STATE	CODE																		
DON'T CARE	-																		

"COMPLEMENT" ARRAY = (C)

<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>INACTIVE 1,3</td><td>O</td></tr> </table>	ACTION	CODE	INACTIVE 1,3	O	<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>GENERATE</td><td>A</td></tr> </table>	ACTION	CODE	GENERATE	A	<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>PROPAGATE</td><td>•</td></tr> </table>	ACTION	CODE	PROPAGATE	•	<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>TRANSPARENT</td><td>-</td></tr> </table>	ACTION	CODE	TRANSPARENT	-
ACTION	CODE																		
INACTIVE 1,3	O																		
ACTION	CODE																		
GENERATE	A																		
ACTION	CODE																		
PROPAGATE	•																		
ACTION	CODE																		
TRANSPARENT	-																		

"OR" ARRAY = (F/F TYPE)

<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>J/K OR D CONTROLLED</td><td>A</td></tr> </table>	ACTION	CODE	J/K OR D CONTROLLED	A	<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>J-K</td><td>•</td></tr> </table>	ACTION	CODE	J-K	•
ACTION	CODE								
J/K OR D CONTROLLED	A								
ACTION	CODE								
J-K	•								

"OR" ARRAY = (D TYPE) F/F = (A) AND F = (L)

<p>K MUST BE DISABLED IN THIS MODE</p>									
<table border="1"> <tr><th>Tn STATUS</th><th>CODE</th></tr> <tr><td>ACTIVE (Set)</td><td>H</td></tr> </table>	Tn STATUS	CODE	ACTIVE (Set)	H	<table border="1"> <tr><th>Tn STATUS</th><th>CODE</th></tr> <tr><td>INACTIVE (Reset)</td><td>-</td></tr> </table>	Tn STATUS	CODE	INACTIVE (Reset)	-
Tn STATUS	CODE								
ACTIVE (Set)	H								
Tn STATUS	CODE								
INACTIVE (Reset)	-								

"OR" ARRAY = (J/K TYPE) F/F = (A) AND F = (H) OR F/F = (•) AND F = (H) OR (L)

<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>TOGGLE</td><td>O</td></tr> </table>	ACTION	CODE	TOGGLE	O	<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>SET</td><td>H</td></tr> </table>	ACTION	CODE	SET	H	<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>RESET</td><td>L</td></tr> </table>	ACTION	CODE	RESET	L	<table border="1"> <tr><th>ACTION</th><th>CODE</th></tr> <tr><td>HOLD</td><td>-</td></tr> </table>	ACTION	CODE	HOLD	-
ACTION	CODE																		
TOGGLE	O																		
ACTION	CODE																		
SET	H																		
ACTION	CODE																		
RESET	L																		
ACTION	CODE																		
HOLD	-																		

**FIELD PROGRAMMABLE LOGIC SEQUENCER
(16X32X12)**

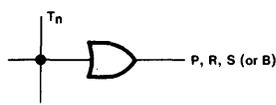
82S154/6/8 (O.C.)/82S155/7/9 (T.S.)

Preview

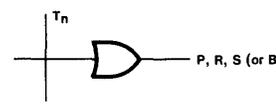
INTEGRATED FUSE LOGIC
SERIES 20

"OR" ARRAY - (S or B), (P), (R)

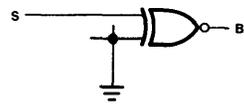
"EX-OR" ARRAY - (B)



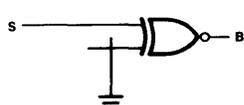
T _n STATUS	CODE
ACTIVE	A



T _n STATUS	CODE
INACTIVE	•

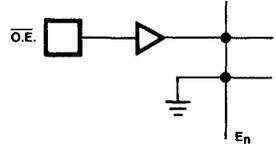


POLARITY	CODE
LOW	L

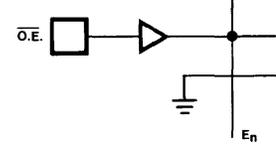


POLARITY	CODE
HIGH	H

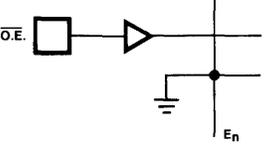
"O.E." ARRAY - (E)



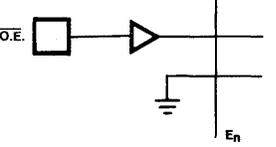
ACTION	CODE
IDLE ⁴	O



ACTION	CODE
CONTROL	A



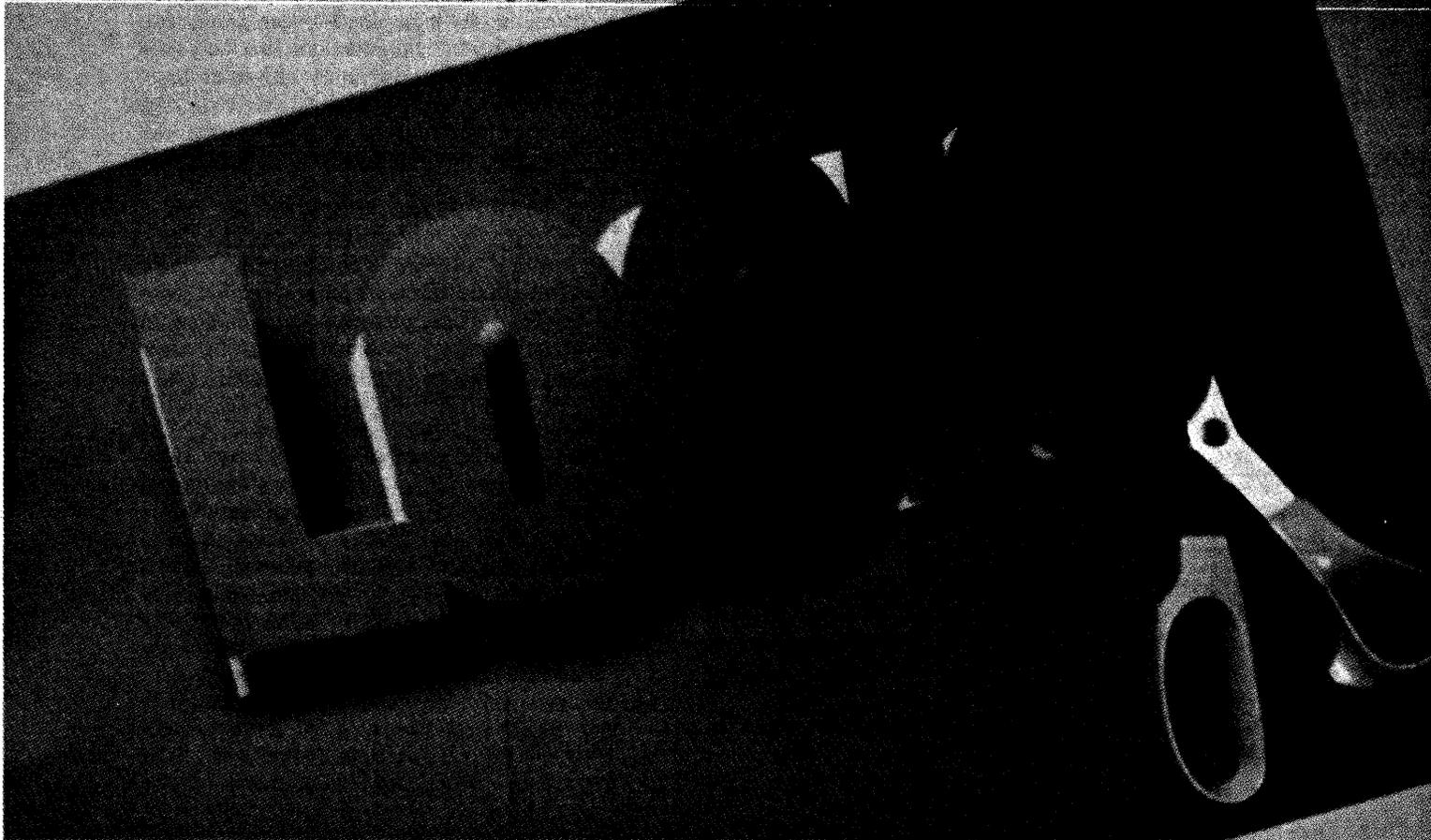
ACTION	CODE
ENABLE ⁴	•



ACTION	CODE
DISABLE	—

NOTES

1. This is the initial unprogrammed state of all link pairs. It is normally associated with all unused (inactive) AND gates T_n.
2. Any gate (T, L, P, R, D)_n will be unconditionally inhibited if any one of the I, B, or Q link pairs is left intact.
3. To prevent oscillations, this state is not allowed for C link pairs coupled to active gates T_n.
4. Although links in the O.E. array are isolated from each other, E_n = 0 and E_n = • are logically equivalent. But if register bank A is enabled with E_A = 0, then E_B can still be controlled (and vice versa).



Field-programmable arrays: powerful alternatives to random logic

Bridging design gap, TTL-compatible logic family
is described in Part 1 of a two-part article

by Napoleone Cavlan and Stephen J. Durham, *Signetics Corp., Sunnyvale, Calif.*

□ With the steady growth of integrated circuit technologies, hardly a day goes by without the news that yet another chip has made scores of discrete TTL packages obsolete. Yet, though large-scale integration is packing entire system architectures onto a few chips, it is still impossible to complete a design without some discrete logic to hold the framework together.

The increase of LSI has thus created the need for efficient ways to bridge the gaps between large functional islands. Because of complexity, performance, or uniqueness, these bridges have evolved into nontrivial random-logic configurations that still rely on clusters of small- and medium-scale integrated circuits, whose fixed functions never quite fit the problem. Now Signetics

Corp. has attempted to meet the need with a field-programmable logic family.

The family spans three ranges of complexity: at the low end are the field-programmable gate arrays (FPGAs); covering the middle range are the more complex logic arrays (FPLAs); and finally there are the logic sequencers (FPLSSs). These last, most complex elements have built-in registers and enable the designer to proceed from state diagram directly to hardware. The family, summed up in the table on p. 110, is compatible with TTL and operates from a +5-volt supply.

The devices provide a powerful and compact alternative to random logic, replacing discrete gates, wires, and connectors, with significant savings in board space,

FIELD PROGRAMMABLE LOGIC FAMILY									
Device	Organization	Device	Inputs	Outputs ⁽¹⁾	Chip enable (\overline{CE})	I_{CC} (max)	Delay (max)	Availability	Package ⁽²⁾
FPGA	• AND/NAND	82S102	16	9 OC	yes	170 mA	35 ns	now	N
		82S103		9 TS			50 ns	now	N, F
FPLA	• AND-OR/ NOR	82S100		8 TS	no		70 ns	4Q79	N
		82S101		8 OC					
FPLS	• AND-OR • Self-enable output	82S106		8 OC	yes ⁽³⁾		90 ns	4Q79	N, F
		82S107		8 TS					
FPLS	• AND-OR • Complement array • 6-bit state register • 8-bit output register	82S104	8 OC	yes ⁽³⁾	90 ns	4Q79	N, F		
		82S105	8 TS						

(1) OC = open collector TS = three-state
(2) N = plastic F = Cerdip
(3) \overline{CE} input may be optionally programmed as preset.

power, and cost. Moreover, since all devices can be programmed and modified in the field (as programmable read-only memories can) using readily available programming equipment, the logic can be changed to meet new customer requirements or specifications, or to recover quickly from design errors—after delivery to the field—without expensive printed-circuit-board retooling.

Programming options

Depending on their complexity, members of the programmable logic family have internal AND gates, OR gates, S-R flip-flops, true or complement buffers, and exclusive-OR (EXOR) gates. Those elements can be combined to perform single-level, double-level, and sequential logic functions—all by blowing fuse links.

There are other fuse options in output structures for the entire logic family, too, since either active-high or active-low functions can be generated without additional hardware or signal delay. Finally, the family is well suited to bus-organized environments such as microprocessor systems, since all its members offer, in addition to open-collector outputs, three-state outputs whose signals are in the high-impedance state until activated by a chip-enable input.

All the logic elements perform standard logic functions that can be represented by augmenting conventional logic symbols with a few new definitions so that they can represent multiple-input gates (see "How the FPLF defines logic," p. 111).

The gate arrays

The simplest member in the family is the field-programmable gate array, which performs single-level logic functions. The equivalent logic diagram for the FPGA is shown in Fig. 1. The two gate arrays currently available are open-collector (82S102) and three-state output (82S103) versions of the same array, which comprise nine NAND gates fuse-selectively connected to 16 common inputs by true/complement buffers.

Fuses in the FPGAs allow individual outputs to be complemented to AND, so that by proper manipulation of the input polarities, and by using De Morgan's theorem, AND, OR, NAND, and NOR logic functions can be easily implemented. The parts thus serve as universal logic elements that can be tailored to applications requiring random logic, as in fault monitors, code detectors, and address decoders for microcomputer systems with memory-mapped I/O.

The logic arrays

Devices performing two-level combinational logic functions are grouped into the field-programmable logic array (FPLA) category. These elements are a step up in complexity from gate arrays, capable of generating AND-OR, AND-NOR, and their De Morgan equivalents. There are at present two array types in the FPLA family, each with either open-collector or three-state outputs.

The equivalent logic diagram of the first array type, the open-collector output 82S101 (or three-state output 82S100), is shown in Fig. 2. The first level of logic in the device is made up of 48 AND gates fuse-connectable to any of 16 common inputs by true/complement buffers. The second logic level consists of eight OR gates—one per device output—each capable of being selectively coupled to any of the 48 gates. Finally, fusing options are included for generating true or complementary outputs.

The second logic array type, the 82S106/107, has nearly the same organization as the first. The exception is that an additional OR gate with fixed inputs has been added to generate an internal enable command for the output structure. That self-enable is generated whenever any of the AND gates become logically true, which occurs when the external input code matches the internal AND-gate program. In the absence of such a match, all device outputs are unconditionally disabled. The self-enable signal is available externally—the chip-enable input (\overline{CE}) pin on the 82S100/101 becomes an open-collector output called \overline{FLAG} . Because of this feature, the 82S106/107 can be viewed as a content-addressable programmable read-only memory, ideally suited to modifying data in large ROMs, as will be shown in the second part of this article.

Shared gates

Both array types benefit from the second level of logic. The advantage here is that the AND gates can be shared—OR gates can couple with up to 48 AND gates. Also, a key advantage of this arrangement over single-level logic is that it allows editing—disconnecting invalid AND terms from the OR array and replacing them with spare AND gates (Fig. 3).

Open-collector versions of both gate-array and logic-array devices can form wired-AND outputs in order to expand the number of AND gates available on a single chip. This solves the problem that is posed by applications exceeding the resources of a single device. The only restriction is that the expanded outputs have to be programmed to be active-low.

By far the most powerful members of the family are the field-programmable logic sequencers (FPLS), which add on-chip registers to arrays of AND and OR gates. The

How the FPLF defines logic

For the most part, schematic representation of logic in the field-programmable logic family follows conventional notation—the devices include AND, OR, and exclusive-OR (EXOR) gates, as well as set-reset (S-R) flip-flops and true or complement buffers. To simplify the representation of fuse-link programmability, however, the FPLF schematics use a matrix arrangement with cross-point coupling to represent intact fuse links.

For example, (a) in the figure shows a typical input and AND gate of a gate array. The square "solder dot" represents a fixed internal connection. Both the line from input A and the line from the output of the inverter intersect the vertical input line of the AND gate; in actuality, fuse links make both connections. An intact fuse link is represented by a round solder dot. Blowing either of the fuse links will determine whether the input to the AND gate is A, or its complement, \bar{A} . (Leaving both fuses intact holds the output of the AND low, whereas blowing both fuses results in a "don't care" situation, an output that is independent of either input.)

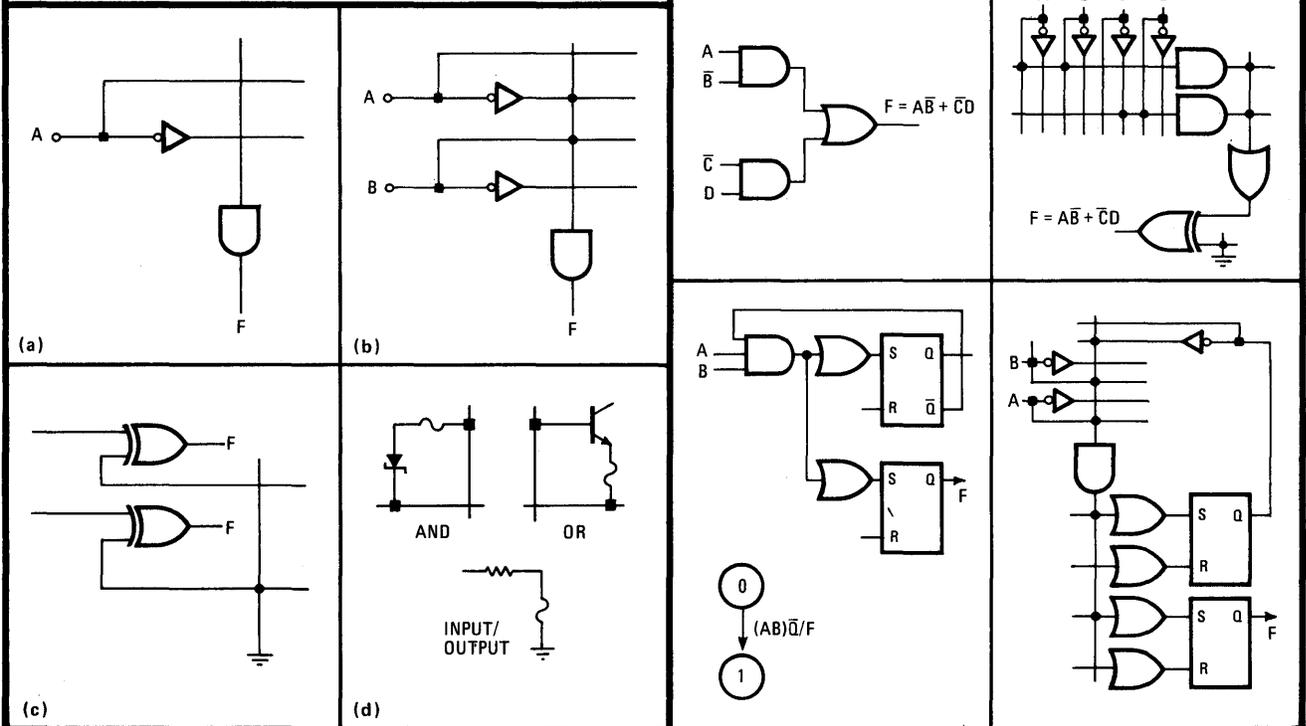
Extending the matrix and cross-point coupling approach a step further, (b) shows the configuration of a two-input AND gate. Since the input to the AND gate crosses the four lines of inputs A and B as well as their complements, the gate serves as a four-input AND while appearing to be a single-input gate. Since the members of the field-programmable logic family have 16 inputs intersecting each AND gate, the gates are actually 32-input devices; the number of inputs used is determined finally by the number of fuses left intact. Thus, in (b), solder dots (or

intact fuse links) create the logical equation $F = \bar{A}B$.

The exclusive-OR gates on all outputs of the logic-family devices allow programming for either active-high or active-low output signals. As shown in (c), a fuse link grounding one of the two inputs of an EXOR gate results in an active-high output; blowing the fuse results in an output that is active-low.

The details of the fusing mechanisms are shown in (d). AND gates have a fuse in series with a Schottky diode, while OR gate fusing uses an npn transistor. The fuses for the true/complement input buffers and active-high/active-low outputs are in series with resistors.

The analogy between fixed and programmed logic is best shown by the examples in the table. The first example is typical of the single-level logic to which the gate array is applicable. The two-level logic of the second example is satisfied by the logic arrays. Finally, the registered state machine that executes the state transition of the third example is a candidate for the field-programmable logic sequencers.

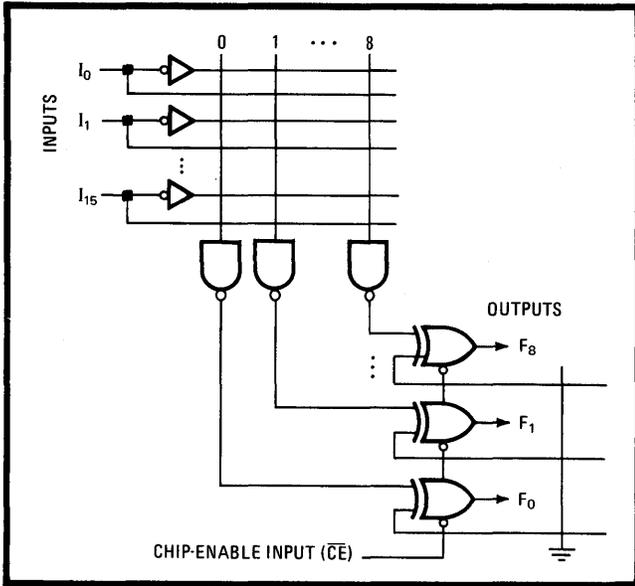


sequencers are actually self-contained state machines, since they can be programmed to perform any synchronously clocked logic sequence.

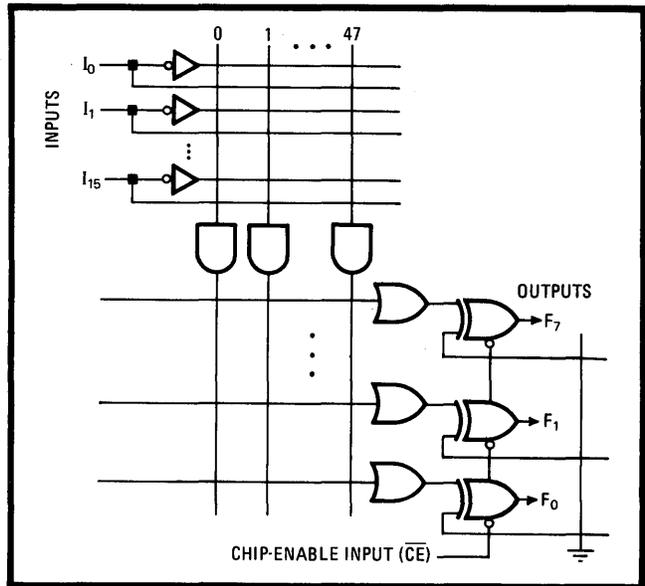
State machines, whose general structure is shown in Fig. 4a, usually take two forms: Moore machines, in

which the output is a function of the present state only; and Mealy machines, whose output is a function of both the present state and the present input.

Figure 4b shows the basic architecture of the open-collector output 82S104 (or three-state output 82S105),



1. Gate array. The simplest device in Signetics' field-programmable logic is the gate array, capable of single-level logic. Any of 16 inputs can connect to nine NAND gates by true/complement buffers. Since outputs can be complemented to AND, manipulating De Morgan's theorem makes the device a universal logic element.

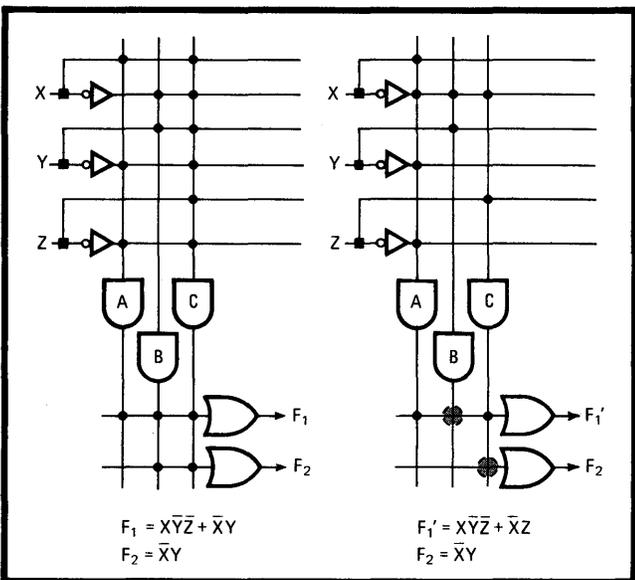


2. Double deep. The field-programmable logic array carries out two-level combinational logic. The 16 inputs couple to 48 AND gates, which in turn connect to any of nine OR gates. Either true or complement outputs are provided.

the first members of the FPLS family. With the FPLS, a user may program any logic sequence that can be expressed as a series of jumps between stable states triggered by a valid input condition I at clock time t . The number of states in the sequence depends on the length and complexity of the desired algorithm.

A typical state diagram is shown in Fig. 5. The state from which a jump originates is called the present state P , and that at which it terminates is the next state N . A jump always causes a change in state, but may or may not cause a change in the machine's output F .

All states are arbitrarily assigned and stored in the state register, where the clock and next-state information from the combinational logic are the inputs. State jumps can occur only when transition terms are true. A transition term is, by definition, the logical AND function of the clock, present state, and valid inputs; hence, $T_n = t \cdot I \cdot P$. However, since the clock is actually applied to the state register, it may be removed from the equation. When T_n is true, a control signal is generated that, at clock time t , forces the contents of the state register from P to N and, if necessary, changes the contents of the output register.



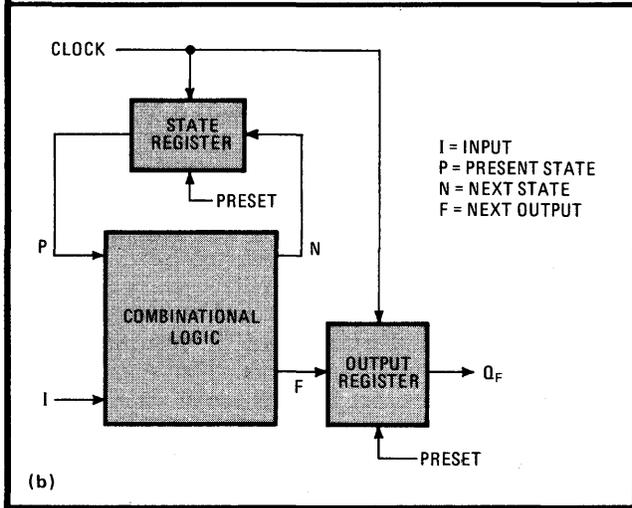
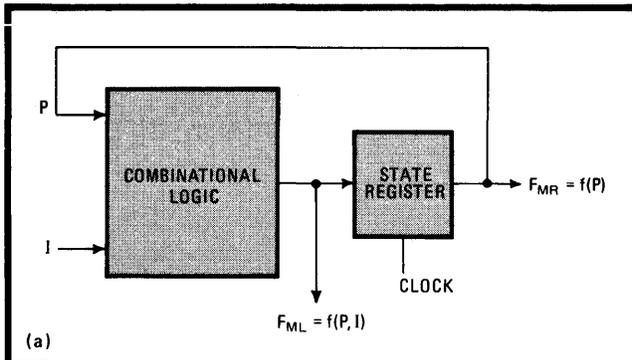
3. Editing. The logic array's programmable OR gates allow sharing of AND gates, as with gate B at left. The OR array also allows easy editing of logic statements when design changes are made; note how spare gate C at right was used to modify output F_1 to F_1' .

FPLS organization

The architecture of the 82S104/105 is a natural extension of the static logic structure of the FPLA. It accepts 16 input variables and provides eight output functions. It has a 6-bit state register and an 8-bit output register; all the internal registers are automatically preset to logic 1 when power is applied. The FPLS provides for 48 transition terms, which can be selected to be either true or complementary.

A look at the equivalent logic diagram of the FPLS (Fig. 6) shows its extension of the static FPLA. The AND and OR gate arrays of the latter have been expanded to control the set and reset (S and R) inputs of six flip-flops (the state register) and to monitor the register's contents over an internal feedback path. Also, an independent 8-bit output register has been added to store output commands generated during state transitions and to hold the output constant during state sequences involving no output changes.

The AND array comprises 48 positive AND gates, each with 44 input connections from a set of true/complement buffers. The AND gates are used to form logic products of 16 external inputs (I_0 to I_{15}) with six present-state (P) inputs fed back from the state register. The gates are



4. State machine. A state machine (a) takes either a Mealy or Moore form. The architecture of the field-programmable logic sequencer (b) is that of a self-contained Mealy machine, where the output is a function of both the present state and the present input.

therefore called transition terms because, like the transition terms in state diagrams, they issue next-state commands.

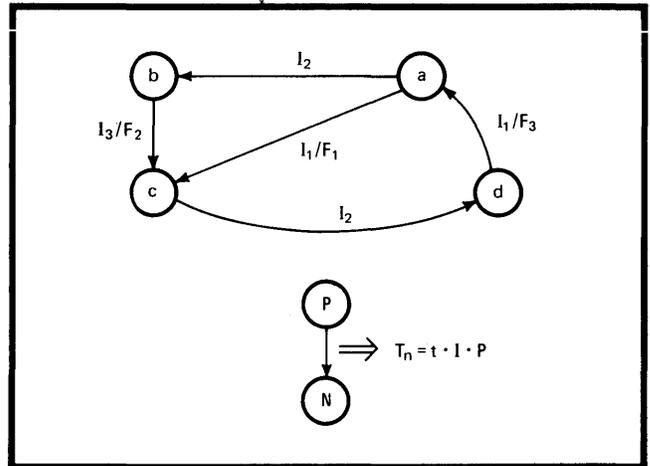
The OR array contains 28 positive OR gates, each with 48 input connections to all 48 AND gates. The outputs of the ORs drive the set and reset inputs of the 14 S-R flip-flops that are state and output registers.

The FPLS is made still more flexible by a complement array comprising a single 48-input OR gate that drives an inverter, which then feeds back into the AND array. The complement array forms a bridge between the AND and OR arrays for generating NAND functions of input-jump conditions; the user programs it in such a way as to suit each transition term.

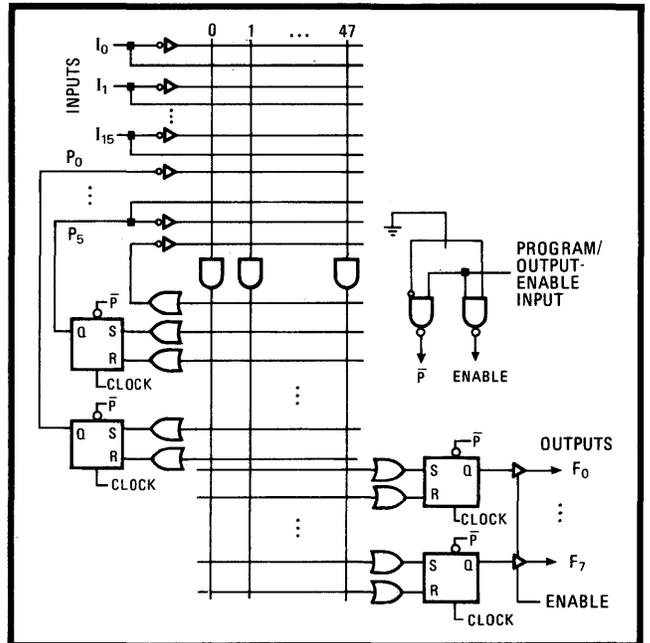
De Morgan's theorem

De Morgan's theorem to reduce logic terms can be easily implemented with the complementary array so that the most use is made of the AND gates. For example, if the transition term is $T = (Q)(\bar{X} + \bar{Y} + \bar{Z})$, where Q is the output of the state register and \bar{X} , \bar{Y} , and \bar{Z} are inputs, three AND gates in the FPLS are required. However, De Morgan's theorem changes the transition term to $T = (Q) \bar{X} \bar{Y} \bar{Z}$, which requires only two AND gates.

The complementary array is also an efficient means of aborting a clocked sequence in the absence of valid jump conditions. As Fig. 7 shows, considerable minimization



5. State diagram. Example of a state diagram (a) with four states—A, B, C, and D. I_1 – I_3 are jump conditions, which trigger output changes F_1 – F_3 . A state change (b) gives rise to transition term T_n , which is logical AND of clock t , input I , and present state P .

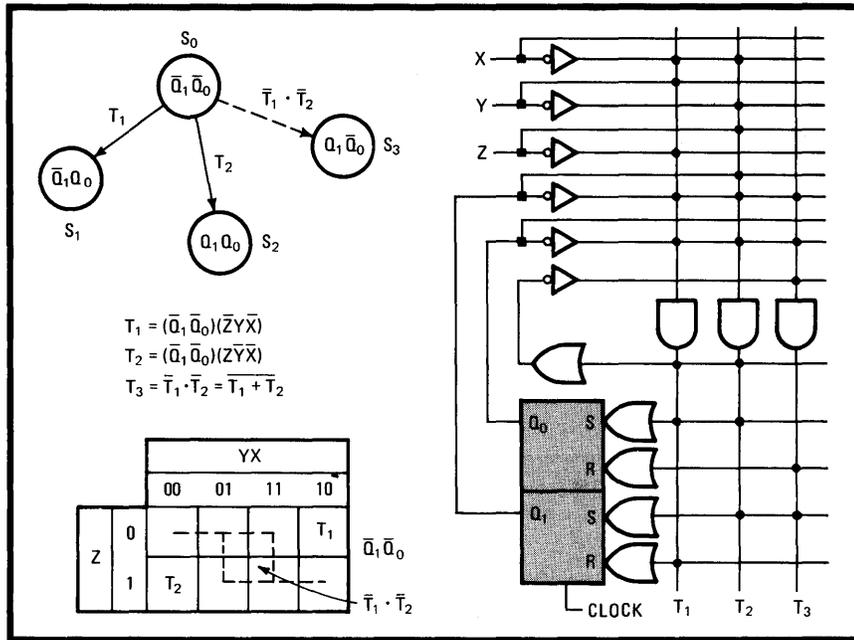


6. Sequencer. The field-programmable logic sequencer has 16 outputs, 48 AND gates, and 28 OR gates, plus 14 flip-flops that serve as state and output registers. Either an asynchronous preset input or an output-enable input is available as a programming option.

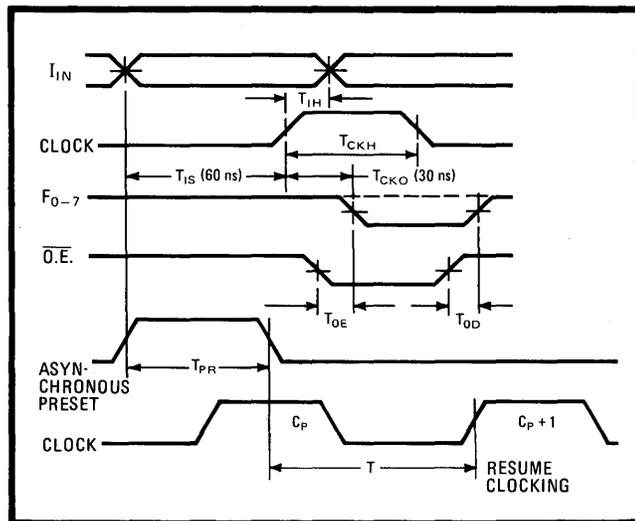
of AND gates is possible when the detection of valid jumps involves many complements of jump functions, especially as the number of variables increases.

All clocked S-R flip-flops that make up the state and output registers offer the option of asynchronous pre-setting to all 1s. The 64-state total that can be represented by the state register is adequate in most cases to chart algorithms involving fewer than 48 nonredundant transitions. The register accepts next-state commands (N) from the OR array and supplies present-state information (P) to the AND array.

The output register is similar to the state register, except it has eight states for servicing eight output functions. It accepts the next-output commands F_0 – F_7



7. Complementary. Use of AND gates in the FPLS is greatly reduced by the complement array, a single 48-input OR gate driving an inverter that feeds back into the AND array. In this example, the default jump from state S_0 to S_3 is reduced from three AND gates to a single gate T_3 .



8. Timing. Minimum clock duration for the FPLS is 20 nanoseconds. Minimum width of preset input, which overrides clock, is 40 ns. Normal clocking resumes with the first full clock pulse following a negative clock transition after the trailing edge of the present signal.

from the OR array and then reflects its contents to the device outputs through the buffered Q outputs of each of the flip-flops. Also, as an added feature to enhance fault isolation, driving input I_0 to +10 volts will route the contents of the state register (P_0 - P_5) directly to outputs F_0 - F_5 without any alteration of the contents of the output register. However, the feature is not recommended for use in a normal mode of operation (as in a Moore machine). This is because it increases the device's maximum current by 5 to 10 milliamperes and thereby lowers the maximum ambient temperature rating of the package by approximately 5°C.

As a final programming option in the 82S104/105, a pin can function as either an active-high asynchronous preset (pr) or an active-low output enable (\overline{OE}). The output-enable function forces all outputs to logic 1 (or to

high impedance in the 82S105) and is normally used when the device is sharing a bus. It does not inhibit clocking of the internal registers. The asynchronous preset option, on the other hand, is useful when the logic sequence requires an immediate state-independent return to initial conditions. The state register and output register can also be synchronously preset independently of one another by dedicating that function to one of the input variables in conjunction with a single transition term and a clock pulse.

Timing constraints

The maximum clock rate of the 82S104/105 can be inferred from its timing diagram (Fig. 8), which shows worst-case delays and setup requirements during a typical I/O cycle. Using stable external inputs as a reference, the device can be clocked after a minimum setup time of 60 nanoseconds. The next output (as well as the next internal state) will be valid 30 ns after the positive edge of the clock, giving a total I/O delay of 90 ns. Since both output enable and disable delays are also 30 ns, when the \overline{OE} pin is used its signal's edge should occur prior to or coincidentally with the clock in order to avoid increasing I/O delays.

The asynchronous preset option includes a clock lockout feature that eliminates the potential hazard of spurious clocking. But, as the timing diagram shows, when using the lockout feature it is possible to miss one clock pulse, which may be prohibitive in some applications.

Applications

The second part of this article, to appear in the next issue of *Electronics*, will provide examples of applications for the gate- and logic-array devices. It will also describe in detail the development of a full-blown cartridge-tape drive controller built with a single logic-sequencer chip. The design example proceeds from flow chart to state-sequence diagram to hardware.

Sequencers and arrays transform truth tables into working systems

by Napoleone Cavlan and Stephen J. Durham

Signetics Corp., Sunnyvale, Calif.

□ Because of its power and flexibility, the Signetics field-programmable logic family is ideal for replacing the discrete logic normally used to interface large-scale integrated devices, as shown in Part 1 [July 5, 1979, p. 109]. The examples of applications that follow show how to exploit its special features.

In designing with these gate and logic arrays and logic sequencers, the user need concern himself only with generating truth tables associated with the state diagrams or sets of Boolean logic equations that define his function. The one restriction is that he must use logic symbols corresponding to the status of fuse links.

As indicated in Fig. 1, an extra set of symbols is needed to describe all the states of FPLF gates corresponding to all combinations of blown and unblown fuse links. Once ordered into truth tables, the user-defined functions are then directly mapped onto standard program tables furnished with FPLF elements, whose fuses are then blown by a logic-type programmer. As the user gains experience, he can manipulate logic variables intuitively and can eventually implement algorithms directly on the program tables with only the device schematics for reference. (The formal step of deriving state diagrams and logic equations will not be considered here.)

Because of their simple and uncommitted structure, FPLF elements are suited to a wide variety of applications, several of them already well documented. The following examples illustrate the typical use of each logic element and match devices with applications.

Bus translator

Signetics' Instructor 50 microcomputer system is built around the 2650 microprocessor; but for compatibility with other systems and peripheral devices in the hobbyist market, it interfaces to the S100 bus, which is based mainly on 8080 microprocessor signals. Yet to carry out the seemingly unwieldy task of bus translation, only a single FPGA is needed. The gate array translates the logical combinations of timing, enable, and control signals supplied by the 2650 and its I/O hardware into control signals entirely compatible with the S100 bus definitions, as shown in Fig. 2.

The programmable feature of the FPGA is strategically

invaluable in this case since the S100 bus is not yet totally standardized. The FPGA permits easy adaptation of the interface to changes in specifications, which are subject to arbitrary manipulation by manufacturers in the hobby arena.

Two-level logic

The logic arrays add a second level of combinational logic to the gate arrays, and thus another level of versatility. AND/OR combinations of the FPLAs are well suited to carrying out polynomial equations and the like, as shown in the next example.

In systems that transfer large blocks of data, a cyclic redundancy check (CRC) scheme can significantly improve data integrity. The technique appends a check word to a transmitted sequence of data, and the receiving end uses that word to check for errors. A cyclical division of the transmitted data by an industry-standard polynomial generates the CRC word; the remainder from the division forms the check word.

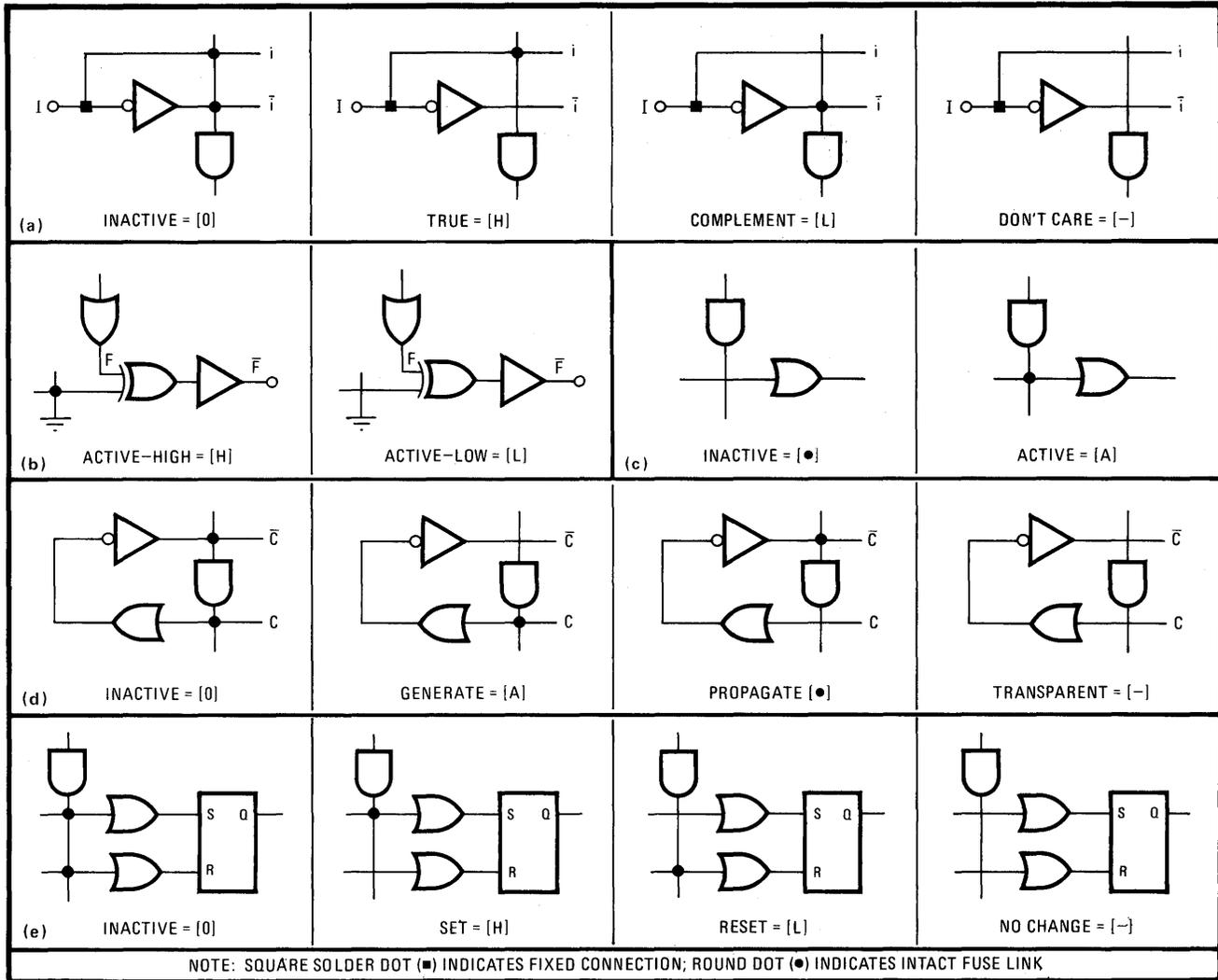
Polynomials lend themselves to serial manipulation, and serial CRC generation and checking are easy to implement. But in a multiple-line data system with parallel organization, a considerable amount of hardware may be needed for parallel-to-serial conversion. Moreover, the multiple-bit clocking for each word carries an inherent speed loss—a factor of 8 for a byte-oriented system. A parallel CRC generator-checker circuit is the answer, developed from the set of logic equations describing the function of the circuit in the form of a state machine.

The general design of the CRC circuit is shown in Fig. 3a, along with the logic equation set for the popular CRC polynomial $P(x) = x^{16} + x^{15} + x + 1$. Figure 3b shows that the entire byte-wide parallel CRC generator-checker circuit can be implemented with only five chips: two 8-bit latches, two FPLAs, and an FPGA. The FPLAs contain the set of logic equations controlling the flip-flop inputs, which are expanded from EXOR form to sum-of-products form. In Fig. 3a, variables N_0-N_{15} represent the next CRC word after clocking, based on the current word B_0-B_{15} and the present input byte D_0-D_7 .

CRC generation begins by driving the RESET line low to initialize the latches to zero. Pulsing the clock line then transfers the first byte of the data block in at D_0-D_7 . Subsequent bytes are clocked in the same way. The cyclic nature of this design places no limit on the size of the data block that can be processed. During data transmission, the 16-bit CRC word is available at outputs B_0-B_{15} after the last data byte has been clocked in; it is appended as two check bytes to the data in the block.

Checking

The circuit is used in the check mode when receiving data containing CRC characters. The last 2 bytes in the data block received are CRC send characters. They too are clocked in and contribute to form a final receive pair of CRC characters, which, for error-free transmission, must both be zero. If an error has occurred, B_0-B_{15} will be nonzero. The FPGA will detect the nonzero condition and generate an error signal. This parallel CRC format can operate on data blocks at speeds in excess of 5.7



1. New notation. The many combinations of blown and unblown fuse links in the field-programmable logic family require new notation. The four possibilities for AND gates are shown in (a), while those for exclusive-OR outputs are in (b). The combinations for OR gates are in (c). The complement array in the logic sequencers is detailed in (d). Finally, OR gates controlling the flip-flops in sequencers are in (e).

megabytes per second.

An interesting use for the FPLA is in changing data at a few locations of a read-only memory (see "How to patch a read-only memory," p. 137).

The abilities of the field-programmable logic sequencer are well demonstrated by its use as a controller for a cartridge-tape transport. In this example, one chip replaces many—a distinct advantage if the controller is to be packed on a single-board microcomputer. Although the chip's function is complex, it can be programmed methodically and worked directly from a flow chart.

Controller routines

The controller executes fixed routines in response to status and input commands that may originate from an input/output bus or a monitoring station. Its outputs operate the velocity servo that drives the cartridge, form I/O status signals, and enable writing of data. The input and output signals of the one-chip controller are shown in detail in Fig. 4.

The controller carries out these eight routines:

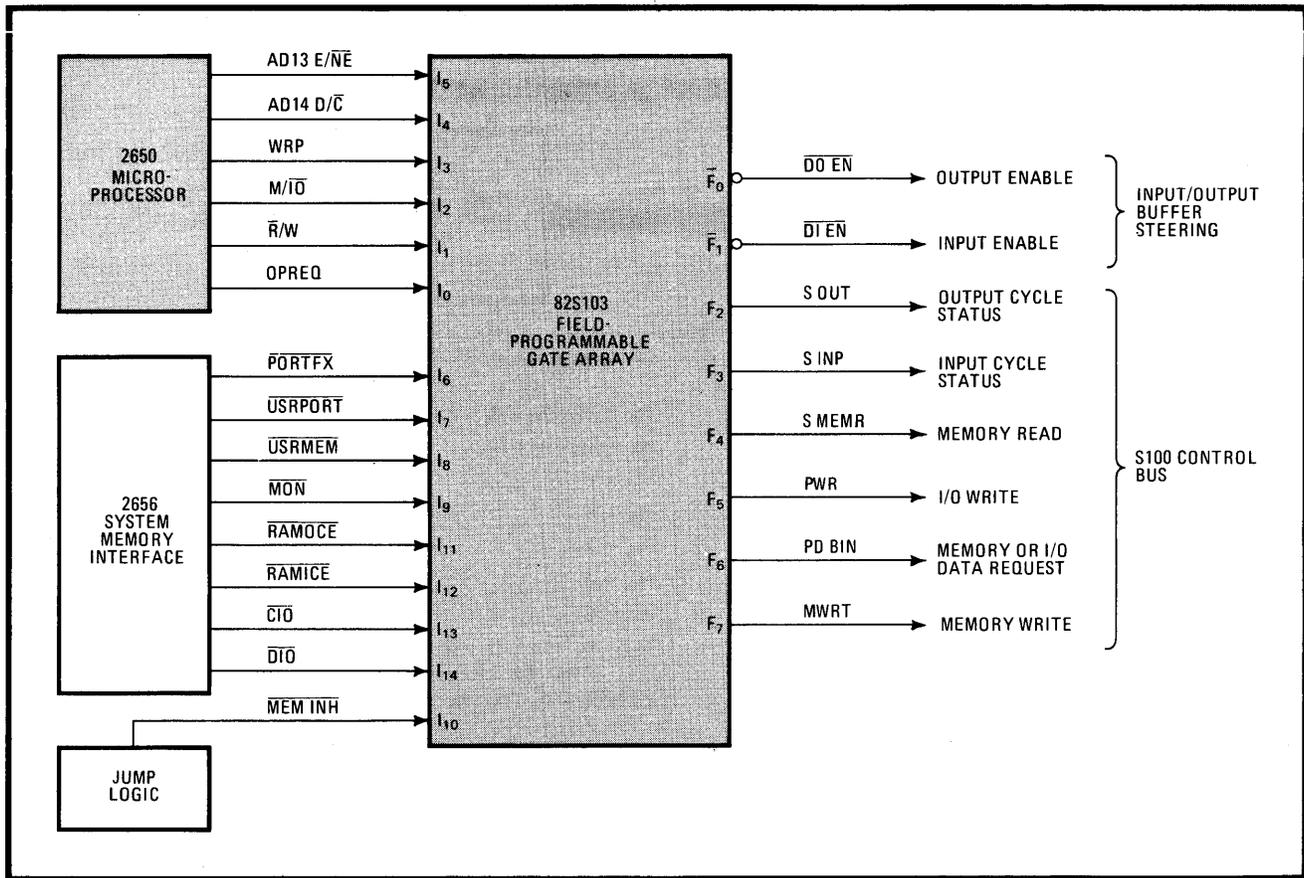
- Move tape fast-forward.

- Move tape slow-forward.
- Move tape fast-reverse.
- Move tape slow-reverse.
- Bring tape to load point when cartridge is inserted.
- Rewind tape to load point.
- Rewind tape to beginning and eject cartridge in response to unload command.
- Rewind tape to beginning and eject cartridge in response to auto-unload true condition.

The routines could be represented concisely in a conventional Mealy state diagram, but that often obscures the actual machine function. Flow charts are more easily understood, where input variables, machine states, and output functions are given variable names. Such a chart is shown in Fig. 5.

Diagramming the flow

What would be transition terms in a Mealy state machine become true/false statements regarding the system inputs (taken one at a time) in the chart. The correlation is most obvious in the simple example in Fig. 6. The flow chart in (a) shows a conditional change from



2. Translator. Getting S100 bus signals, which are mostly 8080 microprocessor signals, out of a 2650 microprocessor calls for a field-programmable gate array. One 82S103 translates signals from the 2650 and its companion 2656 interfacing chip to the hobby bus.

state A to state B. The conditions in the flow chart's diamonds must be simultaneously satisfied for the state change to occur. The conditions take on variable names, and for this example, which arbitrarily assumes a 4-bit state register, three inputs, and two outputs, the corresponding state diagram is shown in Fig. 6b.

The transition from A to B denotes a jump from 10 (1010_2) to 13 (1101_2) and an output transition to 2 (10_2) at the next clock pulse if the combination $X_n = 4$ (100_2) is true. The transition is synthesized by forming a transition term $T = P_3\bar{P}_2P_1\bar{P}_0I_2\bar{I}_1\bar{I}_0$ and using term T at the next clock pulse to generate next-state and next-output commands for the state and output registers, respectively. For the state register, flip-flops N_0 and N_2 are set by connecting T to set lines S_0 and S_2 , and flip-flop N_1 is reset by coupling T to the R_1 reset line. Similarly, for the output register bit F_0 is reset and bit F_1 is set by connecting T to corresponding flip-flop reset (R_0) and set (S_1) lines.

Controller conditions

Referring again to the controller flow chart, it can be seen that whenever the tape-drive power is turned on, or when an interlock is opened, the transport must be stopped. That is achieved by an input signal to the controller called \overline{INTRDY} that resets the state register with an unconditional jump to state 1 or STOP. When that occurs, all outputs on the FPLS chip become inactive, WRITE is inhibited, and speed and direction are

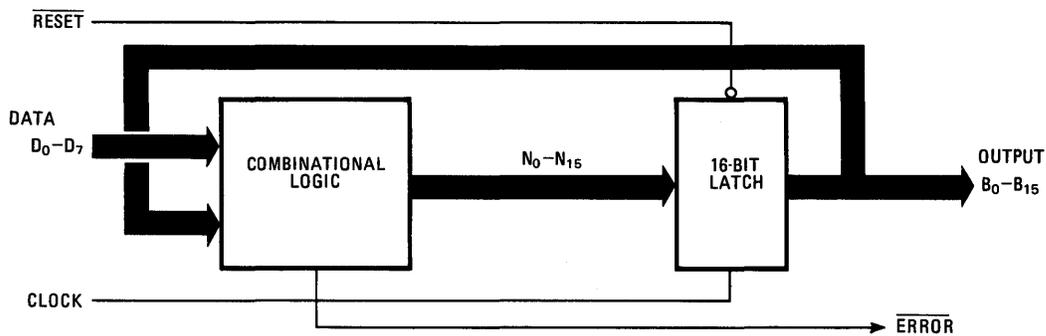
arbitrarily set to SLOW and REVERSE. From the STOP state, operation into any mode occurs by state and output jumps when all of the intervening conditions are simultaneously satisfied.

As an example, writing at normal speed will occur with a jump from state 1 to state 3, which requires that the following criteria be satisfied:

- The data cartridge is in place; therefore CIP is true.
- The drive has been addressed; SEL is true.
- The tape has been commanded to run; TR is true.
- The controller is not in state 6; state 6 is false.
- The tape should move slowly; therefore \overline{FAST} is true (an active-low signal).
- The tape should move forward; \overline{FWD} is true.

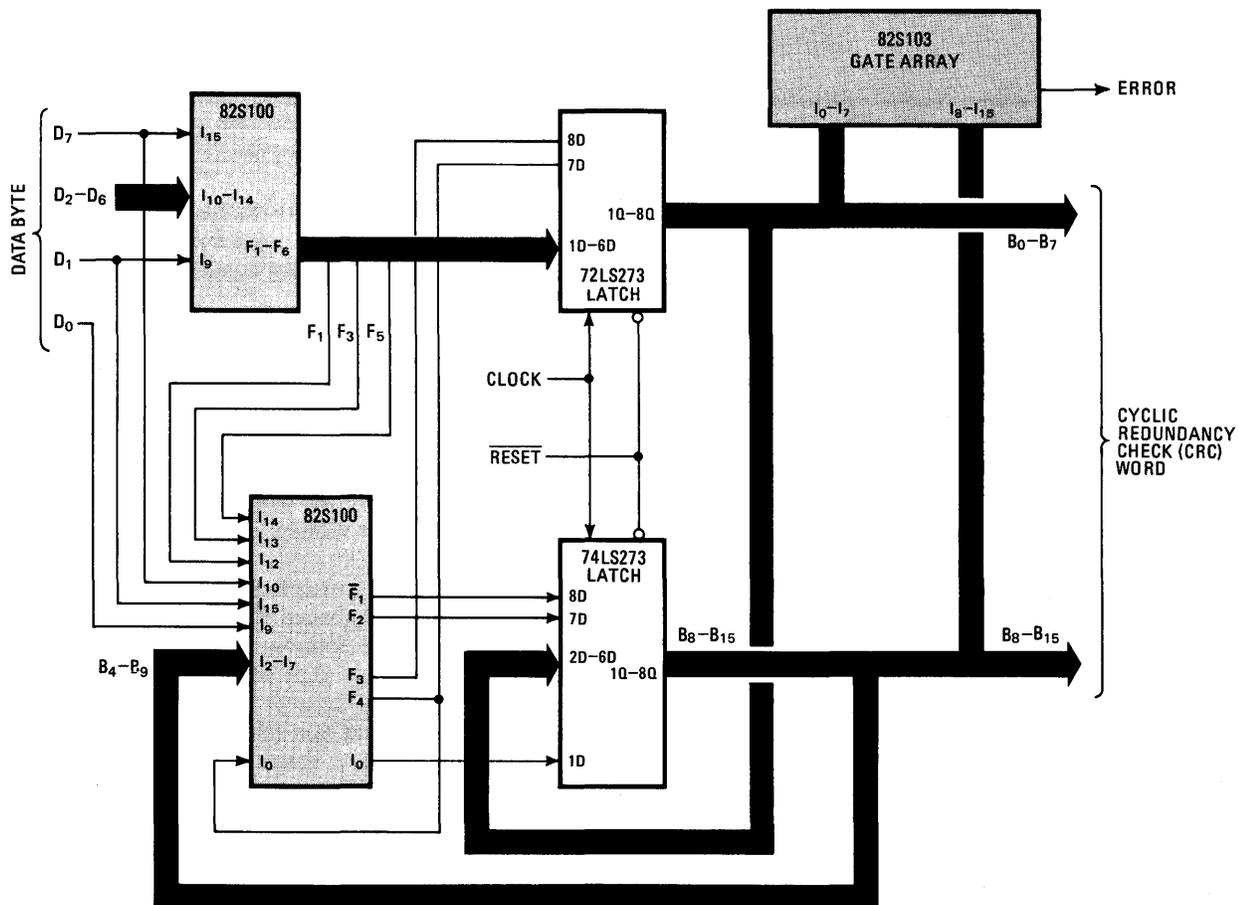
In tracing the jump between these states two things must be noted. First, the commands RWD, UNL, and TR are mutually exclusive, so that when either is true the others can be considered false or "don't care." Second, after $TR = \text{true}$, the condition (State = 6?) is inserted to indicate invalid jumps to states 2 and 3, which could originate from state 6 with an AUTO UNL false. Clearly, these should be avoided to inhibit honoring requests for read slow (or fast) forward while stopped at the end of the tape. So, the (State = 6?) condition is a reminder to avoid programming $6 \rightarrow 2$ and $6 \rightarrow 3$ state jumps in the FPLS. A similar argument holds for (State = 7?) and (State = 11?) conditions.

After data has been either written or read, the tape drive is commanded to stop by $TR = \text{false}$, which causes a



$$\begin{aligned}
 N_0 &= D_0 \oplus D_1 \oplus D_2 \oplus D_3 \oplus D_4 \oplus D_5 \oplus D_6 \oplus D_7 \oplus B_8 \oplus B_9 \\
 &\quad \oplus B_{10} \oplus B_{11} \oplus B_{12} \oplus B_{13} \oplus B_{14} \oplus B_{15} \\
 N_1 &= D_0 \oplus D_1 \oplus D_2 \oplus D_3 \oplus D_4 \oplus D_5 \oplus D_6 \oplus B_9 \oplus B_{10} \oplus B_{11} \\
 &\quad \oplus B_{12} \oplus B_{13} \oplus B_{14} \oplus B_{15} \\
 N_2 &= D_6 \oplus D_7 \oplus B_8 \oplus B_9 \\
 N_3 &= D_5 \oplus D_6 \oplus B_9 \oplus B_{10} \\
 N_4 &= D_4 \oplus D_5 \oplus B_{10} \oplus B_{11} \\
 N_5 &= D_3 \oplus D_4 \oplus B_{11} \oplus B_{12} \\
 N_6 &= D_2 \oplus D_3 \oplus B_{12} \oplus B_{13} \\
 N_7 &= D_1 \oplus D_2 \oplus B_{13} \oplus B_{14} \\
 N_8 &= D_0 \oplus D_1 \oplus B_0 \oplus B_{14} \oplus B_{15} \\
 N_9 &= D_0 \oplus B_1 \oplus B_{15} \\
 N_{10} &= B_2 \\
 N_{11} &= B_3 \\
 N_{12} &= B_4 \\
 N_{13} &= B_5 \\
 N_{14} &= B_6 \\
 N_{15} &= D_0 \oplus D_1 \oplus D_2 \oplus D_3 \oplus D_4 \oplus D_5 \oplus D_6 \oplus D_7 \oplus B_7 \oplus B_8 \\
 &\quad \oplus B_9 \oplus B_{10} \oplus B_{11} \oplus B_{12} \oplus B_{13} \oplus B_{14} \oplus B_{15} \\
 \text{ERROR} &= \bar{B}_0 \cdot \bar{B}_1 \cdot \bar{B}_2 \cdot \bar{B}_3 \dots \bar{B}_{15}
 \end{aligned}$$

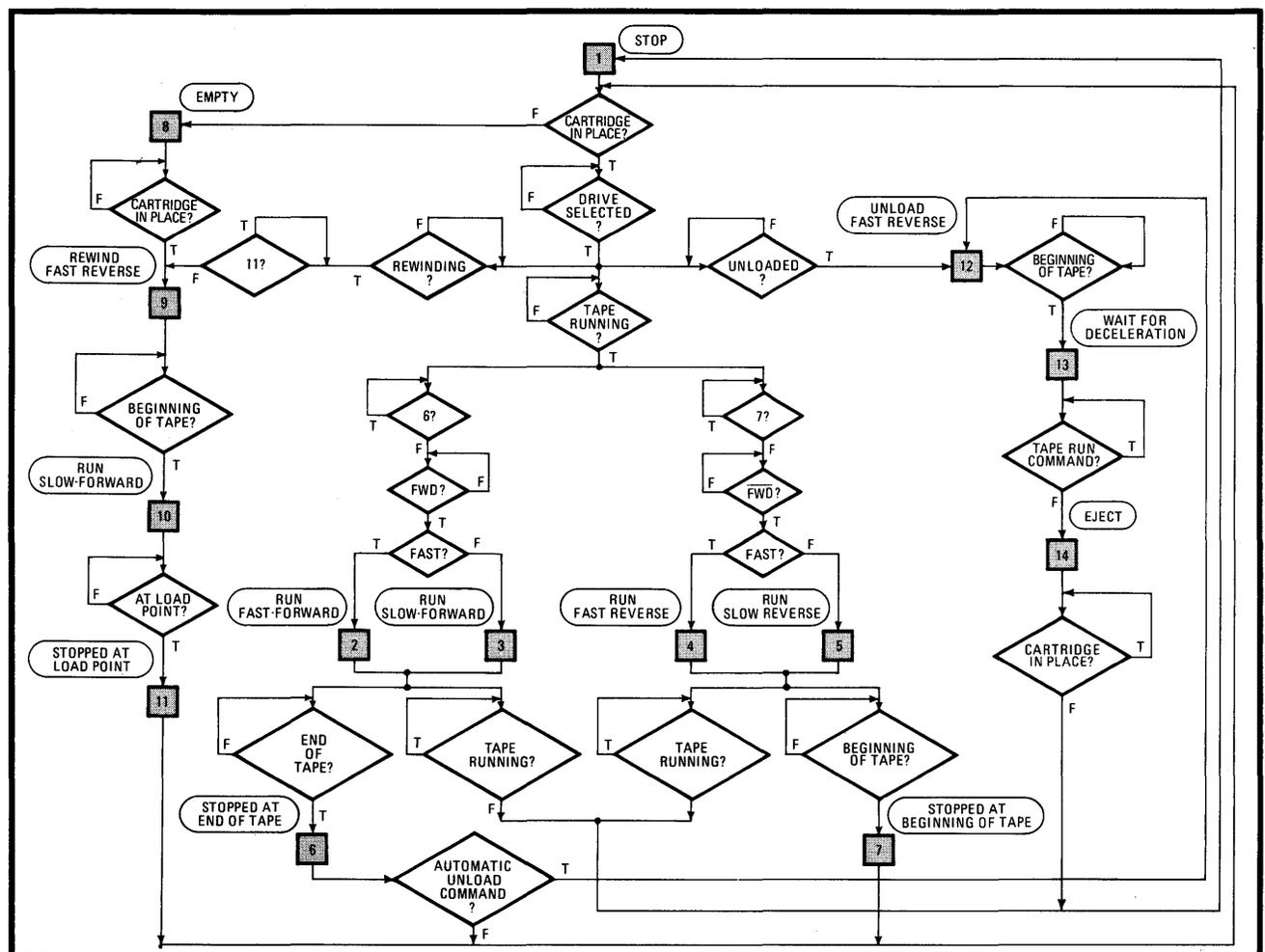
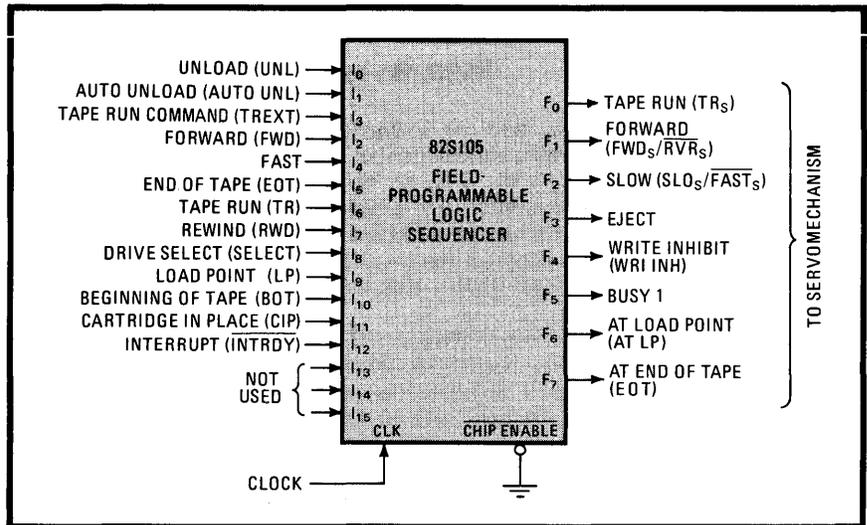
(a)



(b)

3. Error-free. The technique of using a cyclic redundancy check (CRC) word for error-free data transmission requires complex logic to generate the word (a). A pair of logic arrays, two latches, and a gate array (b) do the job, which usually requires a boardful of chips.

4. Tape controller. A field-programmable logic sequencer like this tape controller can perform extremely complex tasks. The 82S105 receives commands from an input/output bus or monitor, and provides all the necessary signals for driving the tape-transport servo-motor mechanism.



5. Goes with the flow. The first step in designing the controller is preparing a flow chart of the operation. The chart is much easier to understand than a state diagram or Mealy machine, yet provides all the information needed for programming the logic-sequencer chip.

jump from state 3 (RUN SLOW FORWARD) to state 1. By similar arguments, the tape drive can be run either fast or slow in either forward or reverse directions by jumping to states 2, 4, and 5.

When the end of tape is reached (EOT true), the tape drive is stopped. That is implemented by jumps 2 → 6 or

3 → 6. Once in state 6, the tape drive can no longer move in the forward direction because of the State 6 false condition preceding states 2 and 3. If AUTO UNL is true, the drive will automatically rewind (state 12), wait for tape to decelerate (state 13), eject the tape cartridge (state 14) and stop. If AUTO UNL is false, the drive must

How to patch a read-only memory

It is a shame to throw away read-only memories. But often firmware-based systems must commit control programs to large mask-programmed ROMs, only to have a design revision requiring a new program—and a new ROM. If no pin-compatible, user-programmable ROM is available, the customer could end up waiting out the 5-to-10-week turn-around time for the new mask parts—and throwing away his inventory of old ROMs.

One way to save an obsolete ROM (or even PROMs—it hurts to throw them away, too) is by patching, which redirects certain addresses to an adjunct smaller memory. This can be done most efficiently with an 82S107 field-programmable logic array.

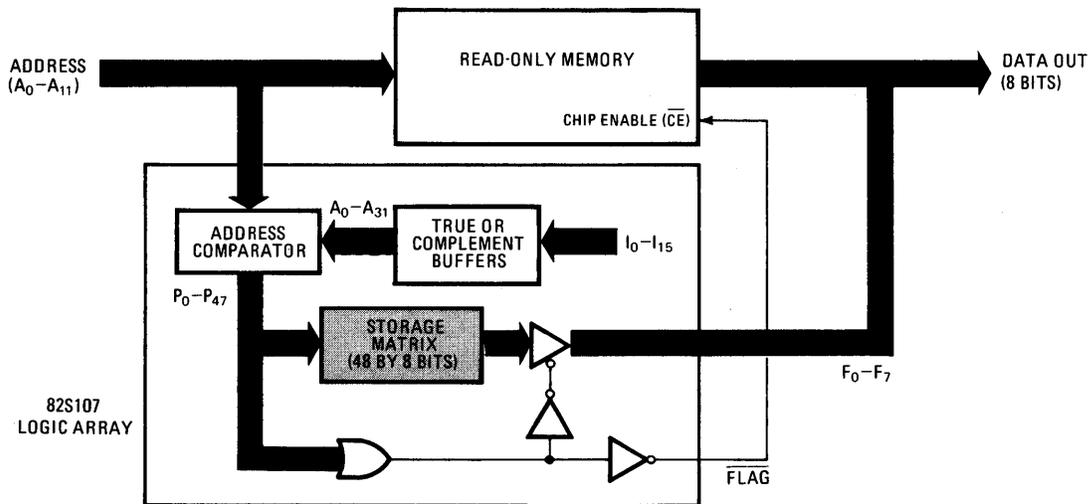
As a ROM patch (FPRP), the FPLA becomes a programmable, content-addressable PROM that continually monitors the address bus. As shown in the figure, when the FPRP encounters a match that signals a correction of data, its flag output (FL) disables the ROM, and new data from the FPRP is put on the output bus. If, for example, address 750 were to be given new data A9, address 5FE were to be given 7F, and addresses OA4-OA7 were all to be reassigned B4, the FPRP would be programmed as in the table. For a 12-bit address, only inputs I_0 - I_{11} are used, and the remaining four, I_{12} - I_{15} then become "don't care." (Incidentally, inputs I_0 and I_1 in the

second product term are also "don't care" because they define an address block of four locations.)

The address comparator can patch up to 48 non-overlapping addresses anywhere within a memory field of 64 kilobytes. Block addressing is possible, too, using the FPRP's true or complement input buffers. Moreover, the number of addresses can be expanded by hooking several devices in parallel and wire-ANDing their flag outputs.

Since the outputs of the ROM patch primarily define a byte of memory data rather than a set of logic functions, output polarity is not controlled. Also, to maintain compatibility with the gate array, the FPRP generates its self-enable signal with a fixed multiple-input OR gate; the only disadvantage of that method is addresses (AND terms), once programmed, may no longer be deleted.

The ROM patch affords a recovery strategy effective in several design situations, including modifications of dedicated application programs, operating systems, assemblers, and monitor routines. It also permits on-site optimization of system parameters, in accordance with, say, environmental variables, and allows custom function options and product-line diversification. The customer need only allot board space next to the mask ROM for an FPRP; no parts are actually used until program changes are required after the product is in the field.



PROGRAM TABLE FOR ROM PATCH

Input address	No.	Product term														Active level								Output data			
		Comparator input														Output function											
		15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	7	6	5	4	3	2		1	0	
750	0	-	-	-	-	L	H	H	H	L	H	L	H	L	L	L	L	A	•	A	•	A	•	•	A		A9
5FE	1	-	-	-	-	L	H	L	H	H	H	H	H	H	H	H	L	•	A	A	A	A	A	A	A	A	7F
OA4-OA7	2	-	-	-	-	L	L	L	L	H	L	H	L	L	H	-	-	A	•	A	A	•	A	•	•		B4

| A₁₁ ————— A₀ | | D₇ ————— D₀ |

wait for either a rewind command (RWD), an unload command (UNL), or reverse command (FWD).

If the tape is moved in the reverse direction until the beginning (BOT), the drive is stopped. This is implemented by a jump from states 4 or 5 to state 7. Once in state 7, the tape drive can no longer move in the reverse

direction because of the state 7 false condition preceding states 4 and 5. The tape will remain stopped at the beginning until TWD, UNL, or FWD commands are given.

If no cartridge is in place (CIP false) when the tape drive is turned on, the controller will jump from state 1 to 8, and signal EMPTY. When a cartridge is installed,

TABLE 1: COMPARISON OF DESIGN ALTERNATIVES FOR TAPE CONTROLLER

Parameter	Field-programmable logic sequencer	Discrete logic	Monolithic Memories Inc.'s Programmable Array Logic
Chip count	1 chip	6 chips	14 chips
Circuit-board area	0.84 in. ²	2.13 in. ²	3.78 in. ²
Power (typical)	0.60 W	1.36 W	4.8 W
Speed	90 ns/state	132 ns/state	105 ns/state
Voltage	+5 V	+5 V	+5 V
Cost (high-volume production)	\$12	\$14	\$48

TABLE 2: PROGRAMMING EQUIPMENT FOR THE FIELD PROGRAMMABLE LOGIC FAMILY

Type	Manufacturer	Model	Field-programmable device				Availability
			Gate array	Logic array	ROM patch	Logic sequencer	
Logic	Signetics	FP-103	•				now
		FP-104		•	•	•	
	Curtis	PR-100		•			
		PR-100A		•	•		
	Data I/O	10		•	•		
Memory	Data I/O	17,19	•	•	•	•	3Q79
	Sunrise Electronics	SM100		•	•		now
			•			•	in development
Hybrid	Stag	PPX-Plus		•	•		now
			•			•	in development

forward (FWD), and fast (FAST).

The flow chart of the controller routines is complete with 14 states and 36 state jumps (including synchronous reset). As such, four state-register flip-flops sufficiently represent all states. All state jumps can be directly programmed into the chip from the flow chart. All state jumps occur on the leading edge of the clock.

The advantage of a controller built with the FPLS is best shown by a comparison to discrete logic, which would comprise PROMs, latches, and gates, using the same state diagram as for the FPLS. Table 1 compares the FPLS controller with a discrete implementation as well as with Monolithic Memories Inc.'s Programmable Array Logic chips, in several aspects.

Programming

The key to design flexibility with programmable logic is the availability of programming equipment. The need for PROMs in this equipment has led to a large number of memory programmers being offered by several manufacturers. Generally, they operate with personality card sets that meet the requirements of various PROM technologies. Suppliers have already begun developing sets compatible with memory programmers for logic devices.

Hardware is expected to be available by the end of the third quarter of this year.

For the concept to work, the logic devices must be manipulated as memory chips are—by defining the desired fusing pattern in terms of an address-data relationship. Although this tends to obscure the logic function of the device, which is not visible on the program table, it is sure to provide low-cost programming equipment that can be manned by low-skilled labor.

Logic programming is another possibility, and low-cost equipment is already available from Signetics. Logic programmers allow direct entry of the logic function from the program table; no reference to the device logic diagram is necessary, and the user need not specify the status of each individual link in a device. Such programmers are more convenient for engineering use during the initial design phase, but with their high programming speed—about 10 seconds per device—can also be effective in production. Their only drawback is that they are dedicated machines and cannot program PROMs.

Some manufacturers offer a hybrid type of PROM programmer that can also be configured to do logic programming. Table 2 shows the various options available to prospective users now, or in the near future. □

SIGNETICS HEADQUARTERS

811 East Arques Avenue
P.O. Box 409
Sunnyvale, California 94086
Phone: (408) 739-7700

ARIZONA
Phoenix
Phone: (602) 265-4444

CALIFORNIA
Canoga Park
Phone: (213) 340-1431
Cupertino
Phone: (408) 725-8100
Inglewood
Phone: (213) 670-1101

IRVINE
Phone: (714) 833-8980
(213) 588-3281

SAN DIEGO
Phone: (714) 560-0242

COLORADO
Aurora
Phone: (303) 751-5011

CONNECTICUT
Danbury
Phone: (203) 744-6066

DELAWARE
Call: Micro-Comp, Baltimore
Phone: (301) 247-0400

FLORIDA
Lighthouse Point
Phone: (305) 782-8225
Atlanta
Phone: (404) 953-0067

ILLINOIS
Schaumburg
Phone: (312) 843-7805

INDIANA
Kokomo
Phone: (317) 453-6462

KANSAS
Overland Park
Phone: (913) 341-8181

MARYLAND
Glen Burnie
Phone: (301) 787-0220

MASSACHUSETTS
Woburn
Phone: (617) 938-1000

MICHIGAN
Farmington Hills
Phone: (313) 476-1610

MINNESOTA
Edina
Phone: (612) 835-7455

NEW JERSEY
Cherry Hill
Phone: (609) 665-5071

PISCATAWAY
Phone: (201) 981-0126

NEW YORK
Liverpool
Phone: (315) 451-5470

Melville
Phone: (516) 752-0130

Wappingers Falls
Phone: (914) 297-4074

NORTH CAROLINA
Raleigh
Phone: (919) 851-2013

OHIO
Worthington
Phone: (614) 888-7143

TENNESSEE
Greeneville
Phone: (615) 639-0251

TEXAS
Austin
Phone: (512) 458-2591

Dallas
Phone: (214) 661-1296

UTAH
Bountiful
Phone: (801) 298-2624

CANADA
SIGNETICS CANADA, LTD.
Eloibicoke, Ontario
Phone: (416) 626-6675

SIGNETICS CANADA, LTD./L.T.E.E.
Pointe-Claire, Quebec
Phone: (514) 697-3385

REPRESENTATIVES
ALABAMA
Huntsville
Electronic Sales, Inc.
Phone: (205) 533-1735

CALIFORNIA
Los Gatos
Sierra Technology
Phone: (408) 354-9986

San Diego
Mesa Engineering
Phone: (714) 278-8021

CONNECTICUT
Danbury
Kanan Associates
Phone: (203) 265-2404

FLORIDA
Altamonte Springs
Semtronics Associates
Phone: (305) 831-8233

Clearwater
Semtronics Associates
Phone: (813) 461-4675

ILLINOIS
Elk Grove Village
Micro-Tex, Inc.
Phone: (312) 640-9633

INDIANA
Fort Wayne
Insul-Reps, Inc.
Phone: (219) 482-1596

Indianapolis
Insul-Reps, Inc.
Phone: (317) 842-5203

IOWA
Cedar Rapids
Comstrand Inc.
Phone: (319) 377-1575

KANSAS
Shawnee Mission
B. C. Electronic Sales
Phone: (913) 888-6680

MARYLAND
Baltimore
Micro-Comp, Inc.
Phone: (301) 247-0400

MASSACHUSETTS
Reading
Kanan Associates
Phone: (617) 944-8484

MICHIGAN
Bloomfield Hills
Enco Marketing
Phone: (313) 642-0203

MINNESOTA
Edina
Mel Foster Technical Sales
Phone: (612) 941-9790

MISSOURI
St. Louis
B. C. Electronic Sales
Phone: (314) 731-1255

NEVADA
Sierra Technology
Phone: (408) 354-9986

NEW MEXICO
Albuquerque
Power Enterprises
Phone: (505) 298-1918

NEW YORK
Ithaca
Bob Dean, Inc.
Phone: (607) 272-2187

OHIO
Cleveland
Norm Case Associates
Phone: (216) 333-4120

Dayton
Norm Case Associates
Phone: (800) 362-6631

OKLAHOMA
Tulsa
Cunningham Co.
Phone: (918) 492-0390

OREGON
Hillsboro
Western Technical Sales
Phone: (503) 640-4621

TEXAS
Austin
Cunningham Co.
Phone: (512) 459-8947

Dallas
Cunningham Co.
Phone: (214) 233-4303

Houston
Cunningham Co.
Phone: (713) 461-4197

VIRGINIA
Lynchburg
Micro-Comp, Inc.
Phone: (804) 237-6221

WASHINGTON
Bellevue
Western Technical Sales
Phone: (206) 641-3900

Spokane
Western Technical Sales
Phone: (509) 922-7600

WASHINGTON, D.C.
Call: Micro-Comp, Baltimore
Phone: (301) 247-0400

WISCONSIN
Waukesha
Micro-Tex, Inc.
Phone: (414) 542-5352

DISTRIBUTORS

ALABAMA
Huntsville
Hall-Mark Electronics
Phone: (205) 837-8700
Hamilton/Annet Electronics
Phone: (205) 837-7210
Pioneer Electronics
Phone: (205) 837-9300

ARIZONA
Phoenix
Hamilton/Annet Electronics
Phone: (602) 894-9600
Wyle Distribution Group
Phone: (602) 249-2232

CALIFORNIA
Costa Mesa
Annet Electronics
Phone: (714) 754-6111
Hamilton Electro Sales
Phone: (714) 641-4100

Culver City
Hamilton/Annet Electronics
Phone: (310) 558-2121
Hamilton/Annet Electronics
Military
Phone: (213) 558-2901

El Segundo
Wyle Distribution Group
Phone: (213) 322-8100

Irvine
Schweber Electronics
Phone: (714) 556-3880
Wyle Distribution Group
Phone: (714) 979-2125

San Diego
Anthem Electronics
Phone: (714) 279-5200
Hamilton/Annet Electronics
Phone: (714) 571-7510
Wyle Distribution Group
Phone: (714) 565-9171

San Jose
Anthem Electronics Inc.
Phone: (408) 946-8000

Santa Clara
Schweber Electronics
Phone: (408) 498-0200
Wyle Distribution Group
Phone: (408) 727-2900

Sunnyvale
Arrow Electronics
Phone: (408) 745-6600
Hamilton/Annet Electronics
Phone: (408) 743-3366

CANADA
Calgary, Alberta
Hamilton/Annet Electronics
Phone: (403) 230-3586

Downsview, Ontario
Cesco Electronics
Phone: (416) 661-0220

Mississauga, Ontario
Hamilton/Annet Electronics
Phone: (416) 677-7432
Zenitronics
Phone: (416) 451-9600

Montreal, Quebec
Cesco Electronics
Phone: (514) 735-5511
Zenitronics
Phone: (514) 735-5361

Ottawa, Ontario
Cesco Electronics
Phone: (613) 729-5118
Hamilton/Annet Electronics
Phone: (613) 226-1700
Zenitronics
Phone: (613) 238-6411

Quebec City
Cesco Electronics
Phone: (418) 524-4641

Ville St. Laurent, Quebec
Hamilton/Annet Electronics
Phone: (514) 331-6443

COLORADO
Denver
Arrow Electronics
Phone: (303) 758-2100
Wyle Distribution Group
Phone: (303) 457-9953

Englewood
Hamilton/Annet Electronics
Phone: (303) 740-1000

CONNECTICUT
Danbury
Hamilton/Annet Electronics
Phone: (203) 797-2300
Schweber Electronics
Phone: (203) 792-3500

Wallingford
Arrow Electronics
Phone: (203) 265-7741

FLORIDA
Ft. Lauderdale
Arrow Electronics
Phone: (305) 776-7790
Hamilton/Annet Electronics
Phone: (305) 971-2900

Hollywood
Schweber Electronics
Phone: (305) 927-0511

Palm Bay
Arrow Electronics
Phone: (305) 725-1480

St. Petersburg
Hamilton/Annet Electronics
Phone: (813) 576-3930

GEORGIA
Atlanta
Schweber Electronics
Phone: (404) 449-9170

Norcross
Arrow Electronics
Phone: (404) 449-8252
Hamilton/Annet Electronics
Phone: (404) 447-7500

ILLINOIS
Chicago
Bell Industries
Phone: (312) 982-9210

Elk Grove
Schweber Electronics
Phone: (312) 364-3750

Schaumburg
Arrow Electronics
Phone: (312) 893-9420

Bensenville
Hamilton/Annet Electronics
Phone: (312) 860-7700

INDIANA
Indianapolis
Pioneer Electronics
Phone: (317) 849-7300
Arrow Electronics
Phone: (317) 243-9353
Hamilton/Annet Electronics
Phone: (317) 844-9333

KANSAS
Overland Park
Hamilton/Annet Electronics
Phone: (913) 888-8900

MARYLAND
Baltimore
Arrow Electronics
Phone: (301) 247-5200

Columbia
Hamilton/Annet Electronics
Phone: (301) 995-3500

Gaithersburg
Pioneer Washington Electronics
Phone: (301) 948-0710
Schweber Electronics
Phone: (301) 840-5900

MASSACHUSETTS
Bedford
Schweber Electronics
Phone: (617) 275-5100

Burlington
Lionex Corp.
Phone: (617) 272-9400

Woburn
Arrow Electronics
Phone: (617) 933-8130
Hamilton/Annet Electronics
Phone: (617) 273-7500

MICHIGAN
Ann Arbor
Arrow Electronics
Phone: (313) 971-8220

Grand Rapids
Hamilton/Annet Electronics
Phone: (616) 643-8805

Livonia
Hamilton/Annet Electronics
Phone: (313) 522-4700
Pioneer Electronics
Phone: (313) 525-1800
Schweber Electronics
Phone: (313) 525-8100

MINNESOTA
Eden Prairie
Schweber Electronics
Phone: (612) 941-5280

Minneapolis
Arrow Electronics
Phone: (612) 830-1800
Hamilton/Annet Electronics
Phone: (612) 932-0600

MISSOURI
Earth City
Hamilton/Annet Electronics
Phone: (314) 344-1200

St. Louis
Arrow Electronics
Phone: (314) 567-6888

NEW HAMPSHIRE
Manchester
Arrow Electronics
Phone: (603) 668-6968

NEW JERSEY
Cherry Hill
Hamilton/Annet Electronics
Phone: (609) 424-0100

Fairfield
Hamilton/Annet Electronics
Phone: (201) 575-3390
Schweber Electronics
Phone: (201) 227-7880

Moorestown
Arrow Electronics
Phone: (609) 235-1900

Saddlebrook
Arrow Electronics
Phone: (201) 797-5800

NEW MEXICO
Albuquerque
Hamilton/Annet Electronics
Phone: (505) 765-1500

NEW YORK
Buffalo
Summit Distributors
Phone: (716) 887-2800

East Syracuse
Arrow Electronics
Phone: (315) 652-1000
Hamilton/Annet Electronics
Phone: (315) 437-2642

Farmingdale, L.I.
Arrow Electronics
Phone: (516) 694-6800

Liverpool
Arrow Electronics
Phone: (315) 652-1000

Melville
Hamilton/Annet Electronics
Phone: (516) 454-6012

Rochester
Arrow Electronics
Phone: (716) 275-0300
Hamilton/Annet Electronics
Phone: (716) 475-9130
Schweber Electronics
Phone: (716) 424-2222

Westbury, L.I.
Schweber Electronics
Phone: (516) 334-7474

NORTH CAROLINA
Greensboro
Pioneer Electronics
Phone: (919) 273-4441

Raleigh
Hamilton/Annet Electronics
Phone: (919) 829-8030

OHIO
Beechwood
Schweber Electronics
Phone: (216) 464-2970

Cleveland
Hamilton/Annet Electronics
Phone: (216) 831-3500
Pioneer Electronics
Phone: (216) 587-3600

Centerville
Arrow Electronics
Phone: (513) 435-5563

Dayton
Hamilton/Annet Electronics
Phone: (513) 433-0610
Pioneer Standard Electronics
Phone: (513) 236-9900

Solon
Arrow Electronics
Phone: (216) 248-3990

OKLAHOMA
Tulsa
Quality Components
Phone: (918) 664-8812

OREGON
Lake Oswego
Hamilton/Annet Electronics
Phone: (503) 635-8831

PENNSYLVANIA
Horsham
Schweber Electronics
Phone: (215) 441-0600

Pittsburgh
Arrow Electronics
Phone: (412) 856-7000
Pioneer/Pittsburgh
Phone: (412) 782-2300

TEXAS
Austin
Hamilton/Annet Electronics
Phone: (512) 837-8911
Quality Components
Phone: (512) 835-0220

Dallas
Hall-Mark Electronics
Phone: (214) 341-1147
Hamilton/Annet Electronics
Phone: (214) 659-4111
Quality Components
Phone: (214) 387-4949
Schweber Electronics
Phone: (214) 661-5010

Houston
Hamilton/Annet Electronics
Phone: (713) 780-1771
Quality Components
Phone: (713) 772-7100
Schweber Electronics
Phone: (713) 784-3600

UTAH
Salt Lake City
Hamilton/Annet Electronics
Phone: (801) 972-4300

WASHINGTON
Bellevue
Arrow Electronics
Phone: (206) 643-4800
Hamilton/Annet Electronics
Phone: (206) 453-5844
Wyle Distribution Group
Phone: (206) 453-8300

WISCONSIN
Oak Creek
Arrow Electronics
Phone: (414) 764-6600

New Berlin
Hamilton/Annet Electronics
Phone: (414) 784-4510

FOR SIGNETICS PRODUCTS WORLDWIDE:

ARGENTINA
Fapasa Ly C
Buenos Aires
Phone: 652-7438/7478

AUSTRALIA
Philips Industries-ELCOMA
Lane-Cove, N.S.W.
Phone: (02) 427-0888

Queensland
Brisbane
(07) 277-3332

South Australia
Adelaide
(08) 45-0211

Victoria
Melbourne
(03) 544-7833

Western Australia
Perth
(09) 277-4199

AUSTRIA
Osterreichische Philips
Wien
Phone: 93 26 22

BELGIUM
M.B.L.E.
Brussels
Phone: 523 00 00

BRAZIL
Ibrapre Electronica Ltda.
Sao Paulo
Phone: (011) 211-2600

CHILE
Philips Chilena S.A.
Santiago
Phone: 39-4001

COLOMBIA
Sadape S.A.
Bogota
Phone: 600600

DENMARK
Miniviat A/S
Kobenhavn
Phone: (01) 69 16 22

FINLAND
Oy Philips Ab
Helsinki
Phone: 72 71

FRANCE
Paris
Phone: 355-44-99

GERMANY
Hamburg
Phone: (040) 3296-1

GREECE
Philips S.A. Hellenique
Athens
Phone: 915 311

HONG KONG
Philips Hong Kong, Ltd.
Hong Kong
Phone: 12-245121

INDIA
Paico Electronics & Elect. Ltd.
Elcoma Div.
Bombay
Phone: 295-144

INDONESIA
P.T. Philips-Ratin Electronics
Jakarta
Phone: 581058

IRELAND
Philips Electrical Ltd.
Dublin
Phone: 693355

ISRAEL
Rapee Electronics, Ltd.
Tel Aviv
Phone: 477115-6-7

ITALY
Philips S.p.A.
Milano
Phone: 2-6994

JAPAN
Signetics Japan

signetics

a subsidiary of U.S. Philips Corporation

Signetics Corporation
811 East Arques Avenue
P.O. Box 409
Sunnyvale, California 94086
Telephone 408/739-7700